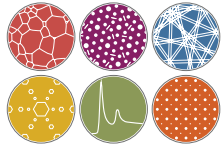


STEM Diffraction Contrast of Crystalline Defects: Advantages and Opportunities



Center for Electron
Microscopy and Analysis

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Carnegie Mellon University



Go Bucks!!

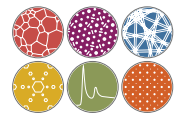
Tecnai F-20 STEM



Center for Electron
Microscopy and Analysis

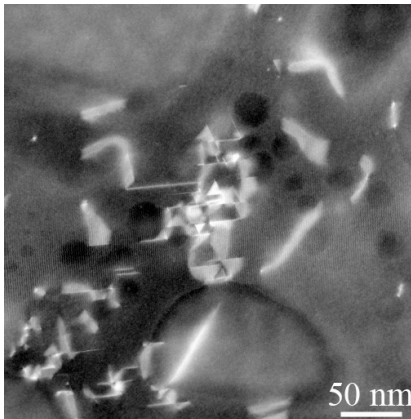
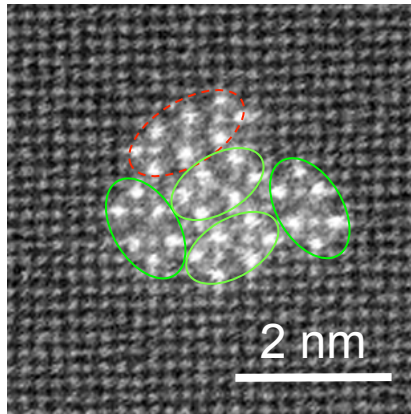
Outline

- Brief Motivation for “Micro/Mesoscale” structure studies
- Conventional Diffraction Contrast Imaging
- STEM-based Diffraction Contrast Imaging:
 - Experimental considerations
 - Advantages over conventional CTEM
- Simulation of Diffraction Contrast of Defects
- 3D and Other Possibilities
 - Tilt series reconstructions
 - High order g imaging
 - Zone axis imaging

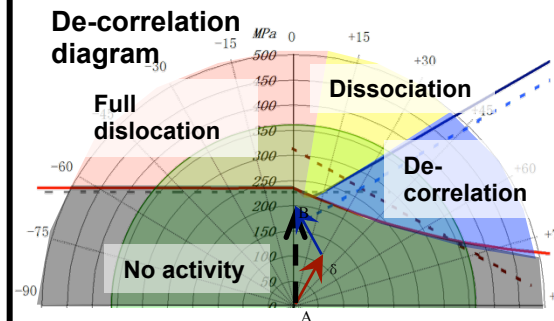
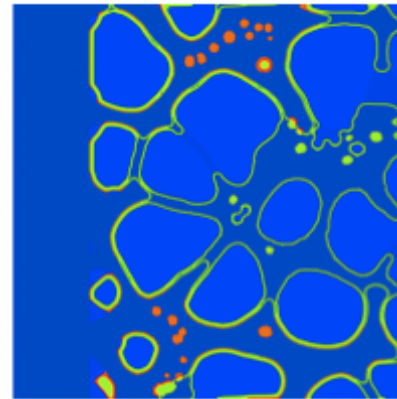


Integrated Computational Materials Engineering

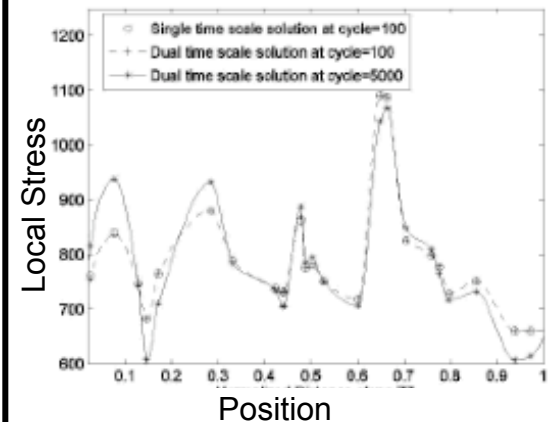
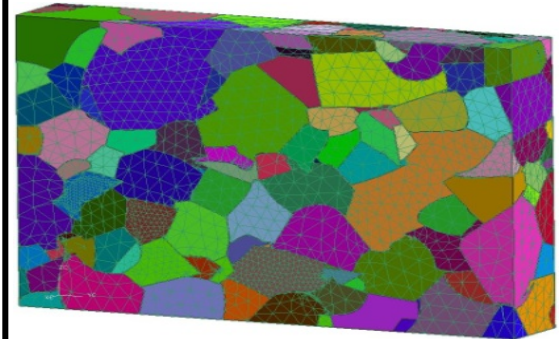
Micro and Mechanism Characterization



Meso-scale Mechanism Modeling



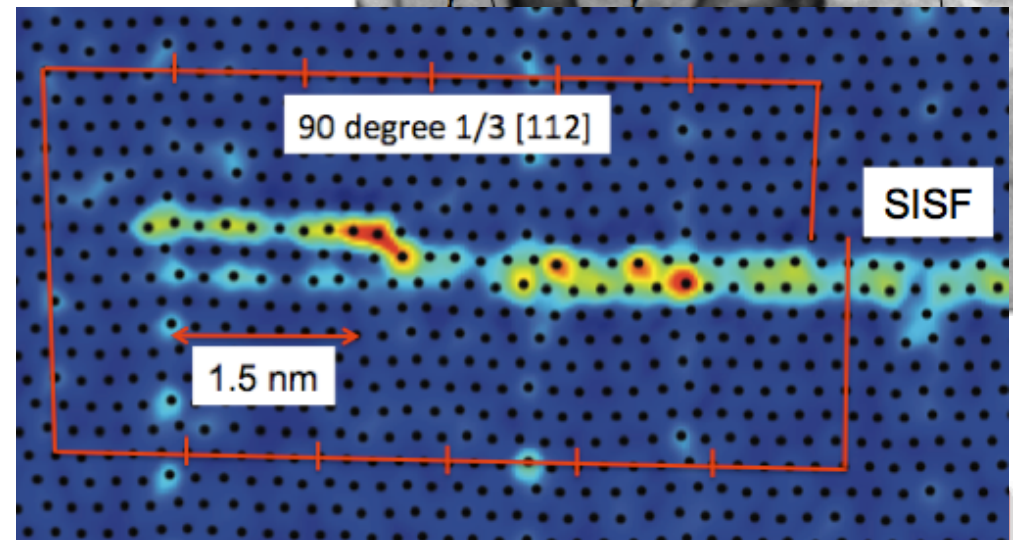
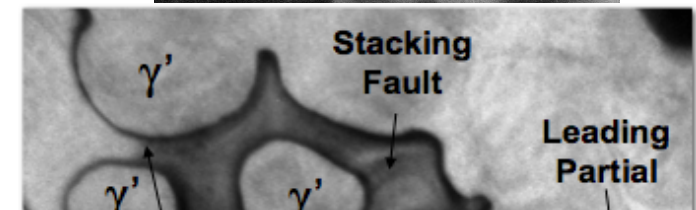
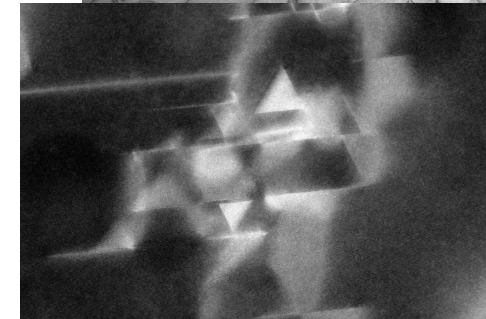
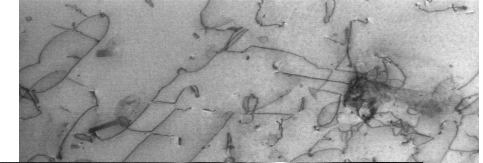
Microstructure-Based FEA Modeling



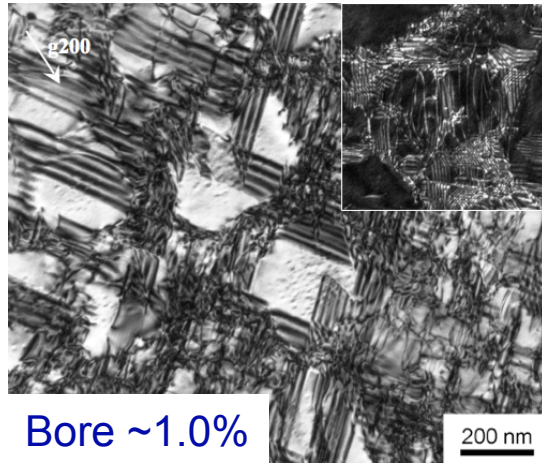
Characterization underpins ICME for structural/functional materials

Characterizing Dislocation Structures

- Dislocation density
- Morphology – preferential line directions
- Dislocation reactions
- Interaction with precipitates
- Dislocation dissociation for fault energies
- Core structure for mobility
- Segregation to defects

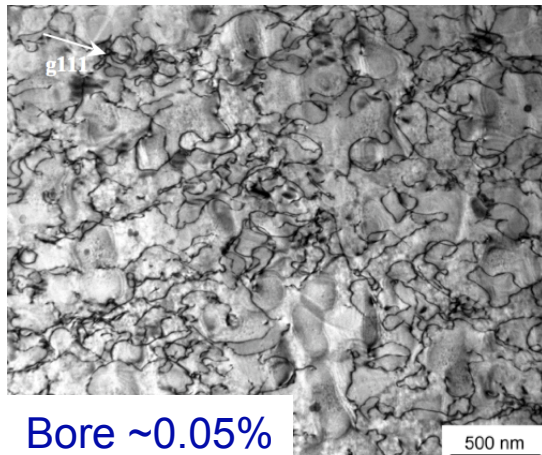


Microstructure Can Alter Deformation Mechanisms



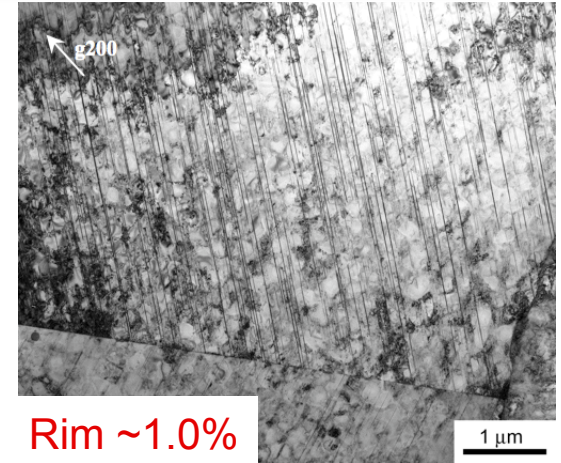
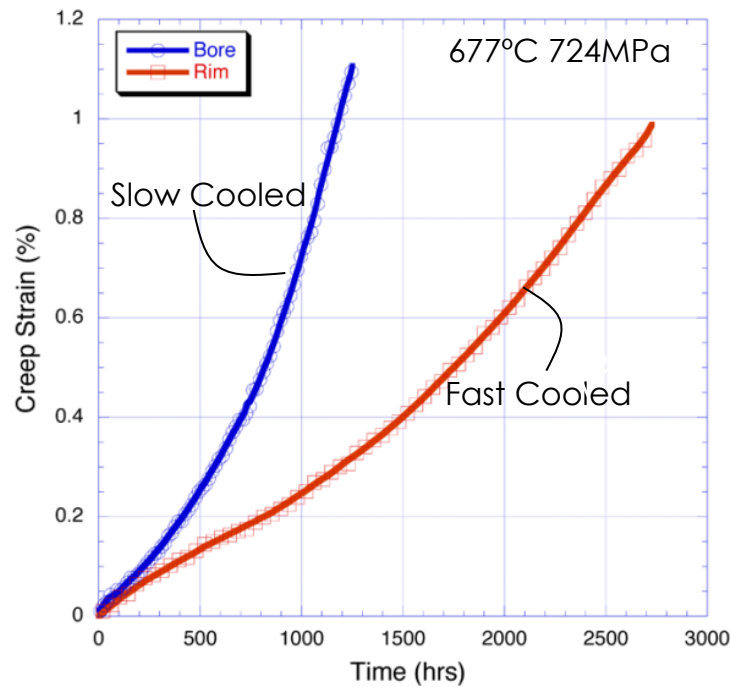
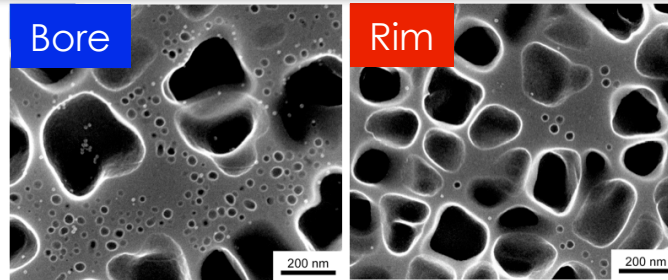
Bore ~1.0%

Increased $a/2\langle 110 \rangle$ matrix dislocation activity and SISF shearing of secondary γ/γ'



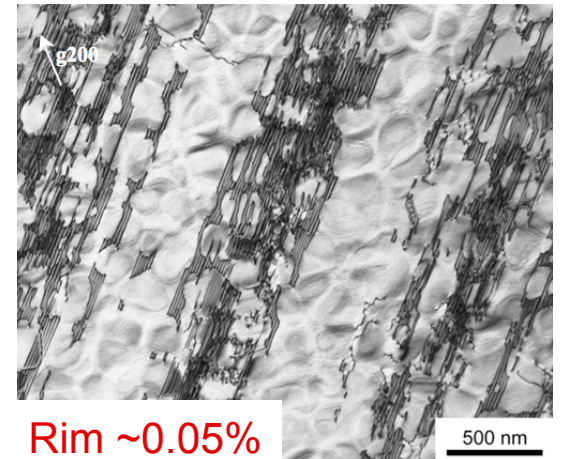
Bore ~0.05%

$a/2\langle 110 \rangle$ matrix dislocation activity



Rim ~1.0%

Microtwinning is the dominant creep deformation mechanism



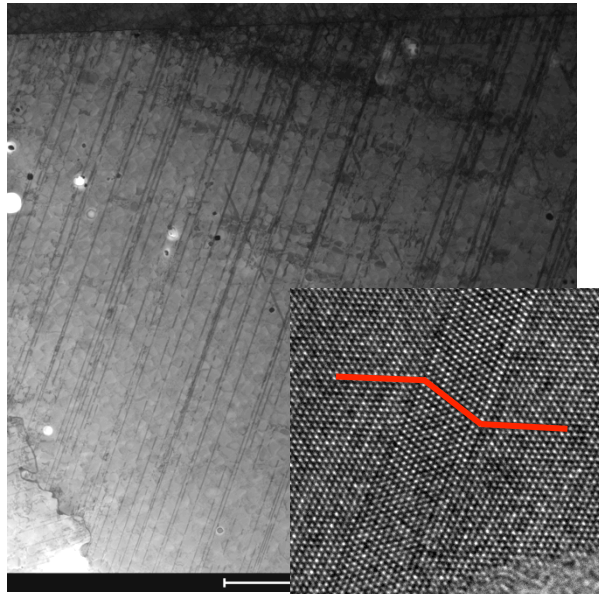
Rim ~0.05%

Matrix intrinsic stacking faults

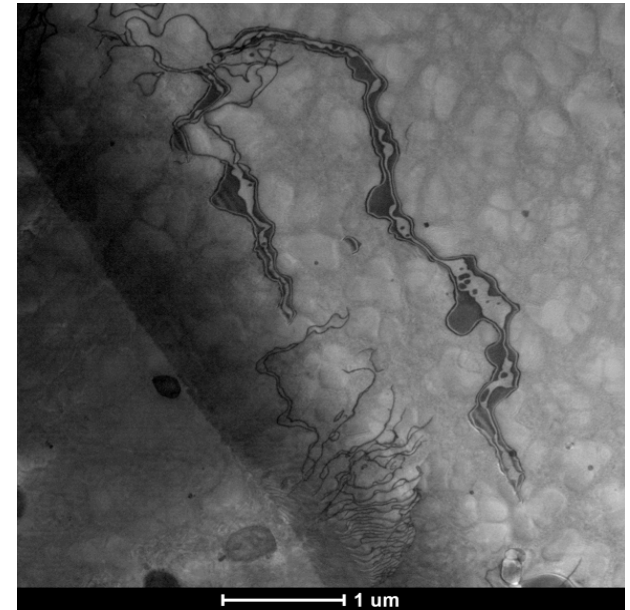
Microstructure scale can alter creep mechanisms

Intragranular Mechanisms in ME3 as Function of Deformation Conditions at 1300°F

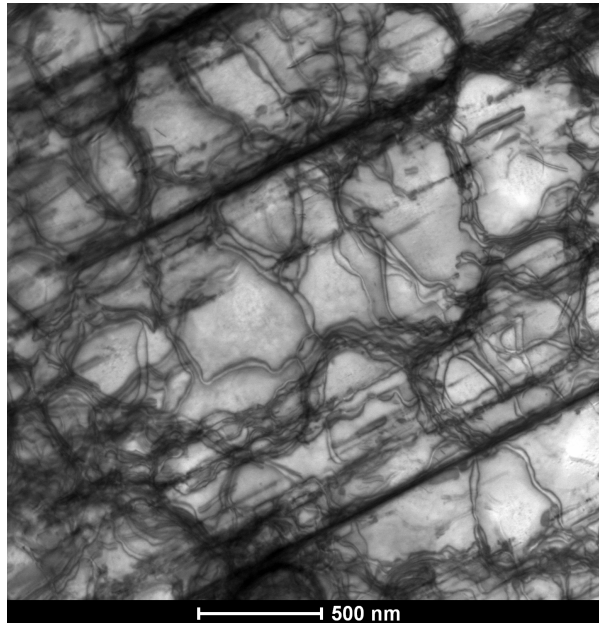
Low Stress
Creep:
Microtwins



Dwell
Fatigue:
SF ribbons



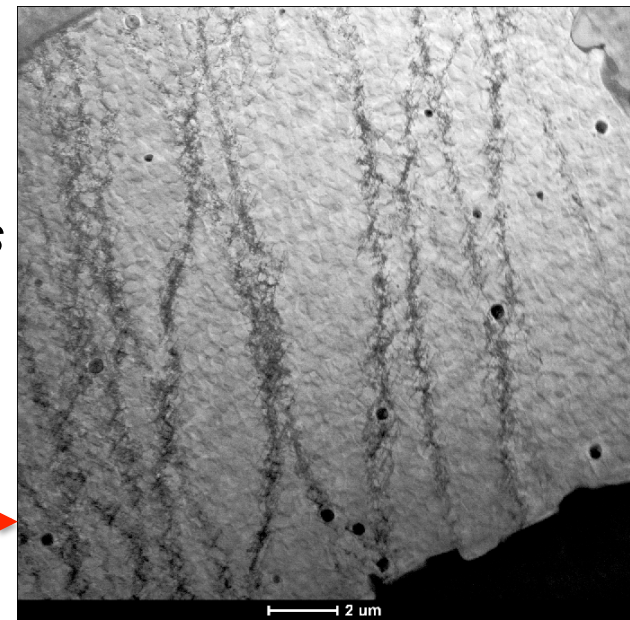
High Stress
Creep/
Constant
Strain Rate/
Low Cycle
Fatigue



*Planar
slip by
paired
dislocations*



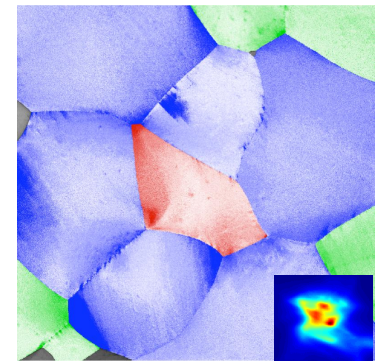
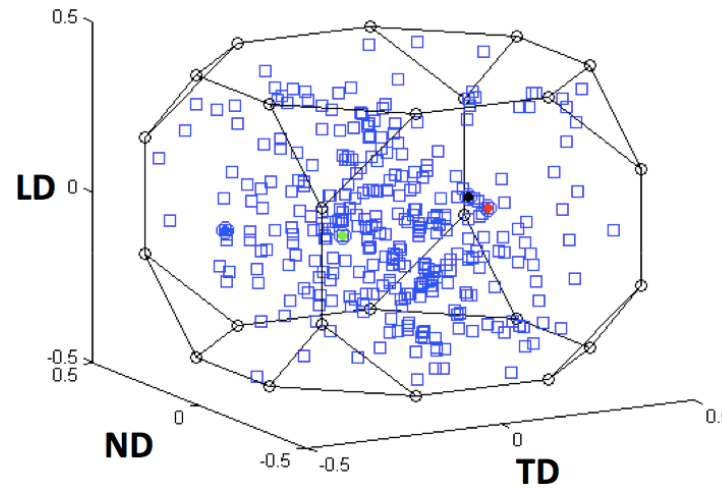
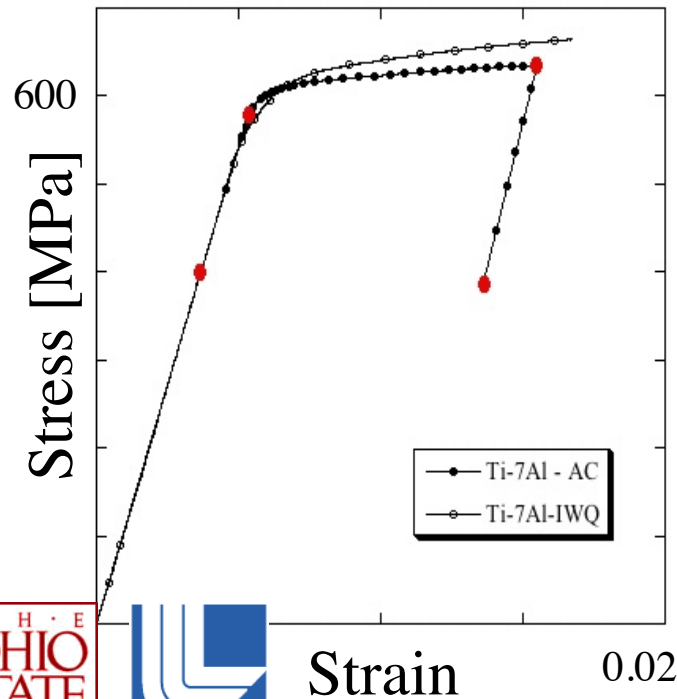
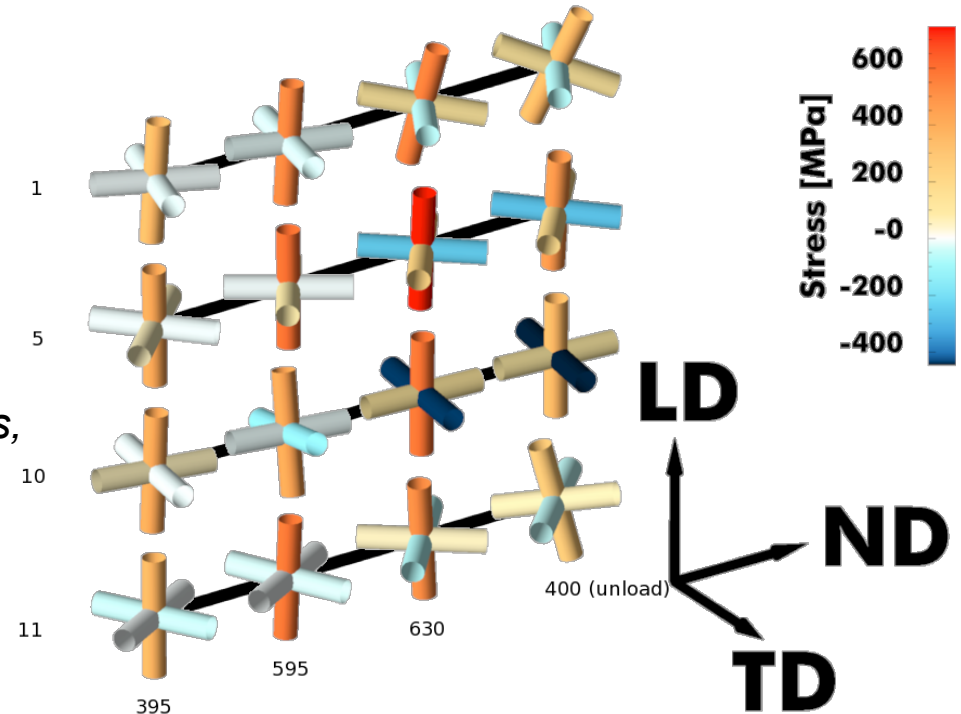
*Wavy
slip*



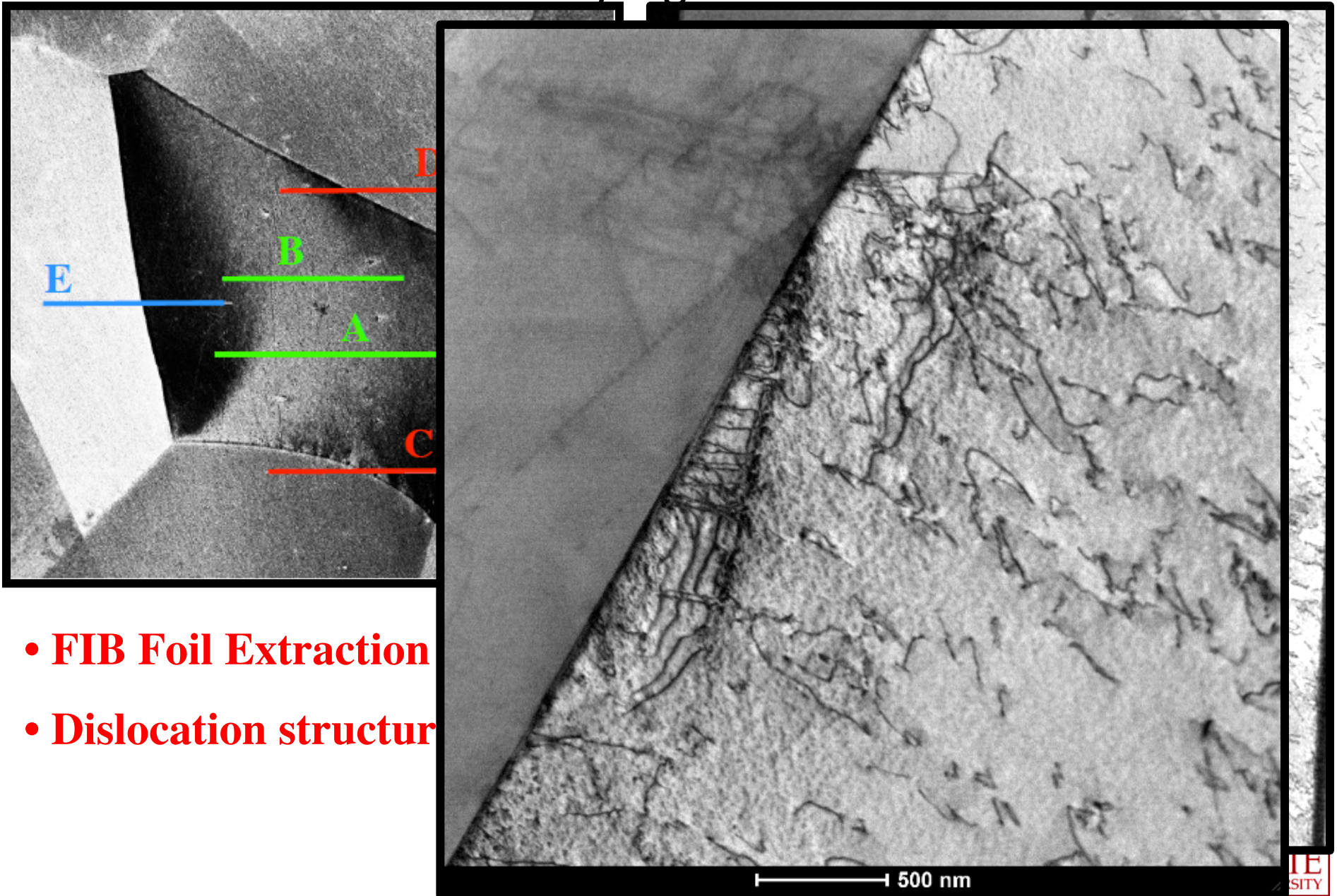
Dynamic In-Situ Loading

- Continuous ω scanning
- Dynamic Loading
 - Constant ϵ -rate ($10^{-8} - 10^{-2} \text{ s}^{-1}$)
 - Creep & Fatigue loading possible
- COM and strain measurements
- $\sim 1 \text{ mm}^3$ volume
- ~ 700 grains

*Lienert, Bernier,
Barton, Brandes, Mills,
Miller, JOM (2011)*



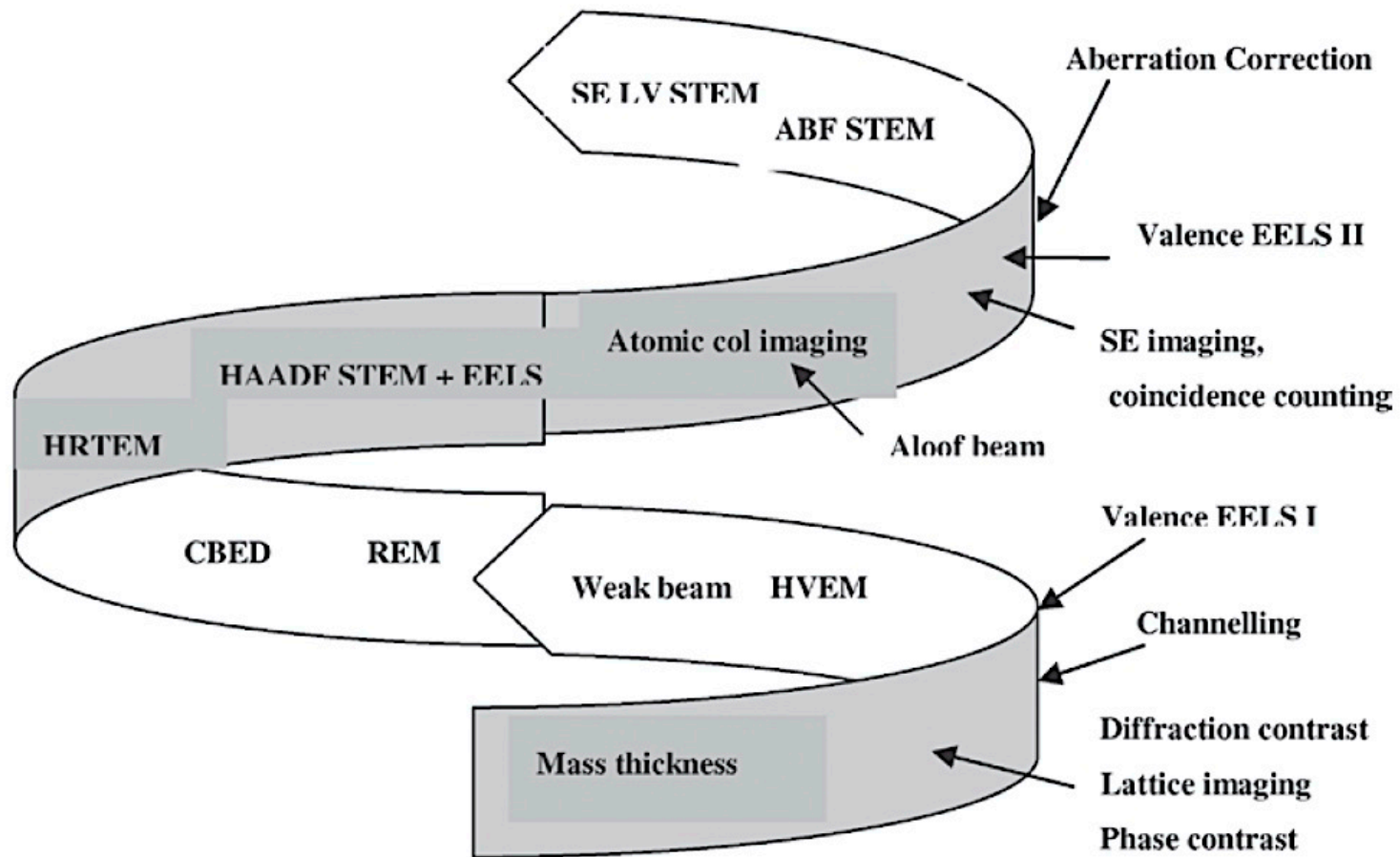
Correlating Dislocation Structure with “X-ray Signatures”



- FIB Foil Extraction
- Dislocation structure

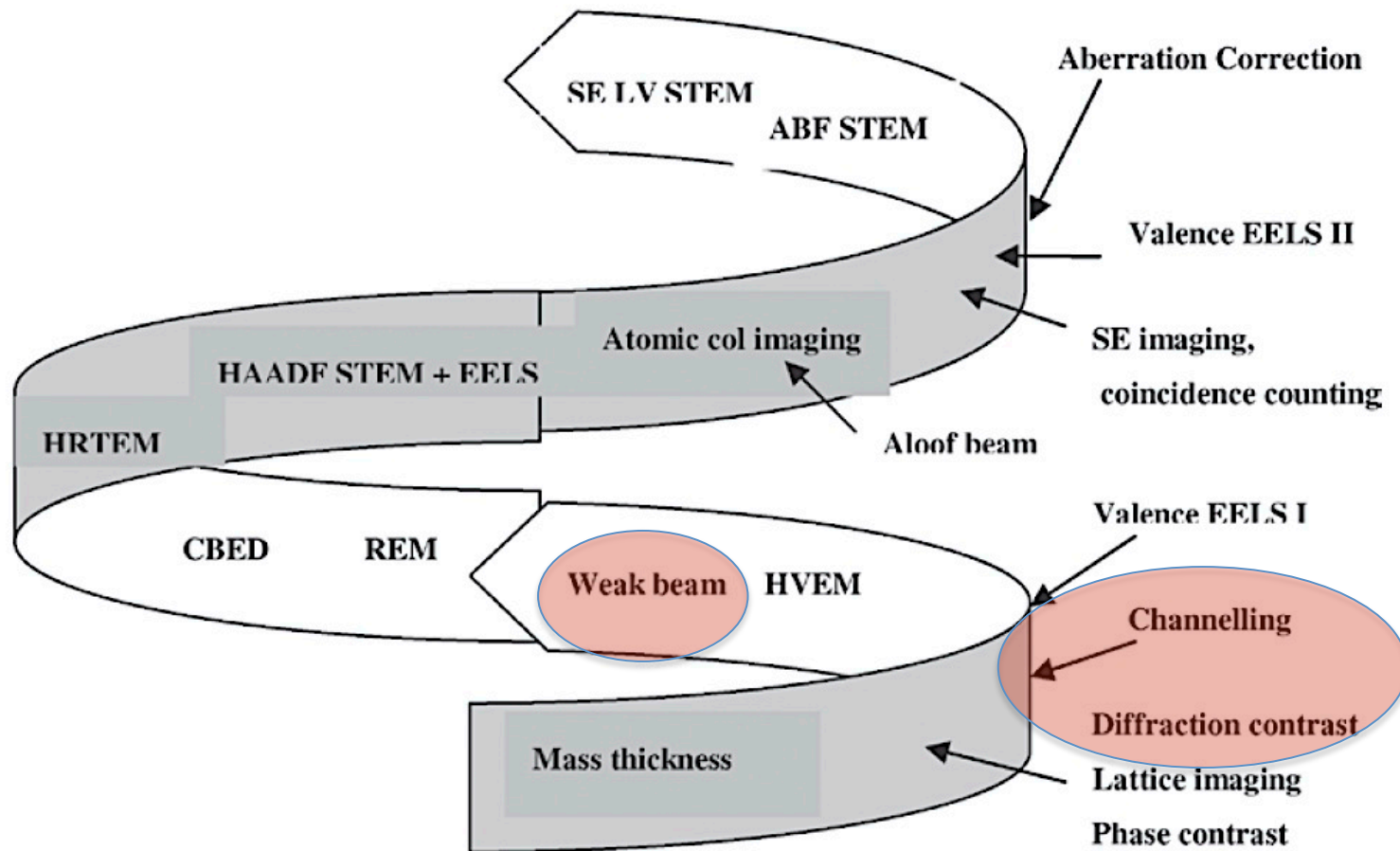
Spiral History of TEM

A. Howie, M&M Proceedings, 2012



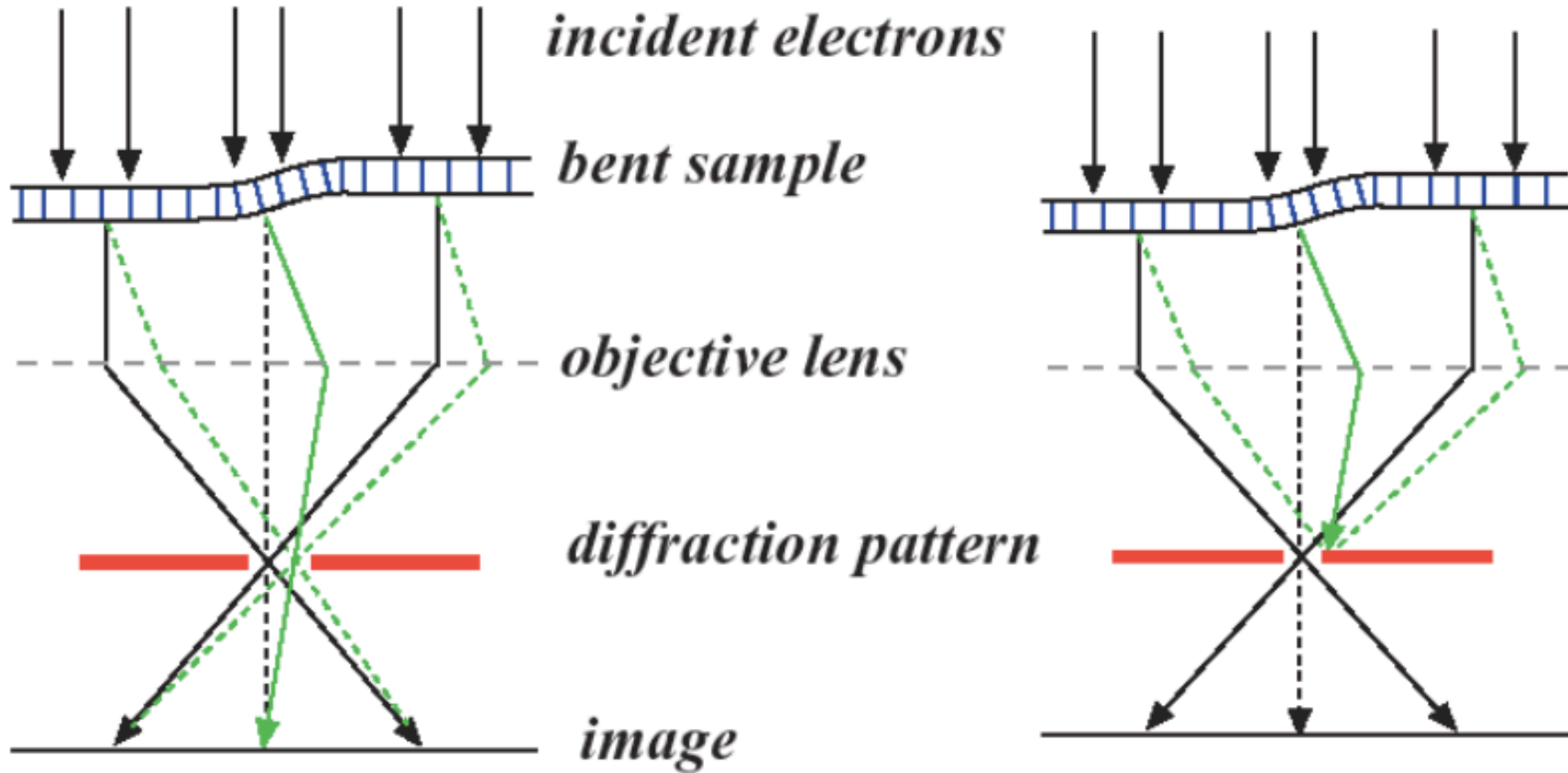
Spiral History of TEM

A. Howie, M&M Proceedings, 2012



“Conventional” Diffraction Contrast

Basic Imaging Concepts: *Difference in Crystal Orientation*

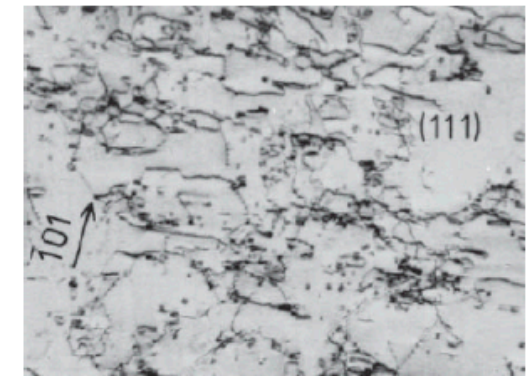
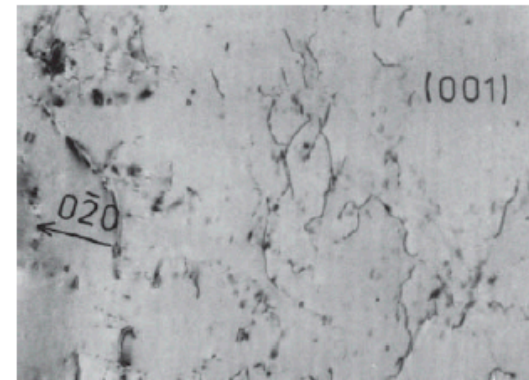
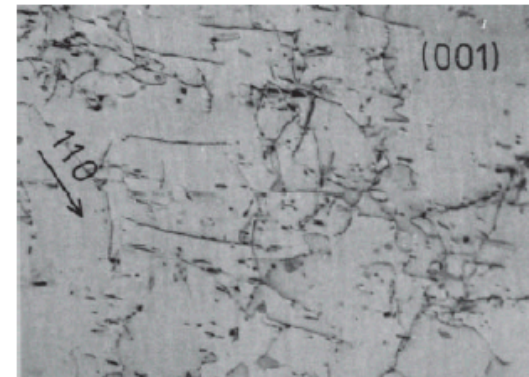
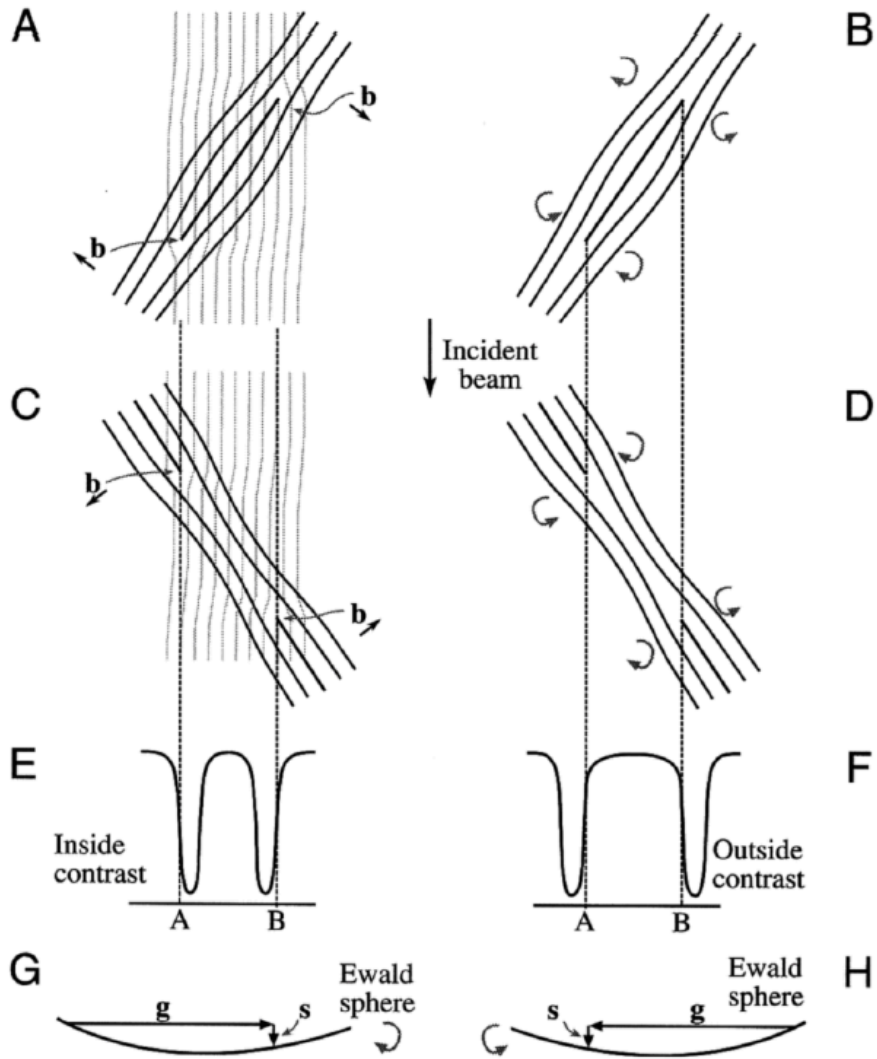


Basis of bend contour and dislocation contrast

“Conventional” Diffraction Contrast

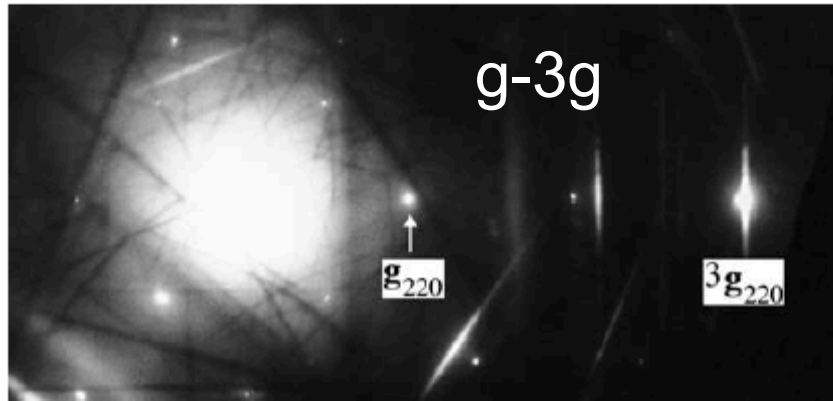
- Dislocation Contrast:

Viswanathan (2006)



“Conventional” Diffraction Contrast

- Weak beam imaging



Rule of thumb – Image width proportional to:

$$\xi_g^{eff} = \frac{\xi_g}{(1 + s^2 \xi_g^2)^{\frac{1}{2}}}$$

So enhance resolution by increasing deviation parameter

Williams and Carter

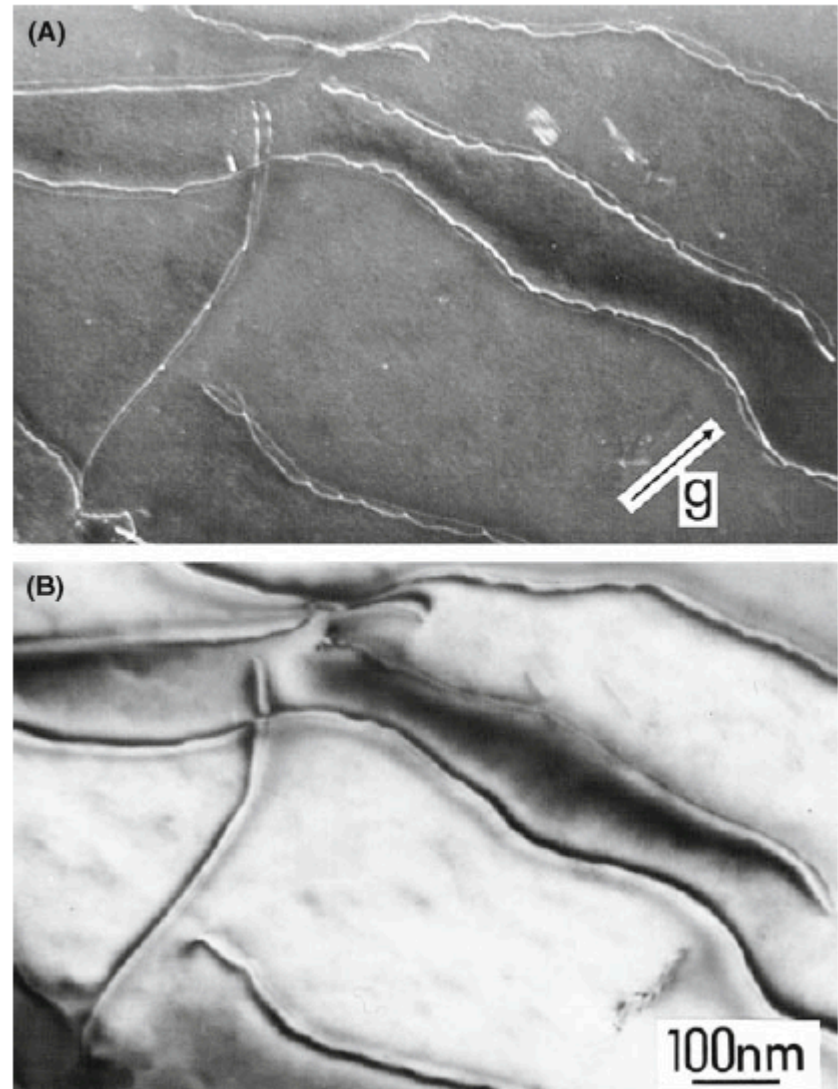
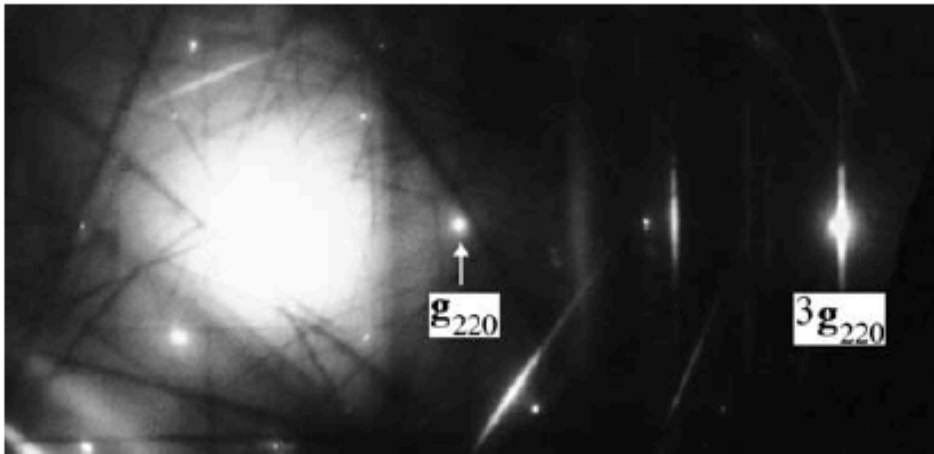


FIGURE 27.8. A comparison of dislocation images in a Cu alloy formed using (A) WB and (B) strong-beam ($s_g > 0$) conditions.

Weak Beam Imaging



- Large deviation parameters reveal fine details associated with defect strain fields
- Large contrast but weak intensities
- Long exposure times
- Drift, sample stability and contamination
- Very thin and flat foils required

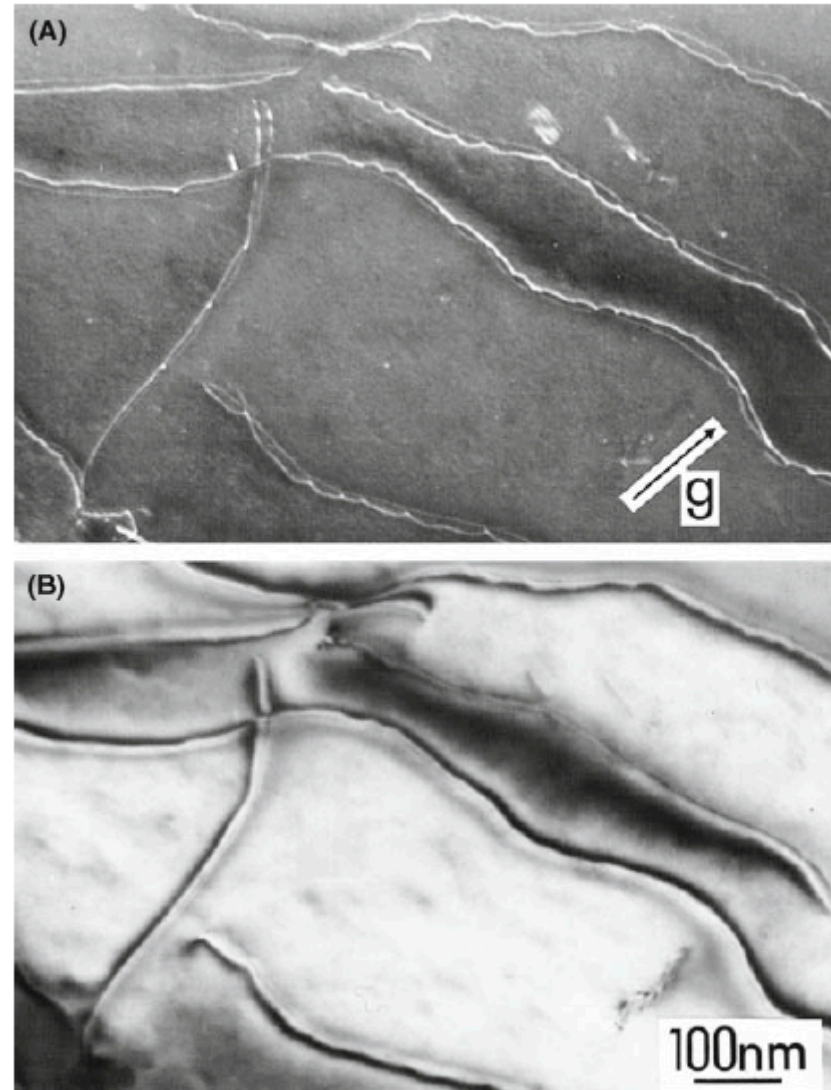
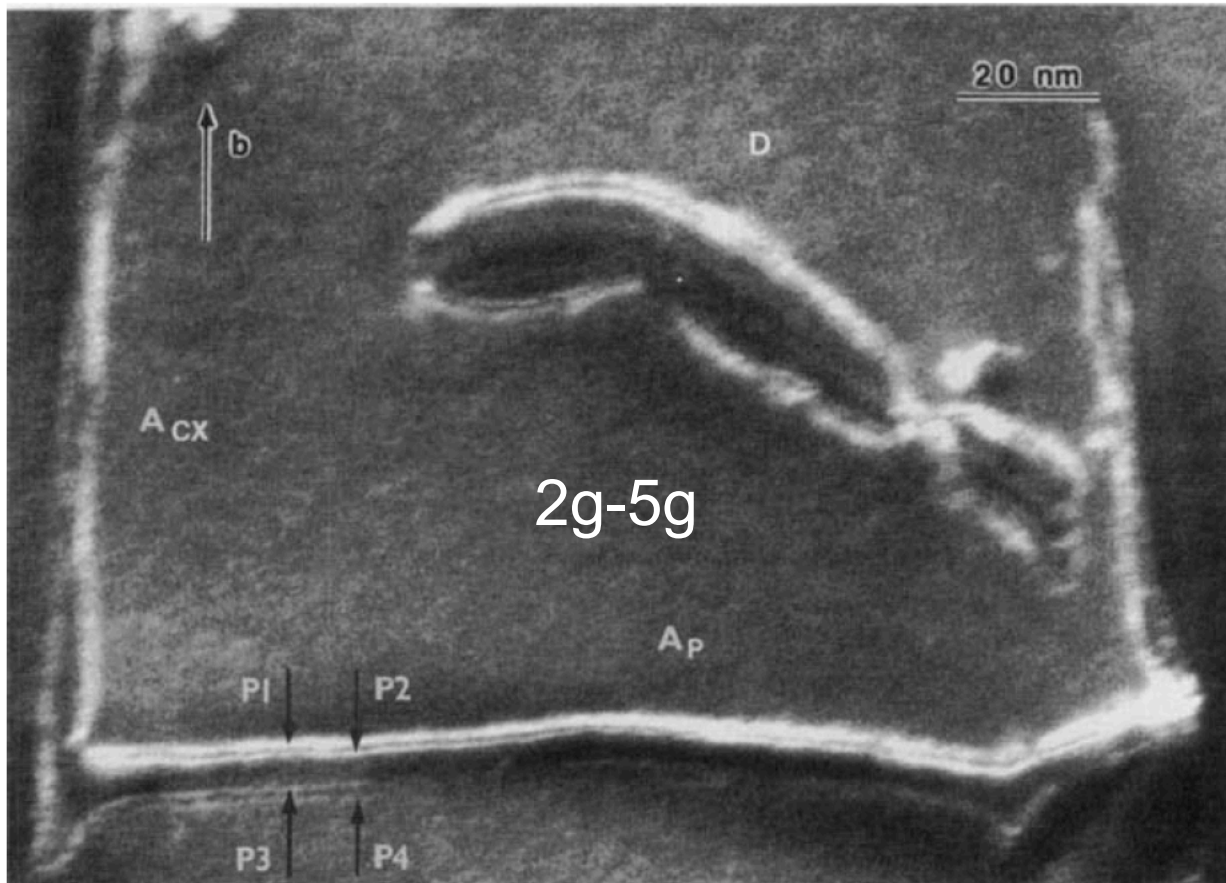
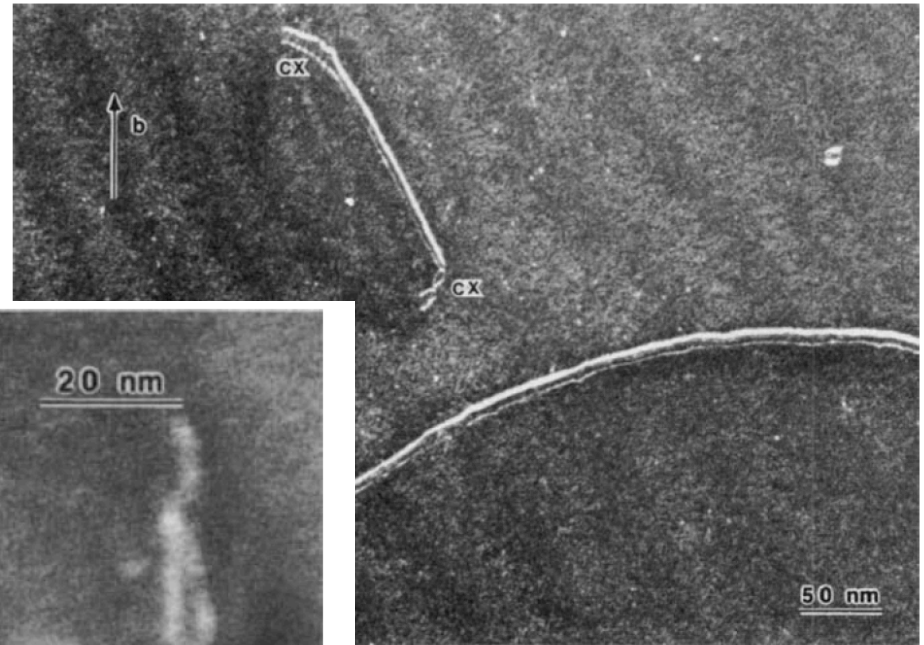


FIGURE 27.8. A comparison of dislocation images in a Cu alloy formed using (A) WB and (B) strong-beam ($s_g > 0$) conditions.

“Conventional” Diffraction Contrast

- Weak beam imaging
 - APB coupled a $\langle 101 \rangle$ dislocations in Ni₃Al

Baluc, et al, Phil Mag 64 (1991)

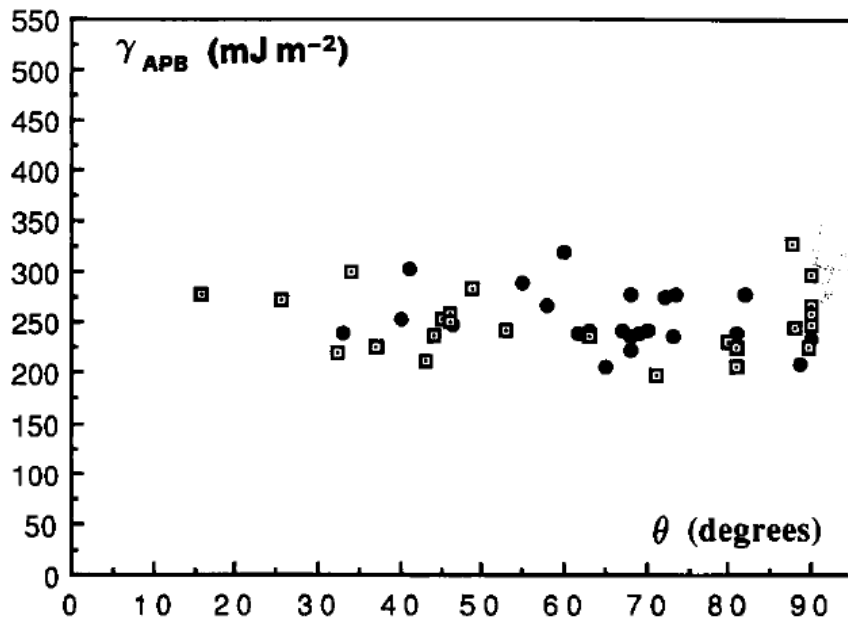
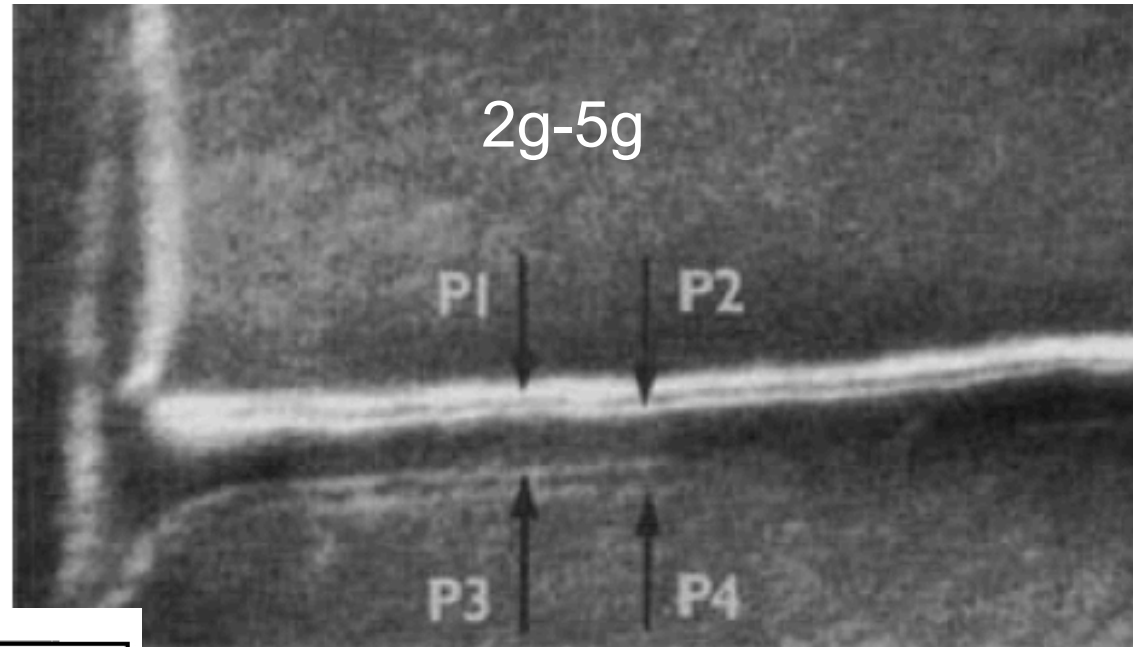


Large deviation parameters enable imaging of fine details associated with defect strain fields

“Conventional” Diffraction Contrast

- Weak beam imaging
 - APB coupled a<101> dislocations in Ni₃Al

Baluc, et al, Phil Mag 64 (1991)



Large deviation parameters enable imaging of fine details associated with defect strain fields

Conventional Diffraction Contrast – Drawbacks

- Very thin specimens required:
 - Absorption and chromatic aberration of post-specimen lenses
- Very flat foils required to insure precise diffraction conditions
- For fine detail, weak beam conditions:
 - Large contrast but weak intensities
 - Long exposure times = “Shooting in the dark”
 - Drift, sample stability and contamination

Advances in high brightness sources have not benefitted diffraction contrast defect studies

New Generation STEMs *Not* Optimal for CTEM

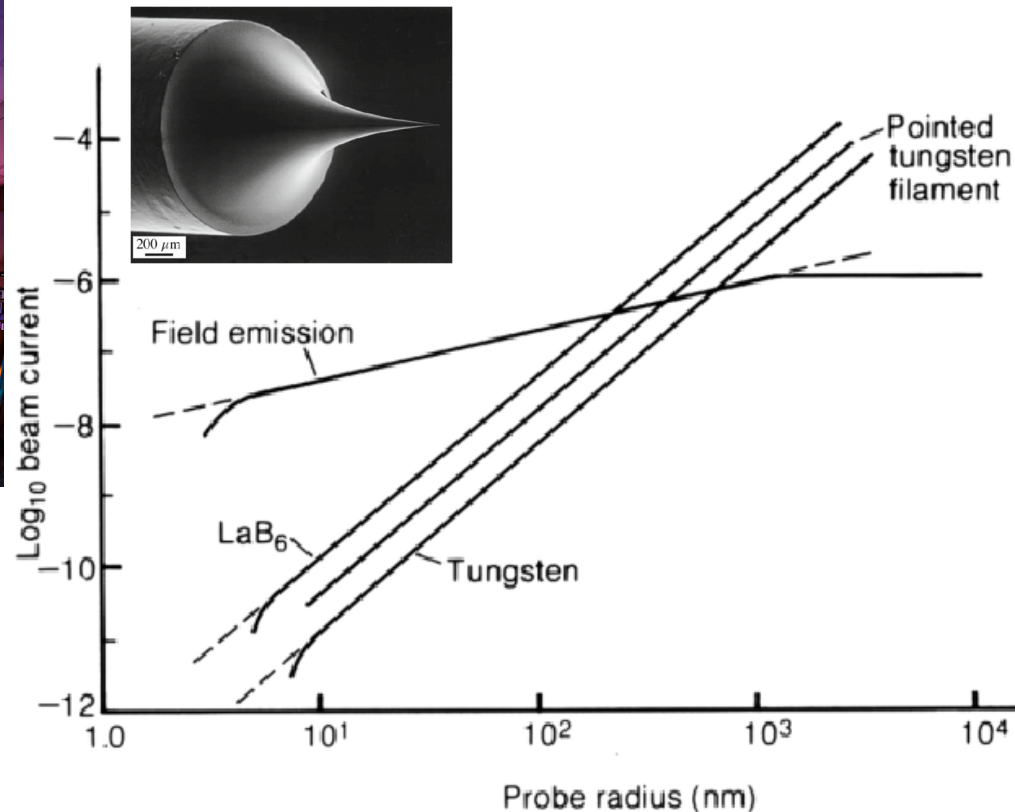


Figure 1.8. Beam current versus probe radius for various electron sources. Data obtained from Veneklasen (1972) and Joy (1974).

- Field emission guns far superior to thermionic emitters for fine-probe STEM and chemical analysis

Conventional Diffraction Contrast – Drawbacks

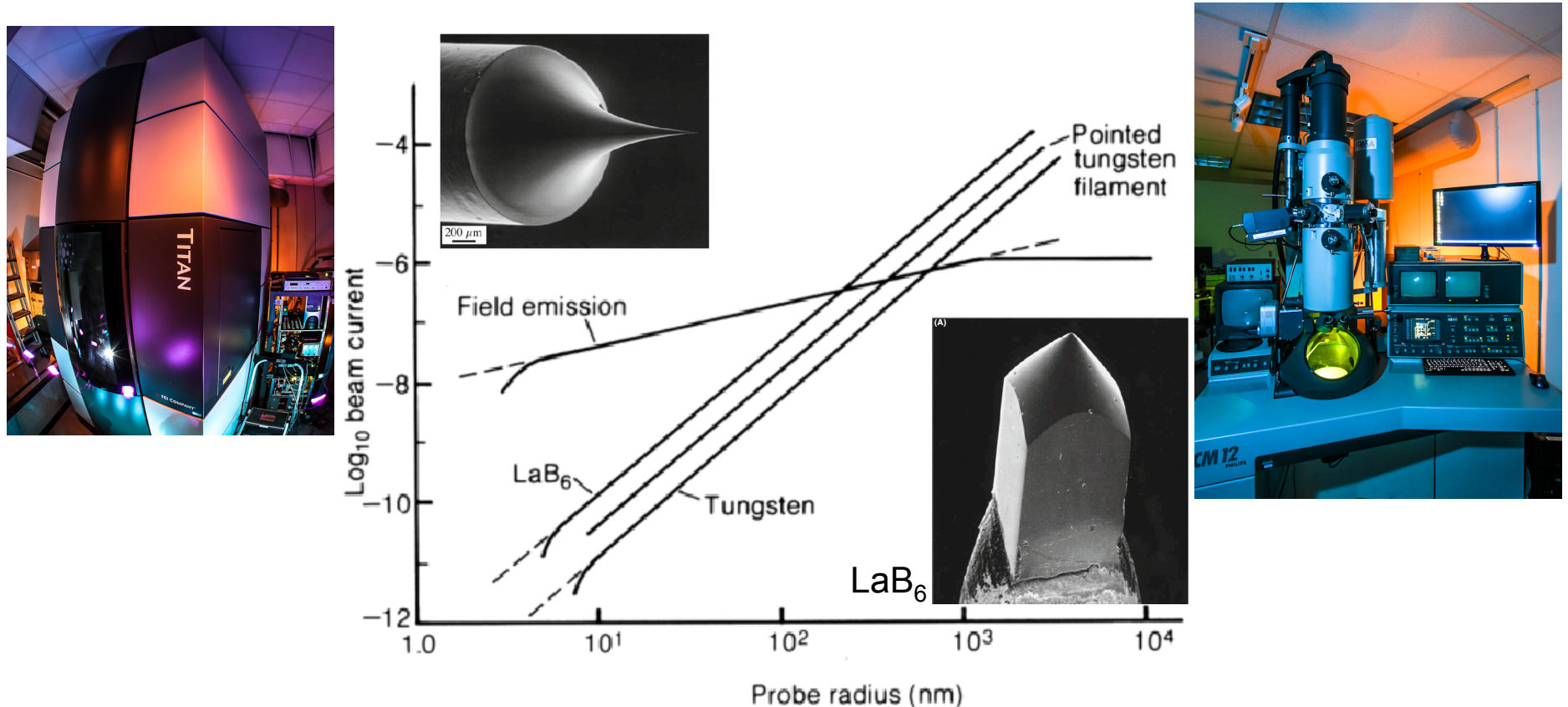
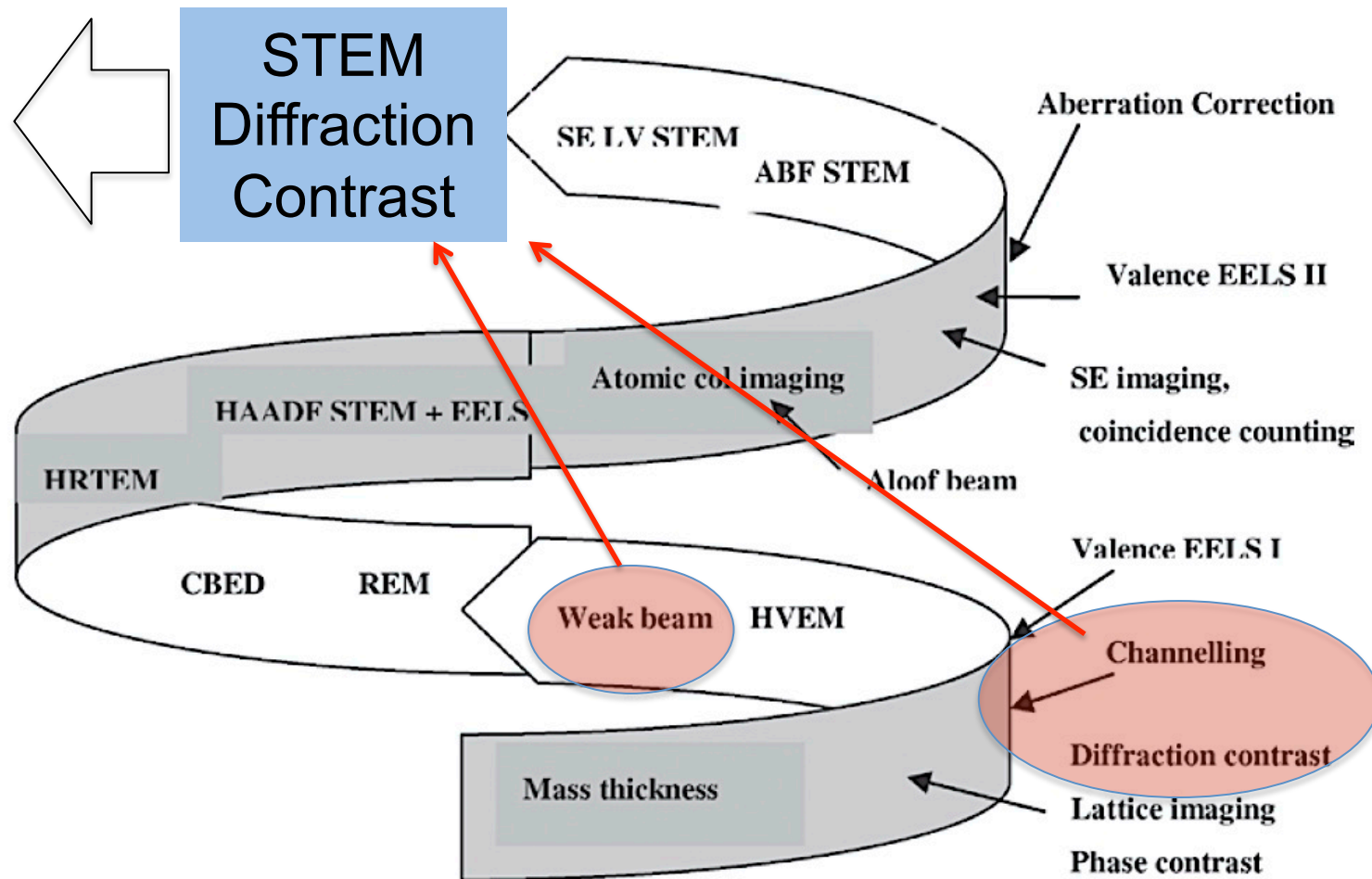


Figure 1.8. Beam current versus probe radius for various electron sources. Data obtained from Veneklasen (1972) and Joy (1974).

- LaB₆ provides better current density for conventional (and weak beam) imaging !!
- Field emission guns far superior to thermionic emitters for fine-probe STEM and chemical analysis

“Revised” Spiral History of TEM

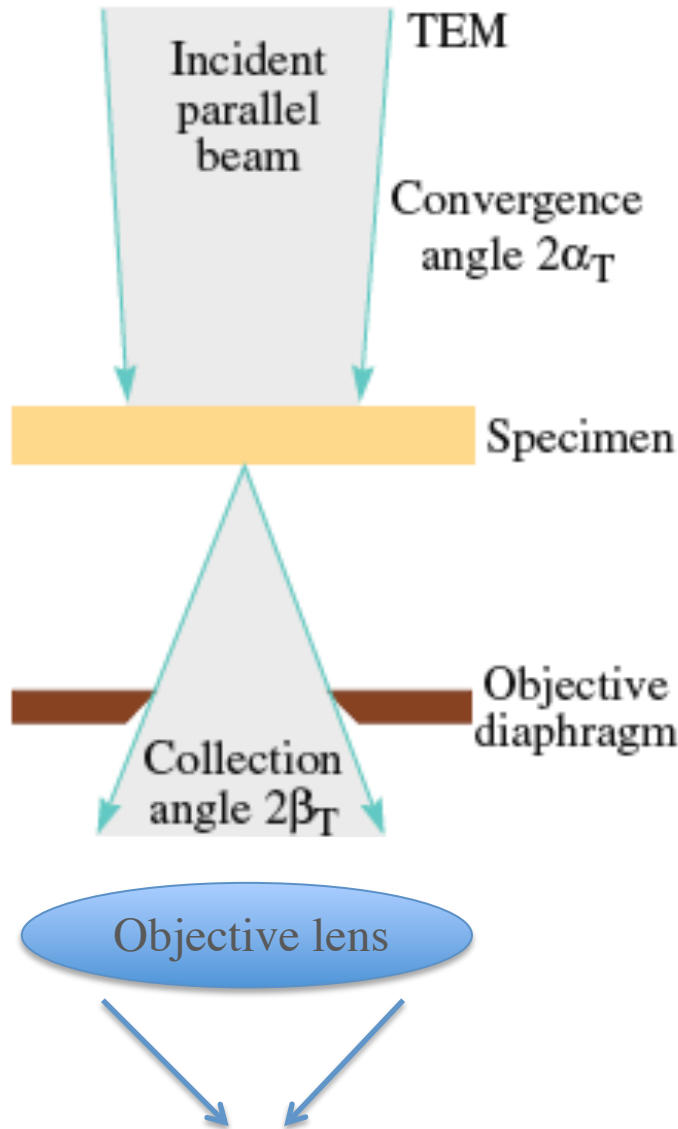
A. Howie, M&M Proceedings, 2012



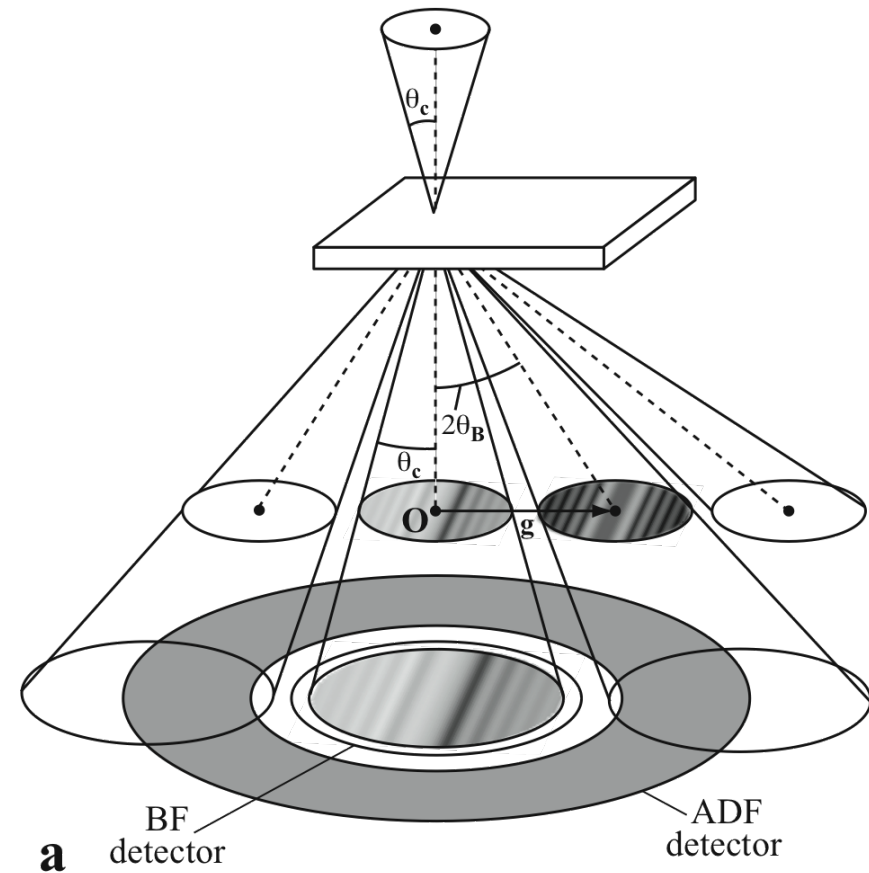
Advances in high brightness sources can benefit diffraction contrast defect studies

“Conventional” vs. STEM Diffraction Contrast

Williams and Carter



*PJ Phillips, MJ Mills, M De Graef
Phil Mag (2011)*

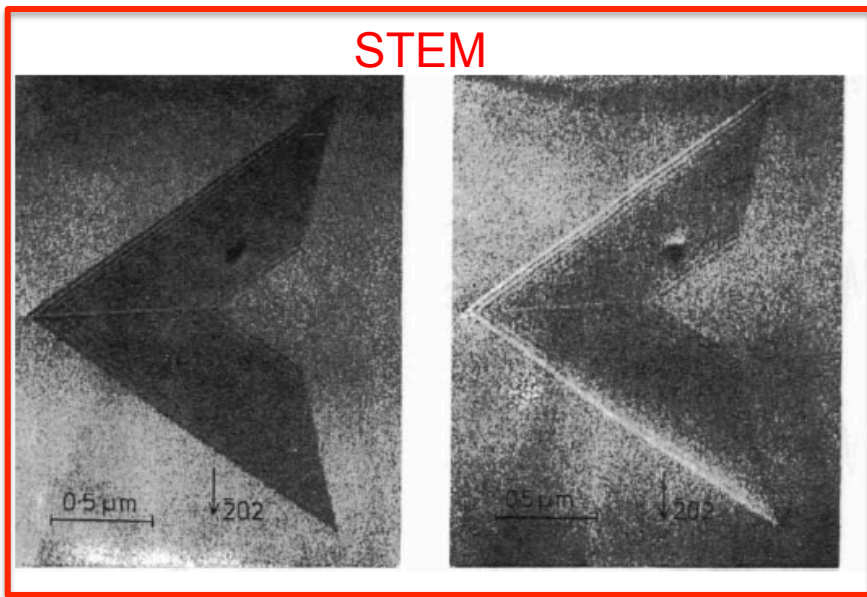
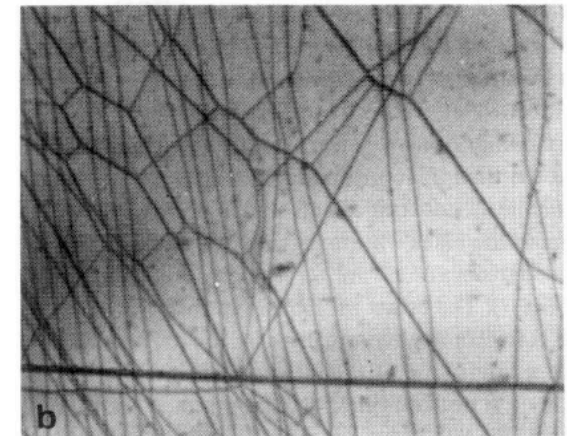
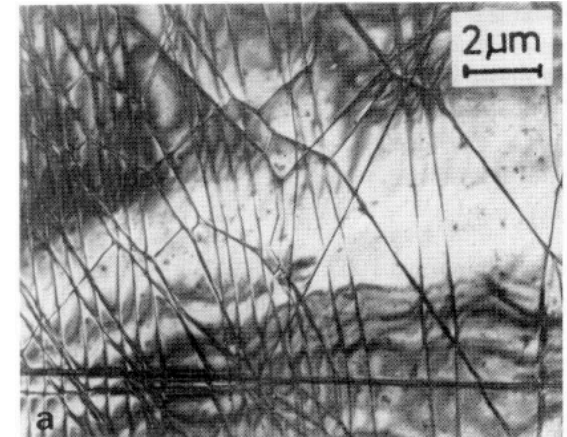


- Underdeveloped technique !
- Significant advantages relative to conventional diffraction contrast

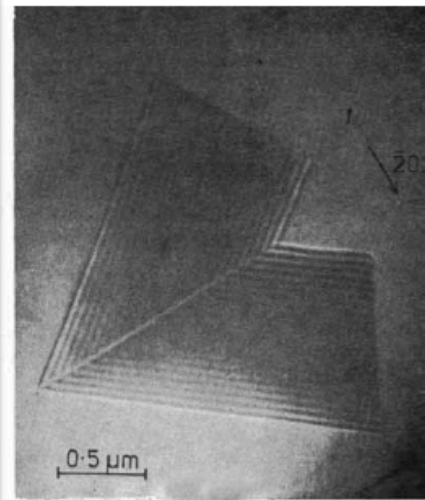
Early STEM Diffraction Contrast Studies



- CJ Humphreys, et al., Proc. of the 5th SEM Symposium (1972) 205-214.
- GR Booker, et al., Proc. of the 7th SEM Symposium (1974) 225-234.
- DM Maher and DC Joy, *Ultramicroscopy*, **1** (1976) 7-12.
- KE Easterling, *J Mater Sci*, **12** (1977) 857-868.
- HL Fraser, et al., *Phil Mag*, **35** (1977) 159-176.



CTEM



Dislocations in bent MoS₂ foil. (a) CTEM, incident beam divergence **0.5 mrad** (b) STEM, detector acceptance angle **5 mrad**. Figure 5 of Humphreys *Ultramicroscopy* **7** (1981) 7-12.

Series of STEM micrographs taken at 200 kV with the 202 diffracting vector indicated. (a) and (b) are a bright-field/dark-field pair taken close to the Bragg condition so that $w \approx 0$. The value of $2\beta_s$ was 1×10^{-2} radians and $2\alpha_s$ was about 1.0×10^{-2} radians. For (c) and (d) which are also a bright-field/dark-field pair the value of $2\beta_s$ was reduced to 3.5×10^{-3} radians. For all these micrographs the electron beam direction **B** was close to [111]. A CTEM image of the same fault with **B** close to [141] is shown in (e). The top surface (T) and bottom surface (B) of the foil are marked.

“Conventional” Diffraction Contrast

- Bend contours limit defect visibility

Williams and Carter

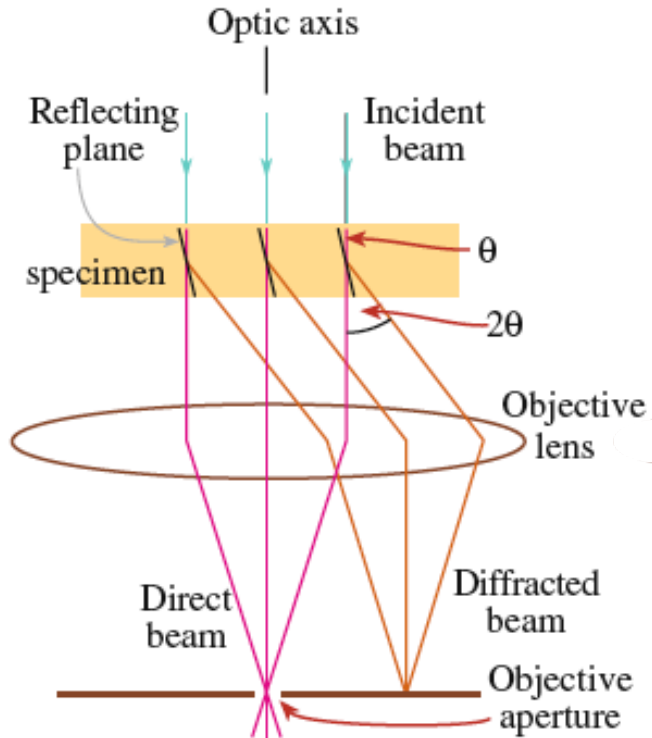
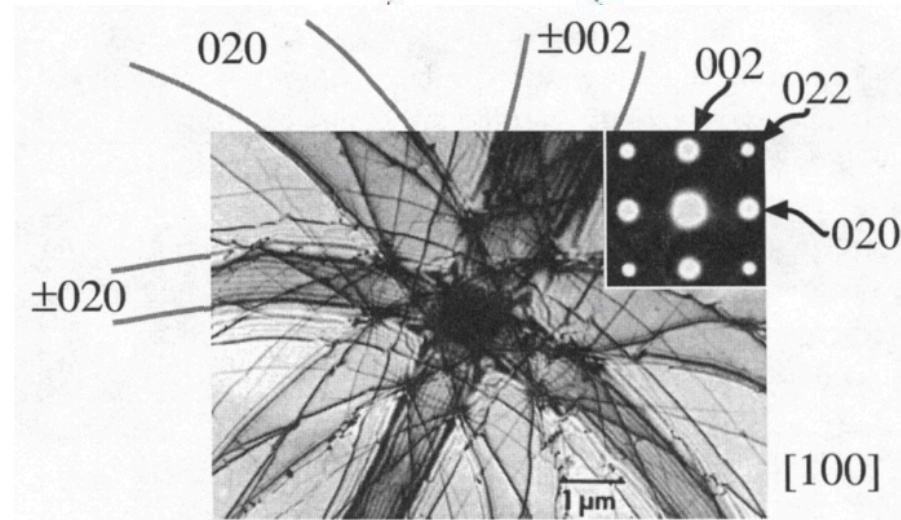
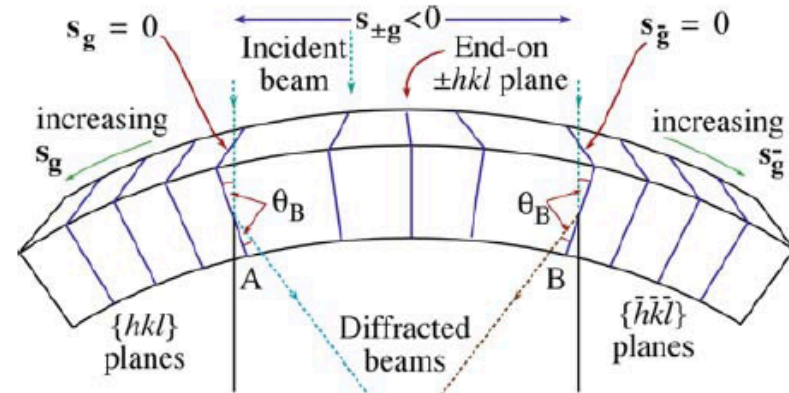
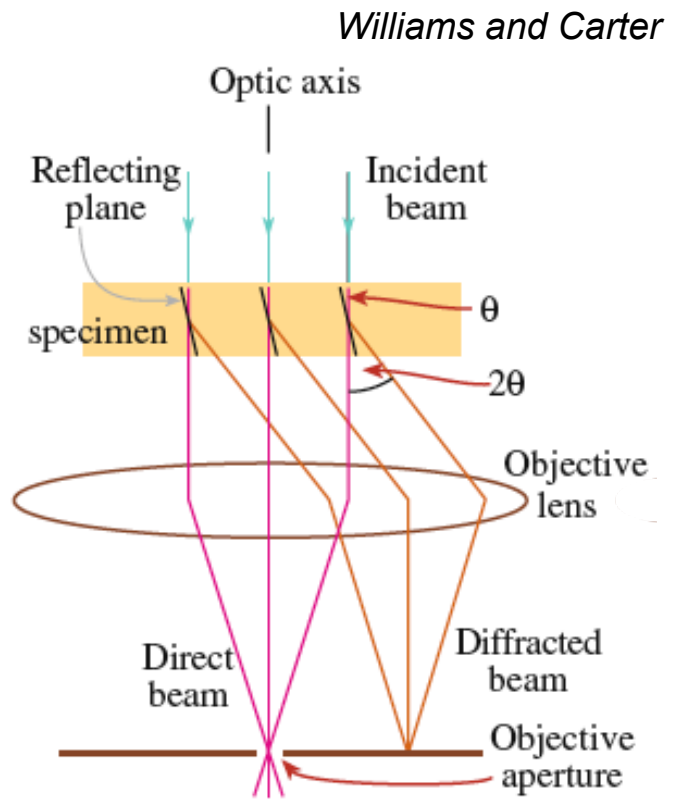


Image Formation

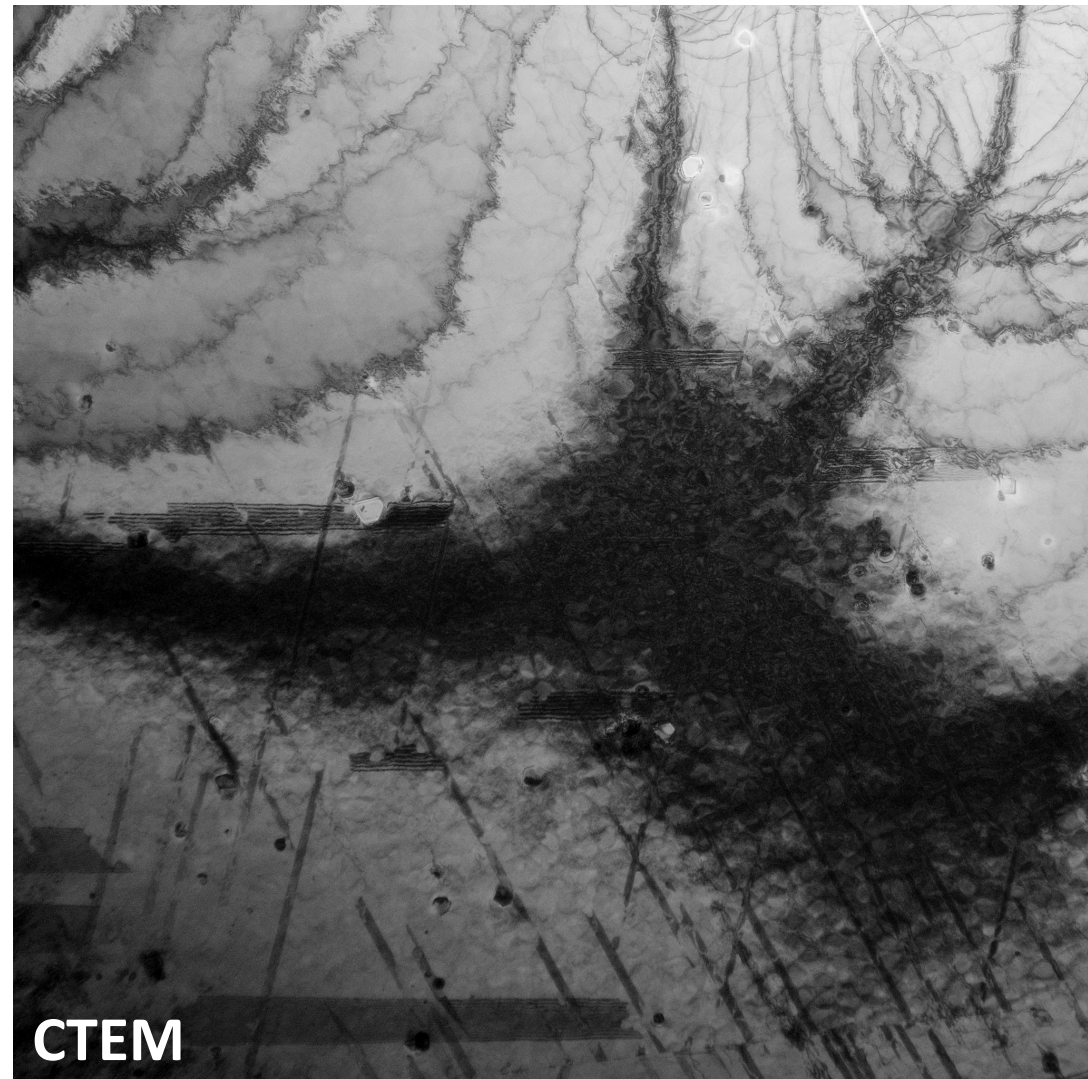


“Conventional” Diffraction Contrast

- Bend contours limit defect visibility

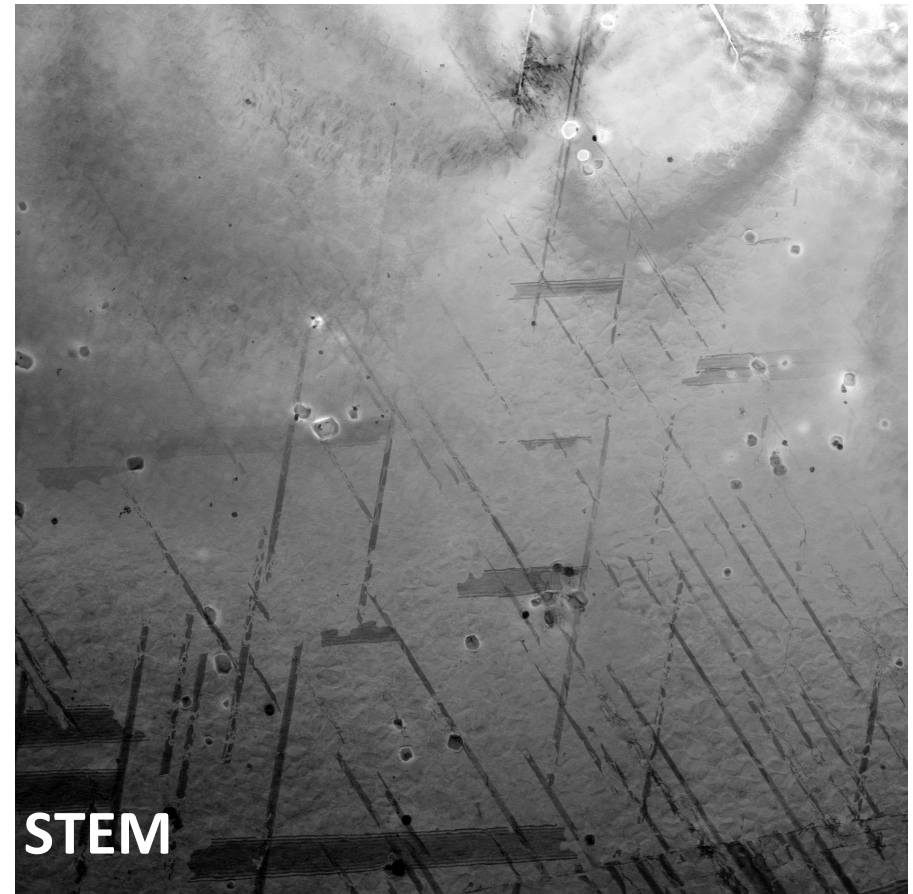
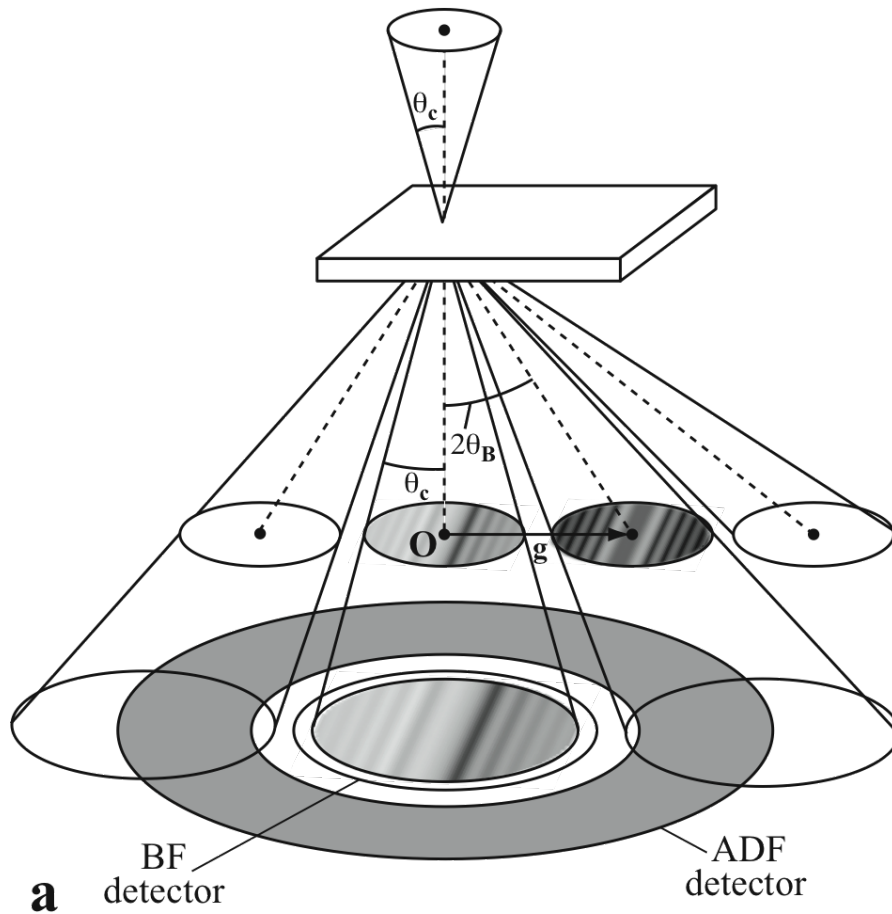


*Image
Formation*



Advantage 1: Minimize Bend Contour Effects

- Bend contours and defect visibility



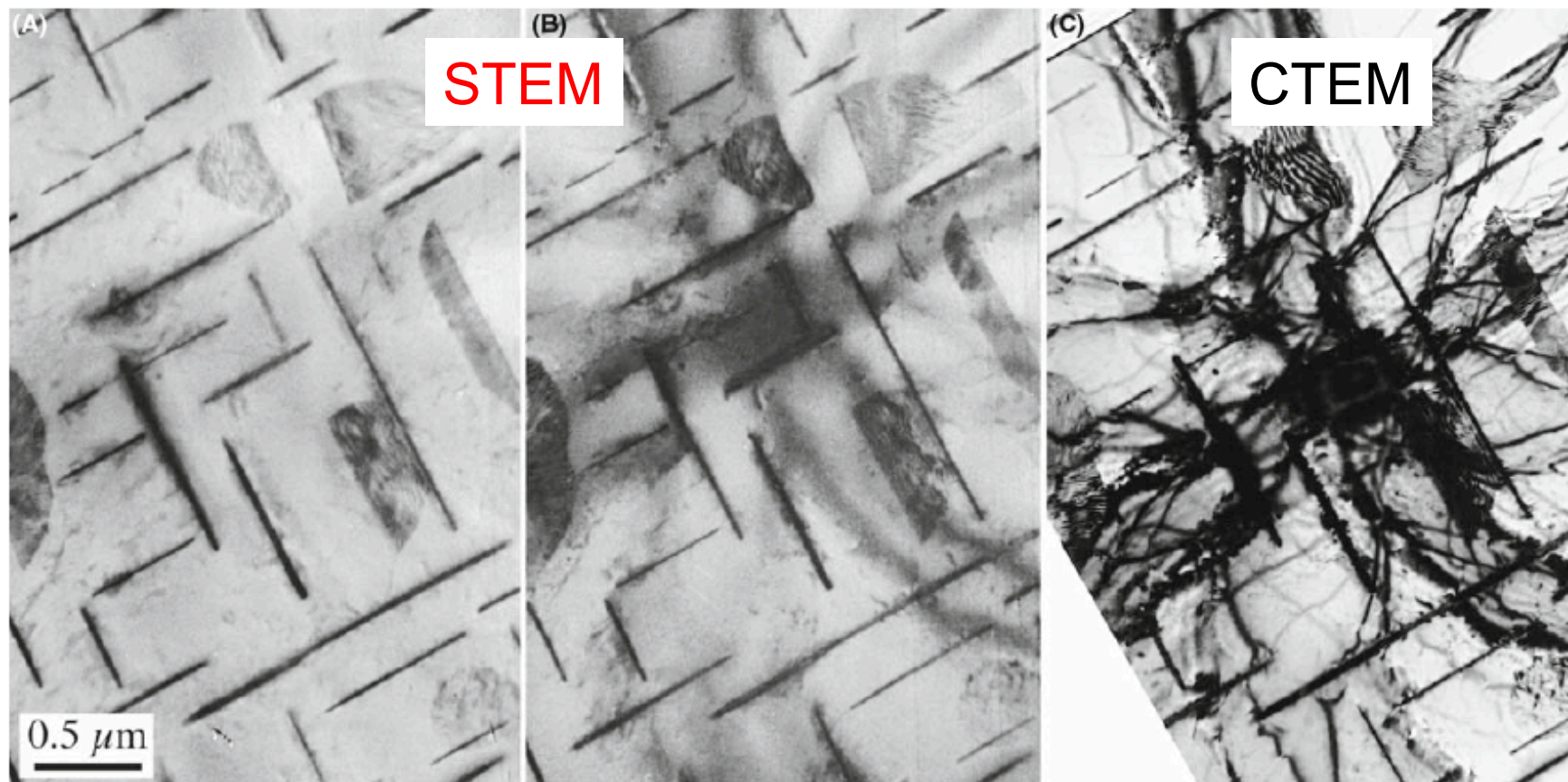
Converged beam “mutes” bend contours but reveals dislocation and stacking fault contrast

“Conventional” vs. STEM Diffraction Contrast



- STEM Images in Al-4Cu alloy as function of collection angle

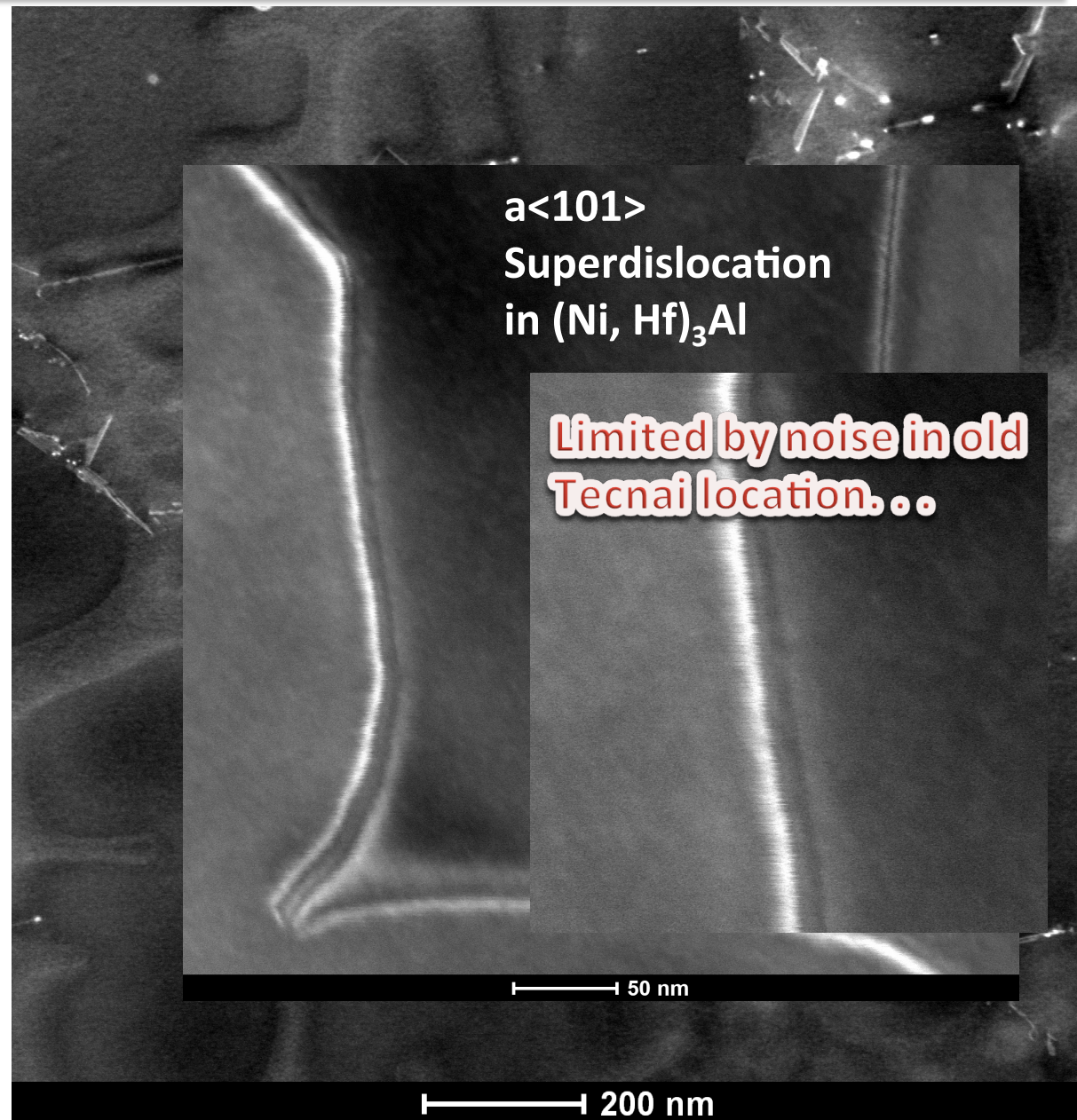
Williams and Carter



- As collection angle decreases, approach conventional diffraction contrast condition
- “Compares unfavorably to TEM images...”
- “Imaging crystal defects is solely the domain of TEM...”

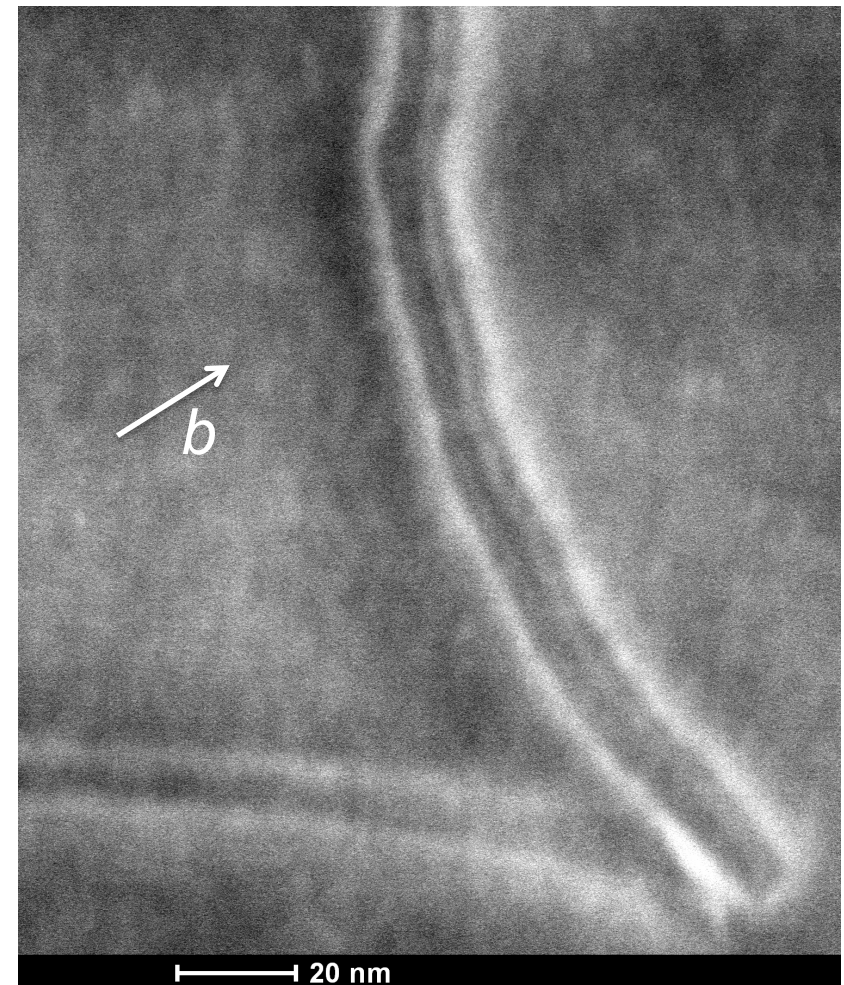
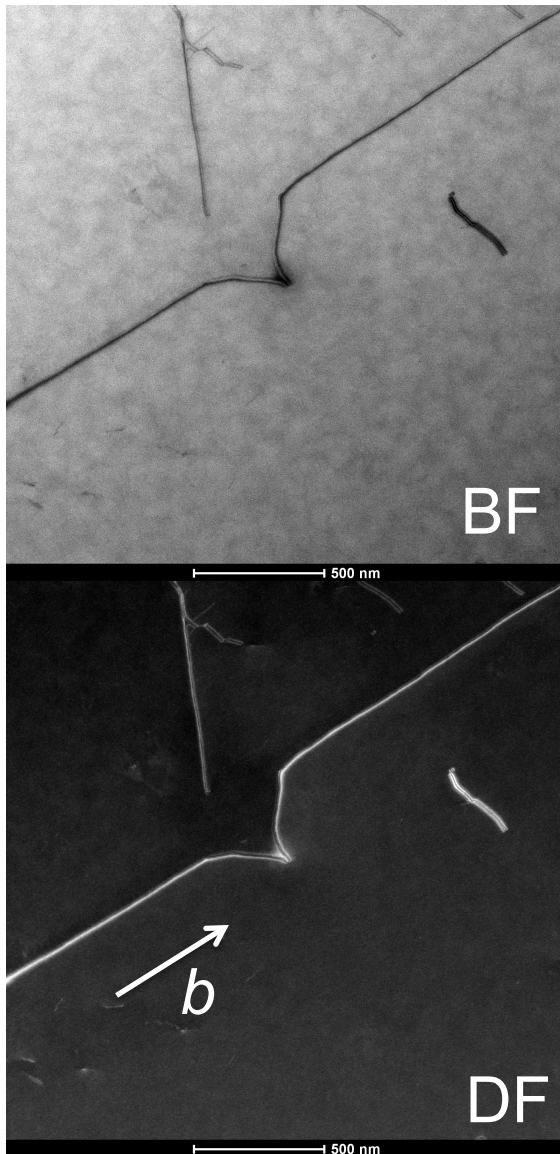
Advantage 2: Higher Order g Imaging of Strain Fields

- **Higher Order g imaging**
 - similar image contrast to CTEM
 - weak-beam dark field**
 - rapid, simultaneous acquisition of bright field/dark field images
 - fewer limitations than WBDF
 - thicker samples
 - practical applications



Advantage 2: Higher Order g Imaging of Strain Fields

a<101> Superdislocation in (Ni,Hf)₃Al

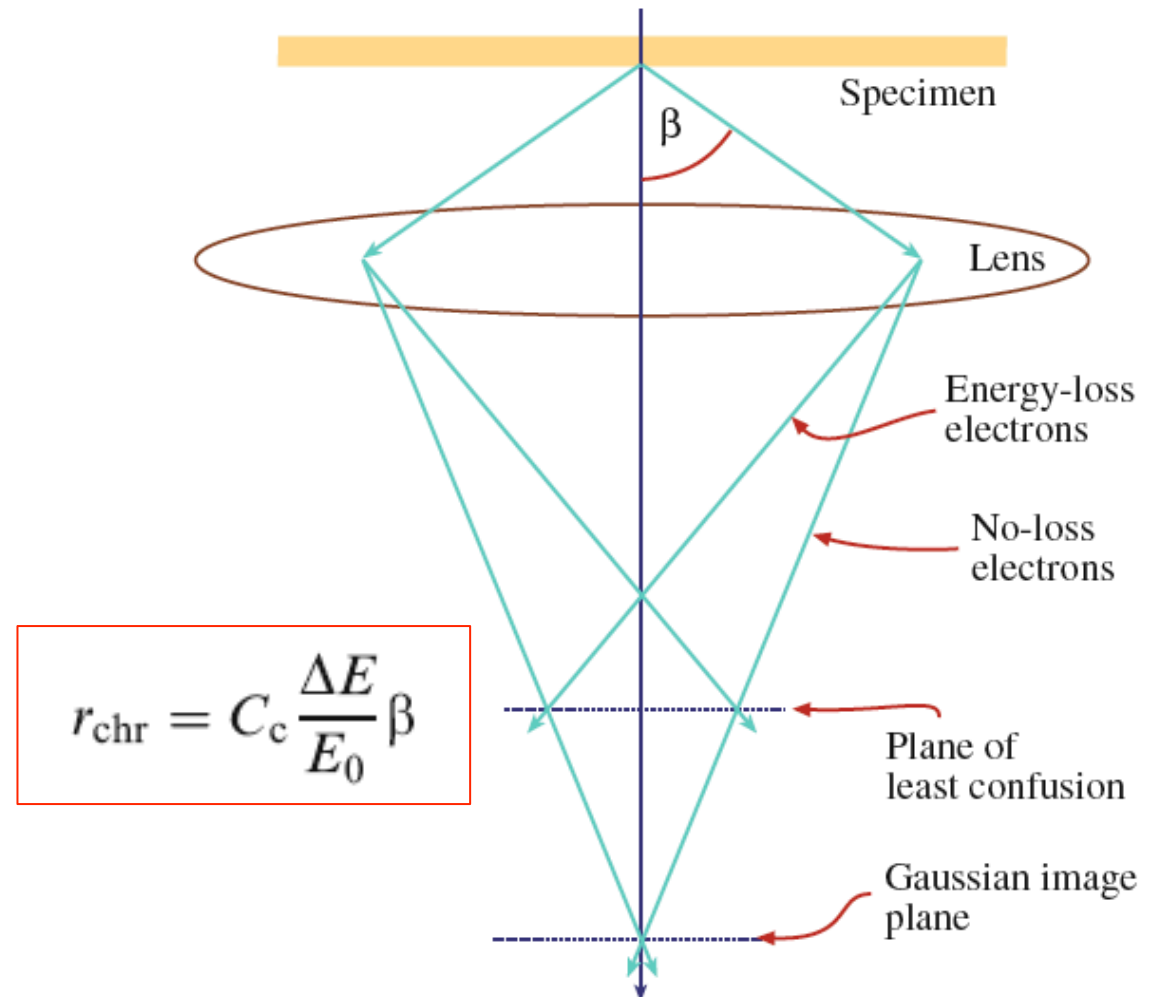


No longer
noise limited
in CEMAS. . .

Advantage 3: Thick Samples Can Be Examined

Williams and Carter

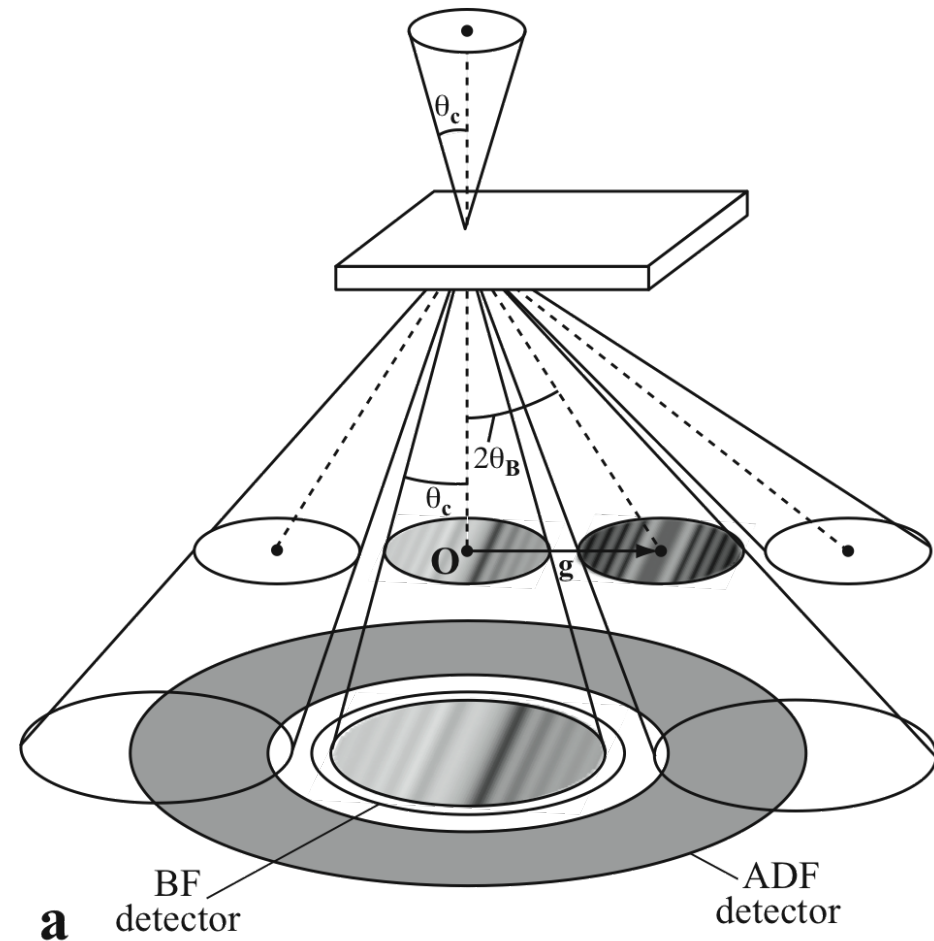
- In CTEM, **loss of resolution** in thicker samples due to chromatic aberration



Advantage 3: Thick Samples Can Be Examined

Williams and Carter

- In CTEM, **loss of resolution** in thicker samples due to chromatic aberration
- In STEM, no post-specimen lenses, thus **chromatic aberrations** normally suffered are non-existent



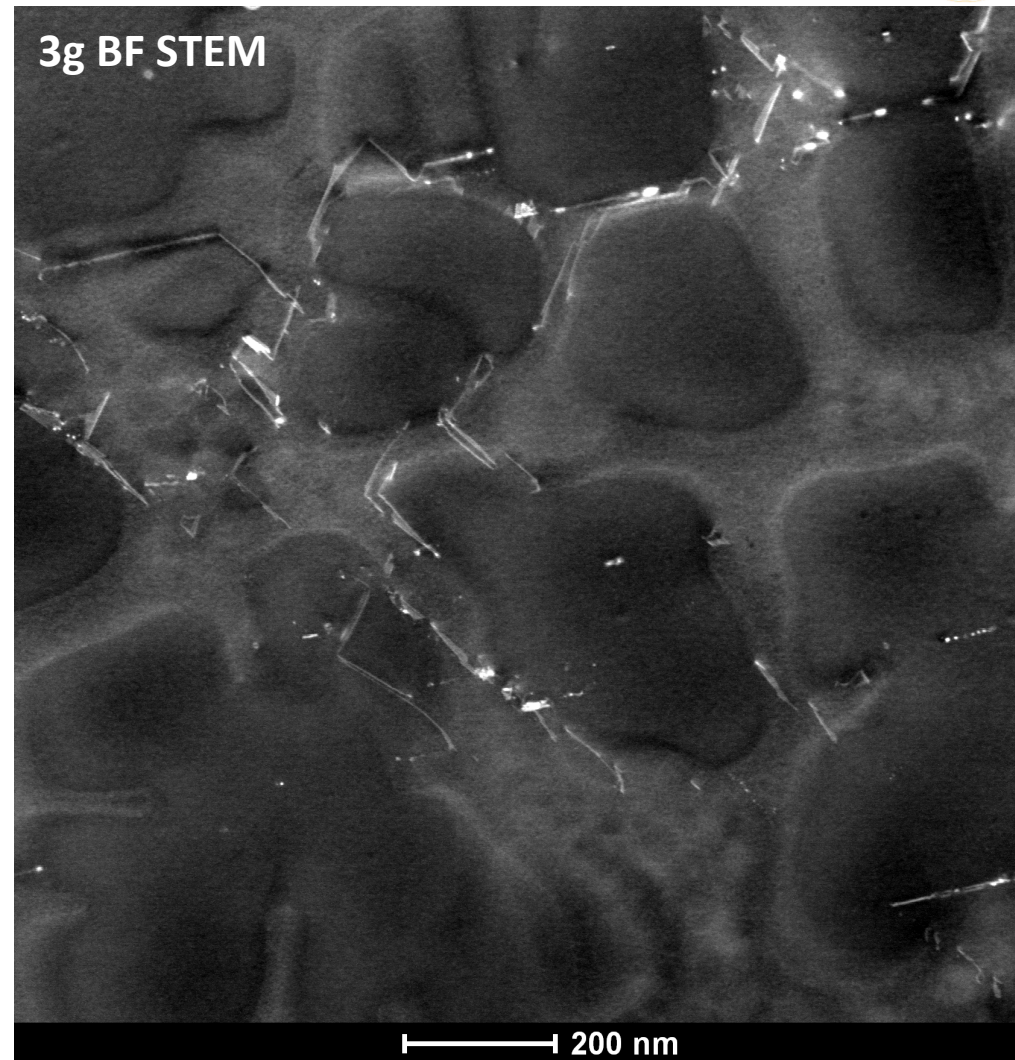
Advantage 3: Thick Samples Can Be Examined



- In CTEM, **loss of resolution** in thicker samples due to chromatic aberration

- In STEM, no post-specimen lenses, thus **chromatic aberrations** normally suffered are non-existent

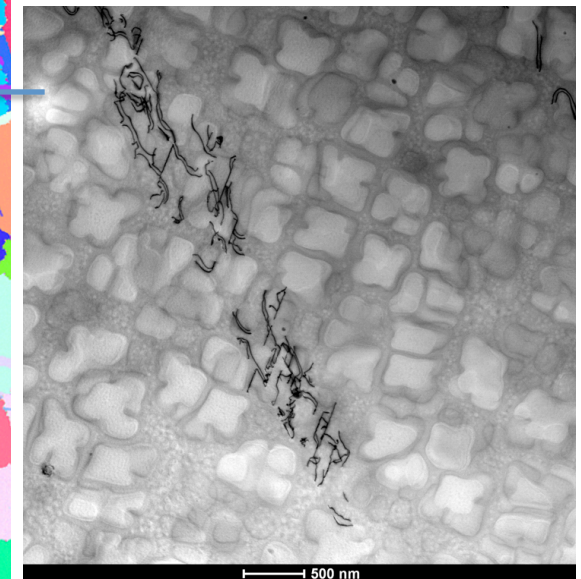
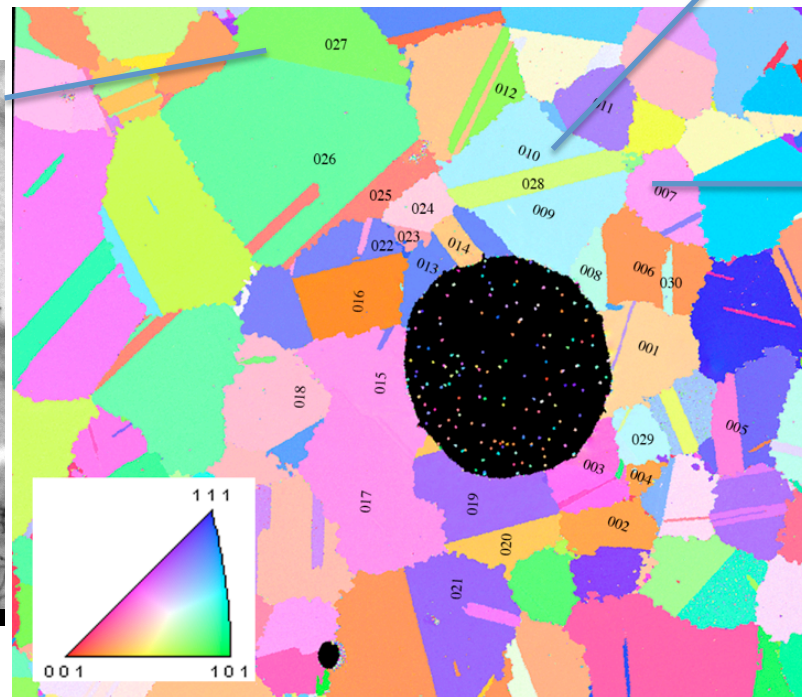
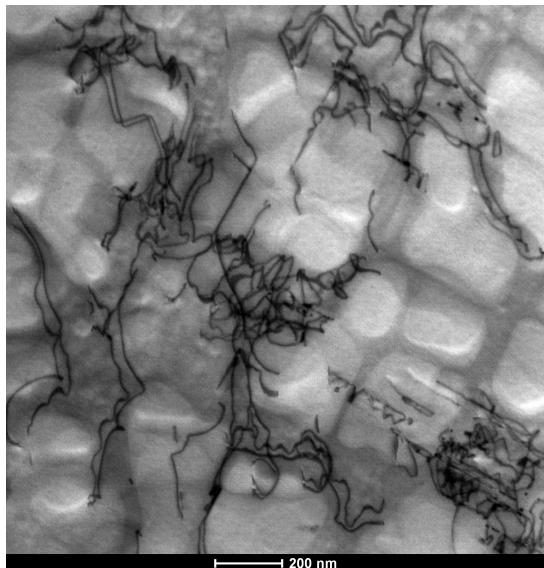
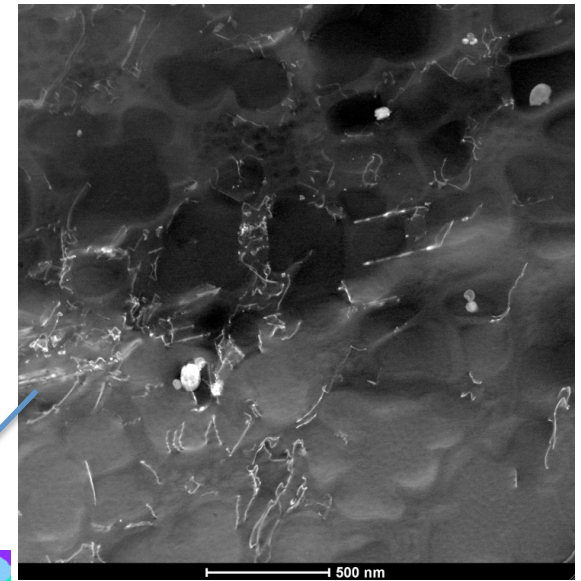
- High brightness FEG sources enable shorter exposure times (less drift)



*370 nm thick specimen of Ni-superalloy
CTEM WBDF also attempted but low intensity
and long exposure times introduced sample drift*

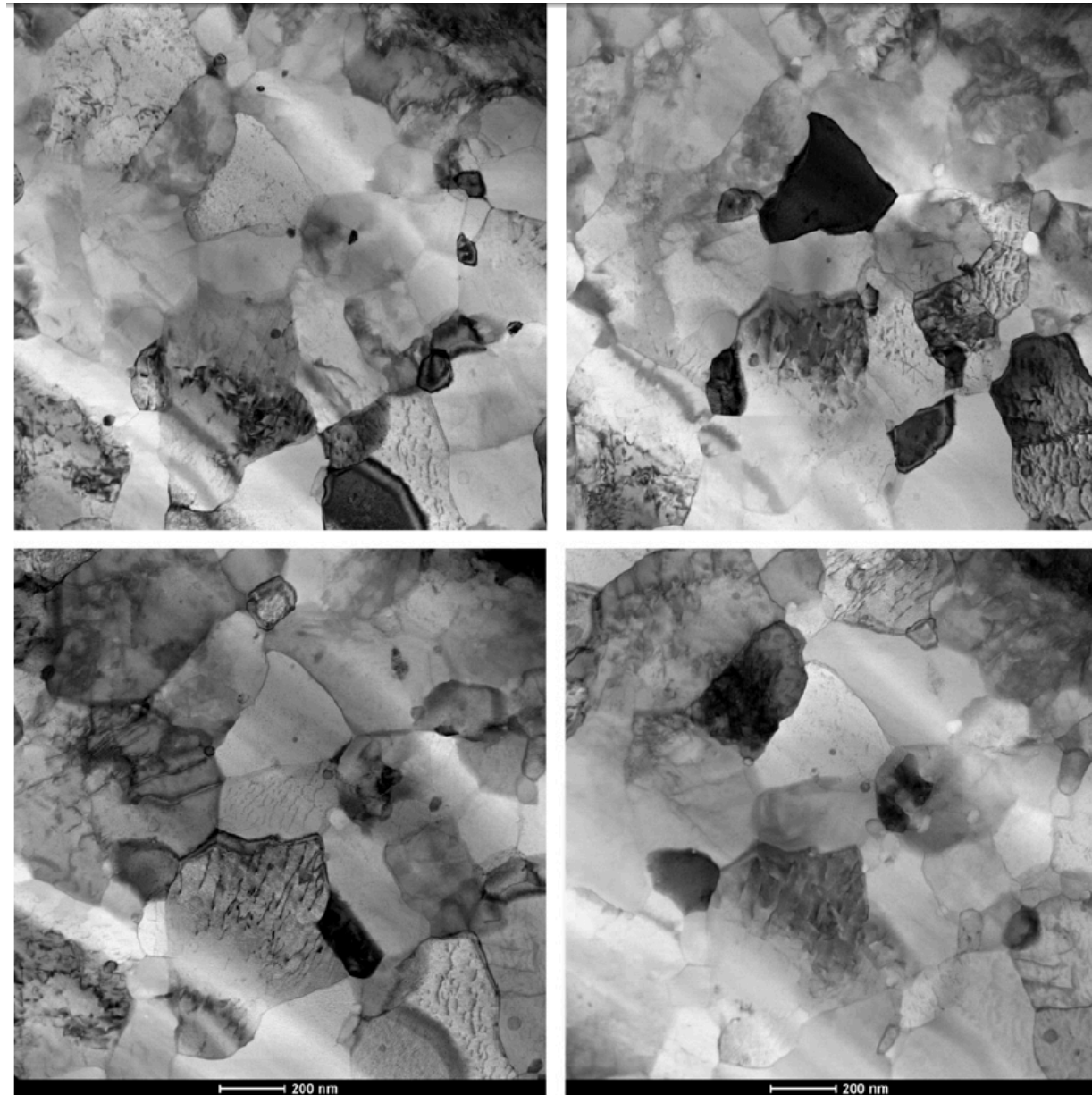
Assessment of Deformation Mechanisms in Commercial Alloys

- Grain-to-grain variation in deformation modes
- Correlate orientation information from specific grains to deformation activity
- Many grains need to be assessed
- STEM diffraction contrast has been crucial due to ability to probe thicker regions



Dislocation Substructure within Ultra-fine Grains

STEM images
obtained at four
different “tilts”
of the sample
for dislocation
density
measurements

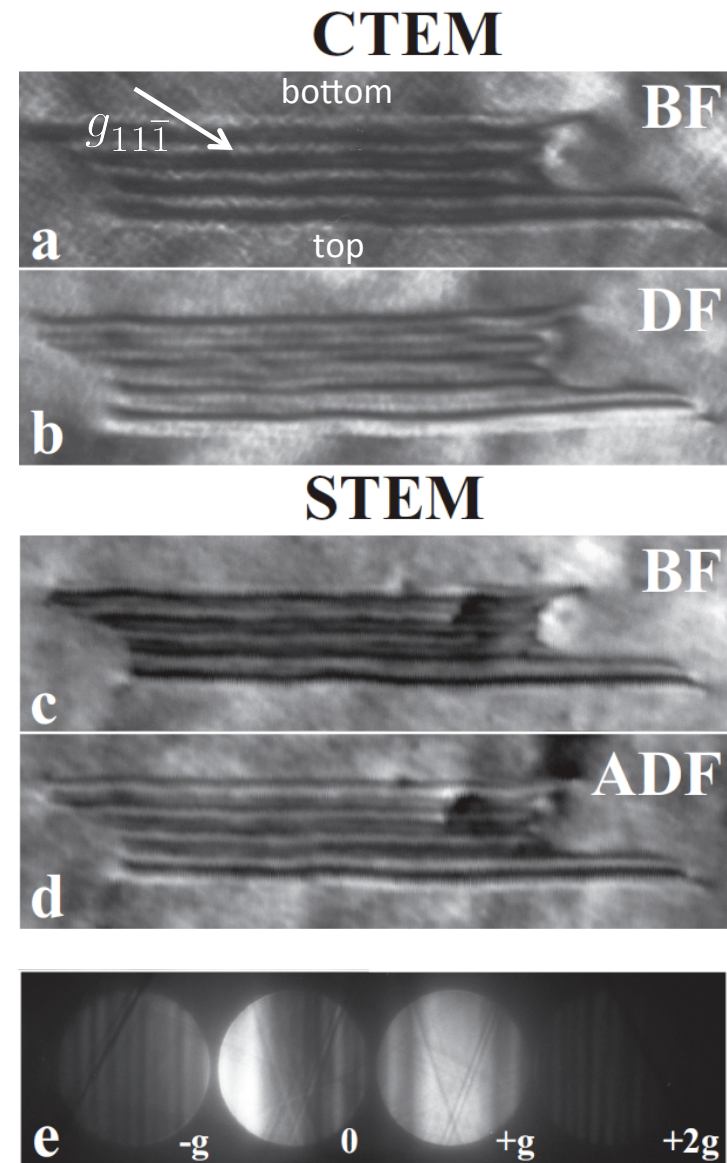


*M. C. Brandes, et al,
Acta Materialia 60
(2011) 1827–1839.*

Defect Analysis with STEM Diffraction Contrast



- Systematic studies in STEM on variety of materials in Tecnai TF20
- Variations in:
 - camera length (CL)
 - convergence angle (θ_c)
 - diffraction aperture placement
- Imaging:
 - two-beam diffraction
 - **3g**
 - zone axis orientation
- Promising but need simulations to support apparent capabilities / advantages



CTEM vs. STEM Diffraction Contrast

- Previously instrumentation made STEM an inefficient and impractical tool for defect analysis

- Tungsten or LaB_6 source
- Low intensities, long exposures
- Now, FEG sources readily available
- Digital imaging capabilities

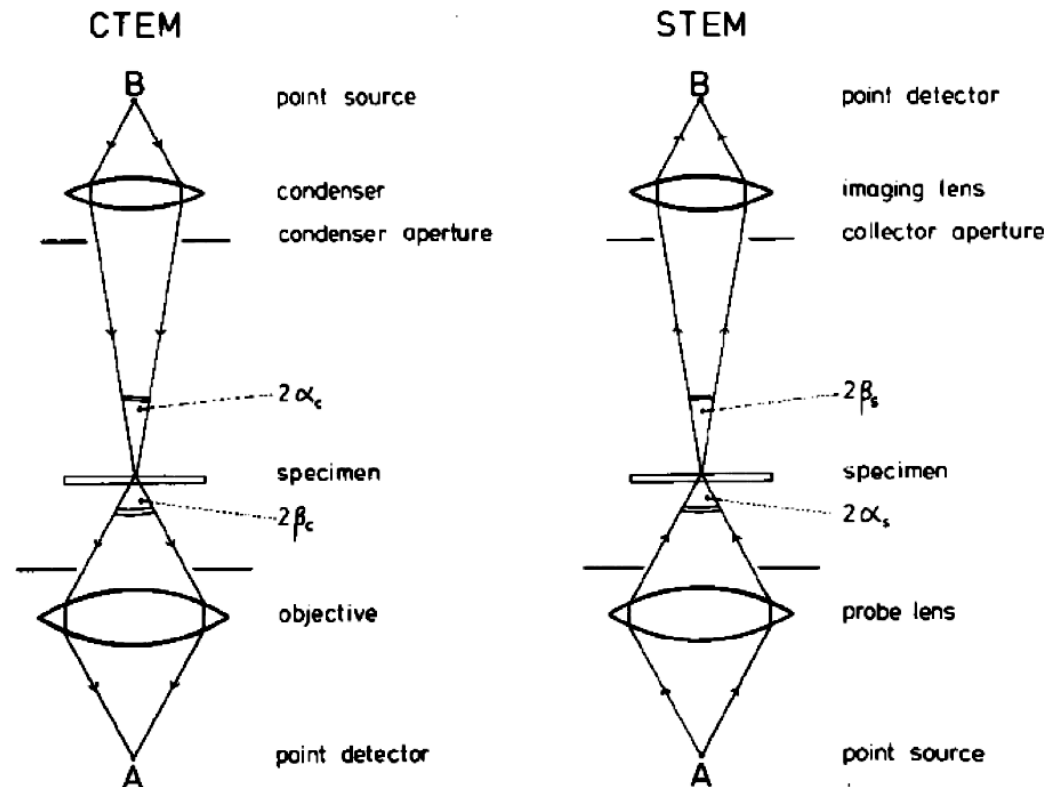
- Reciprocity:

$$\alpha_s = \beta_c$$

$$\beta_s = \alpha_c$$

not generally applicable to STEM image interpretation

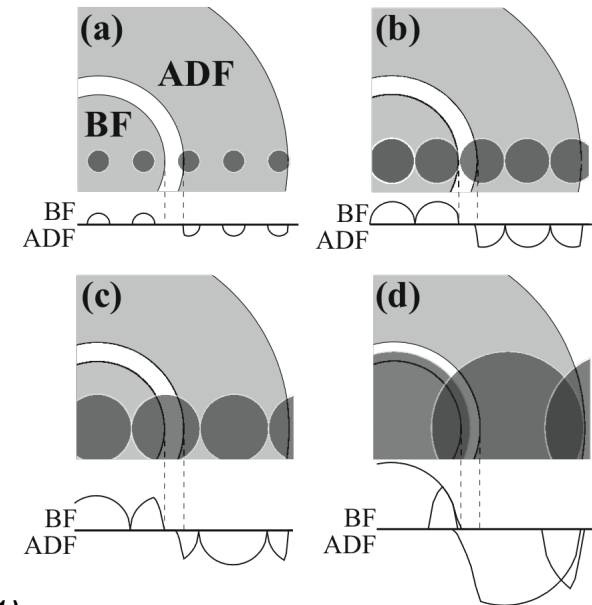
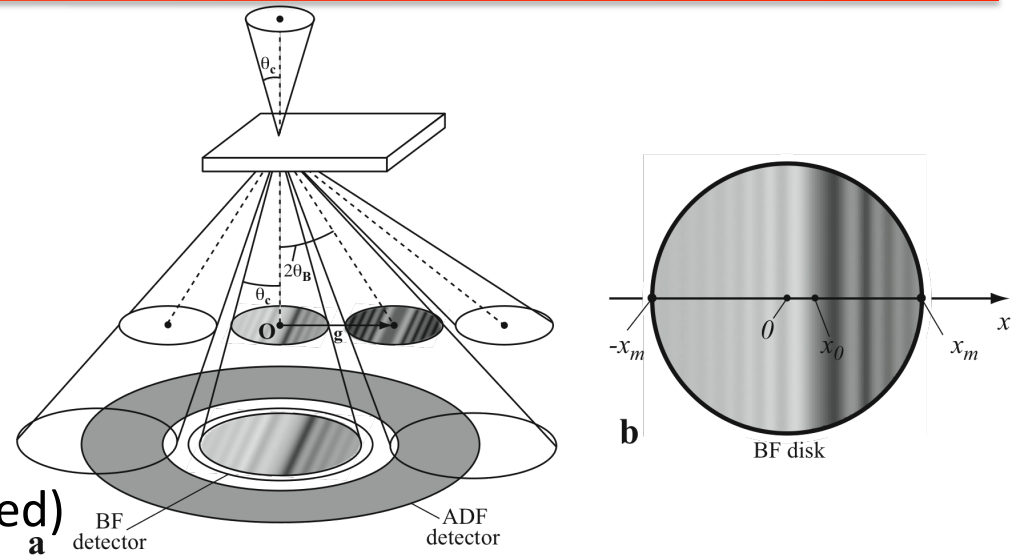
- Simulation capability required to support promising results



$$\beta_s \approx 10\alpha_c$$

Simulation of STEM Diffraction Contrast

- Depending on imaging conditions, reciprocity may not hold
- Need **computational** validation of contrast rules for interpreting defect images:
 - Diffraction condition changes across disks (transmitted/diffracted)
 - Each incident beam orientation averaged according to appropriate weight factor
 - Length of chord perpendicular to systematic row
 - **Scattering matrix approach utilized (much faster than conventional solution of DHW)**



PJ Phillips, MJ Mills, M De Graef, *Phil. Mag.* **91** 2081-2101 (2011)

PJ Phillips, MC Brandes, MJ Mills, M De Graef, *Ultramicroscopy* **111** 1483-1487 (2011)

Background on Scattering Matrix Approach



- Darwin-Howie-Whelan multibeam equations
 - describe how the amplitude of a diffracted beam changes with depth in the crystal
 - changes depend on Bragg condition and strengths of interactions with other beams

$$\frac{dS_{\mathbf{g}}(z)}{dz} = 2\pi i s_{\mathbf{g}} S_{\mathbf{g}}(z) + i\pi \sum_{\mathbf{g}'} \frac{e^{-i\alpha_{\mathbf{g}-\mathbf{g}'}(\mathbf{r})}}{q_{\mathbf{g}-\mathbf{g}'}} S_{\mathbf{g}'}(z),$$

- With defects:

$$\alpha_{\mathbf{g}}(\mathbf{r}) \equiv 2\pi \mathbf{g} \cdot \sum_{i=1}^{N_d} \mathbf{R}_i(\mathbf{r}) = 2\pi \mathbf{g} \cdot \mathbf{R}_t(\mathbf{r});$$

- Writing the diffracted amplitudes S_n as column vector gives:

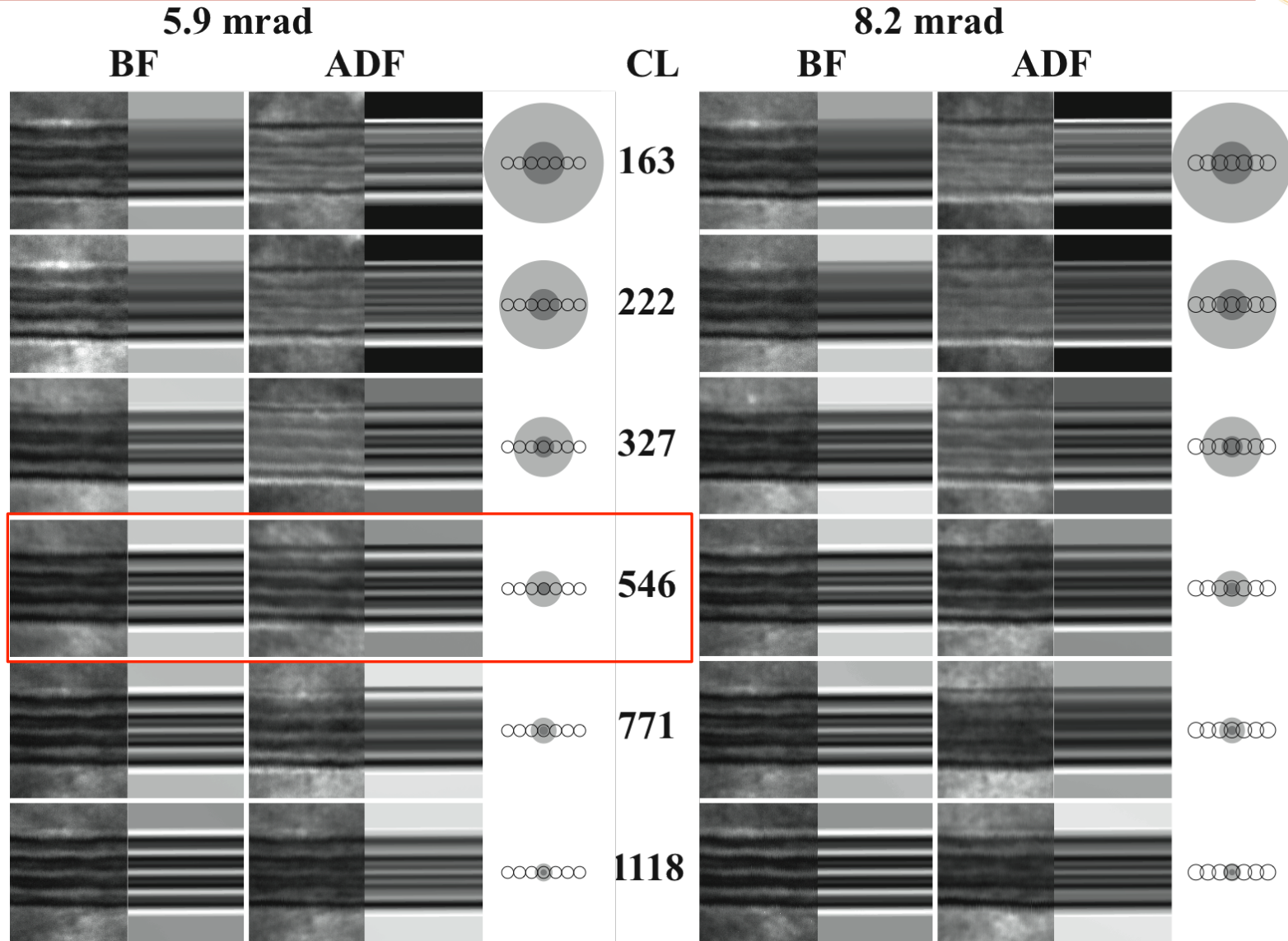
$$\frac{d\mathbf{S}(z)}{dz} = i\mathcal{A}(\mathbf{r})\mathbf{S}(z) \longrightarrow \text{Scattering matrix}$$

↓
*Crystal transfer or
structure matrix*

which separates the diffraction geometry and the coupling of diffracted beams

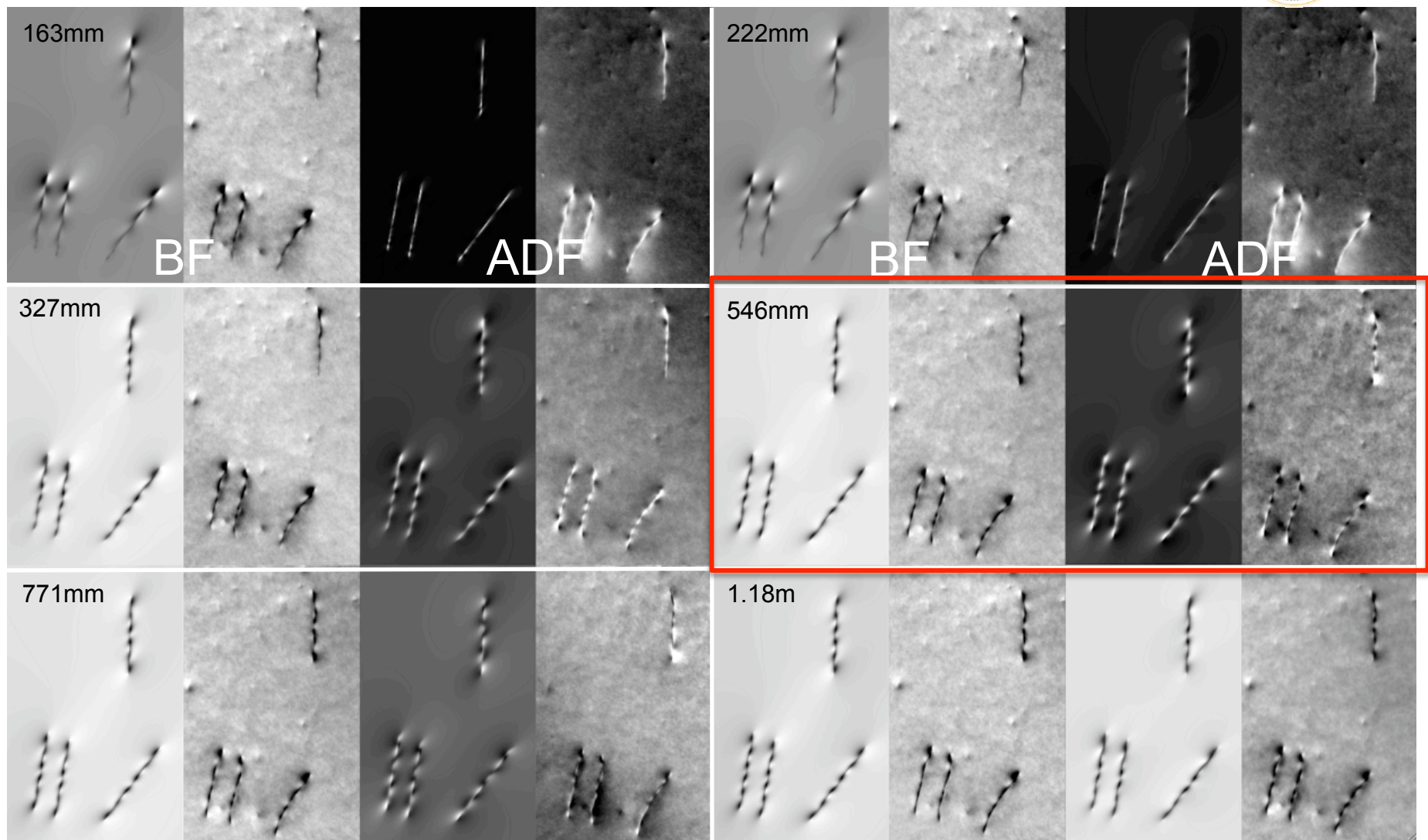
- Matrix diagonal contains excitation errors of all scattering beams while off-diagonal components describe interactions between all the beam through the q parameter, which are *phase-shifted* in the presence of defects

Observed and Simulations for Stacking Faults



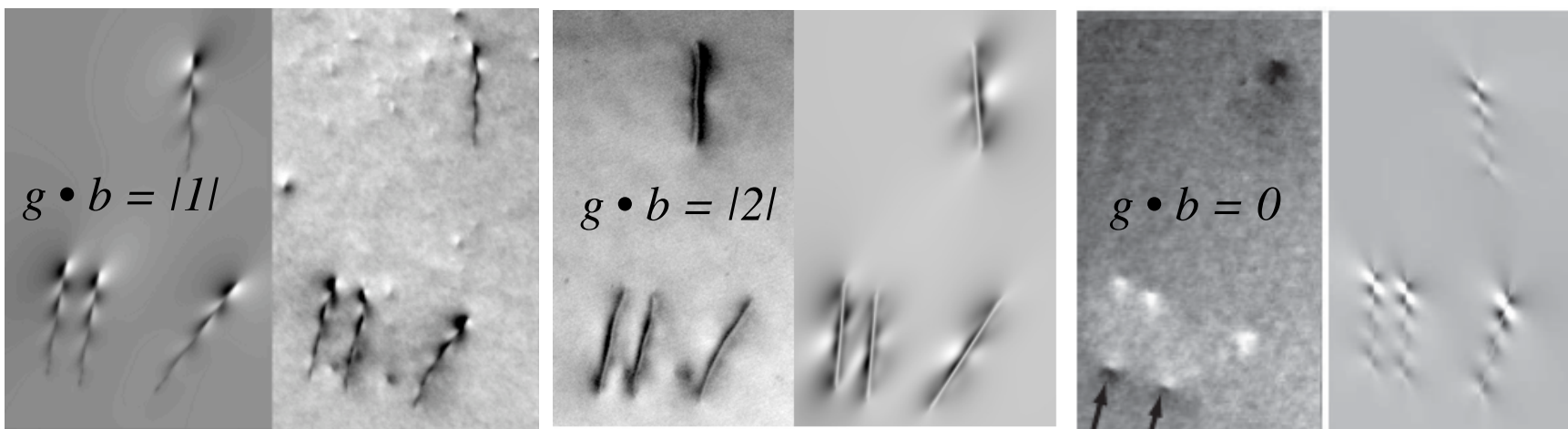
- General fringe pattern consistent in nearly all cases; this is critical for SF analysis
- At “optimal” CL, fault is symmetric/asymmetric in BF/ADF (as in CTEM)

Dislocations in Ti (g_{10-11})

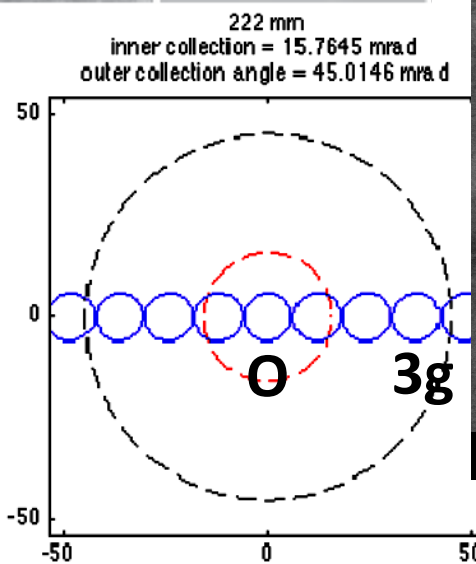
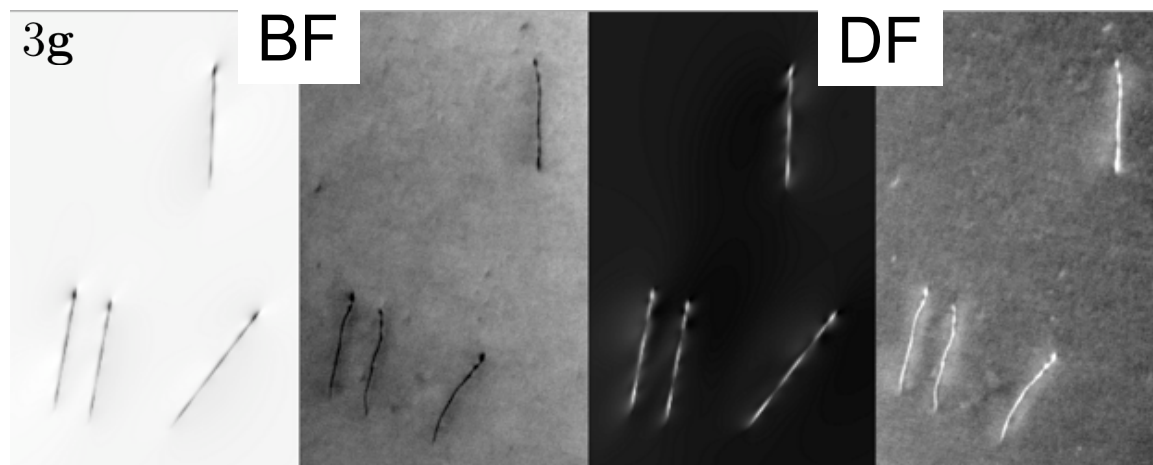


- Fringe blurring toward bottom of foil at low CL
- BF symmetric about foil center, ADF asymmetric (for **optimal** CL)

Diffraction Contrast STEM Simulation

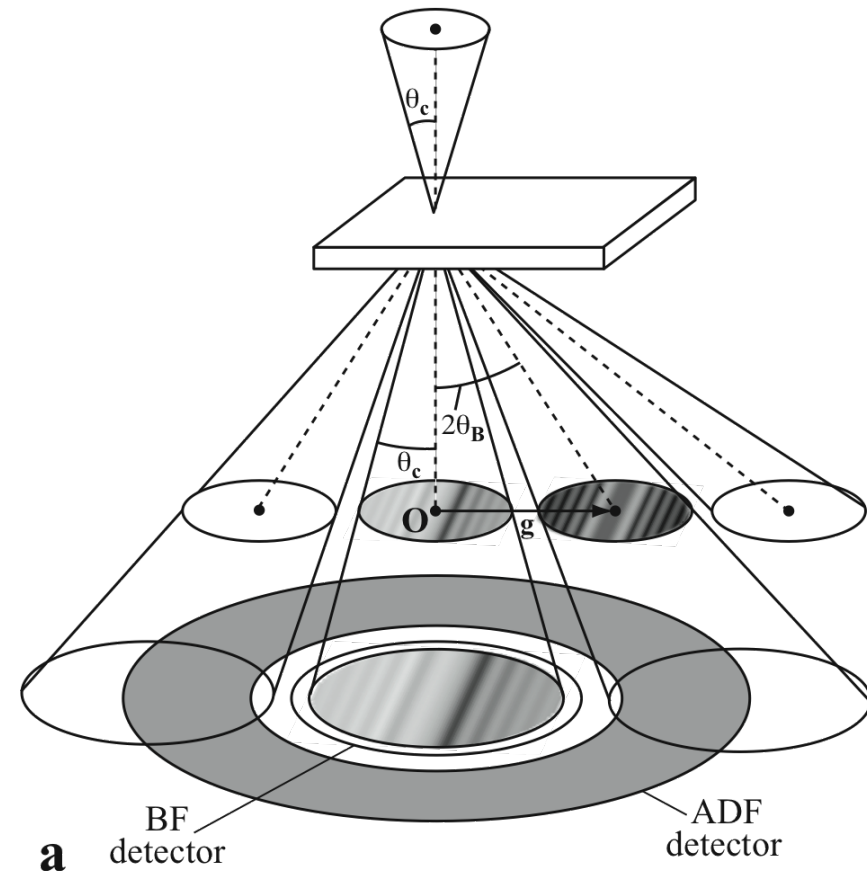


- Can apply “standard” $g \cdot b$ imaging criteria
- Higher order reflections (e.g. $3g$) produce very fine detail similar to weak beam



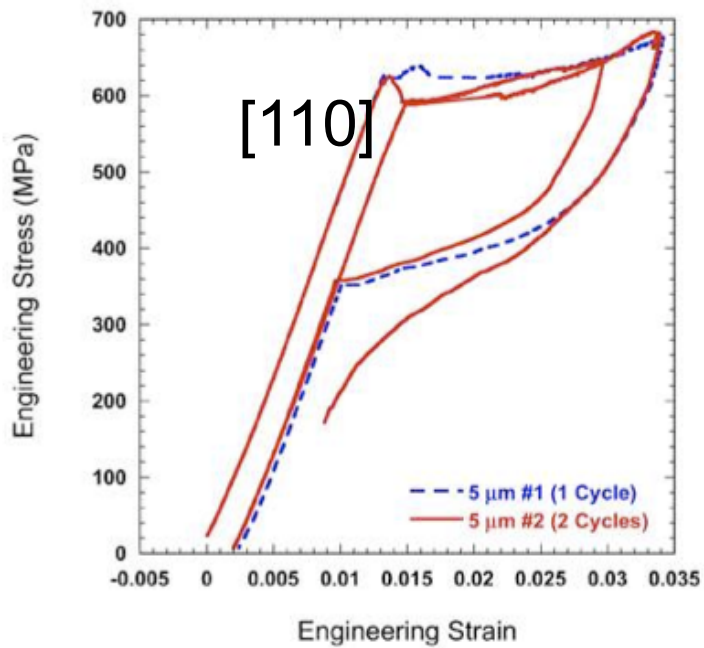
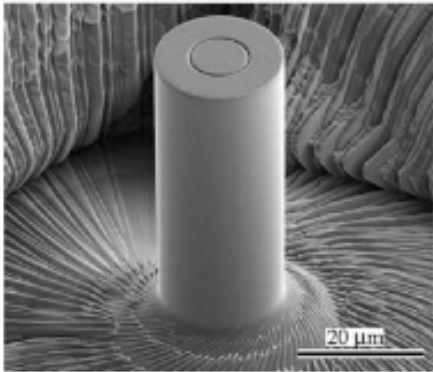
Summary of Advantages of STEM-DC

- Obscuring effect of bend contours muted
- High order g imaging enables fine detail (similar to weak beam) but with much faster image acquisition
- Much thicker samples can be examined (> 1 micron)
- “Conventional” defect visibility rules hold for optimal conditions (beam convergence and camera length)

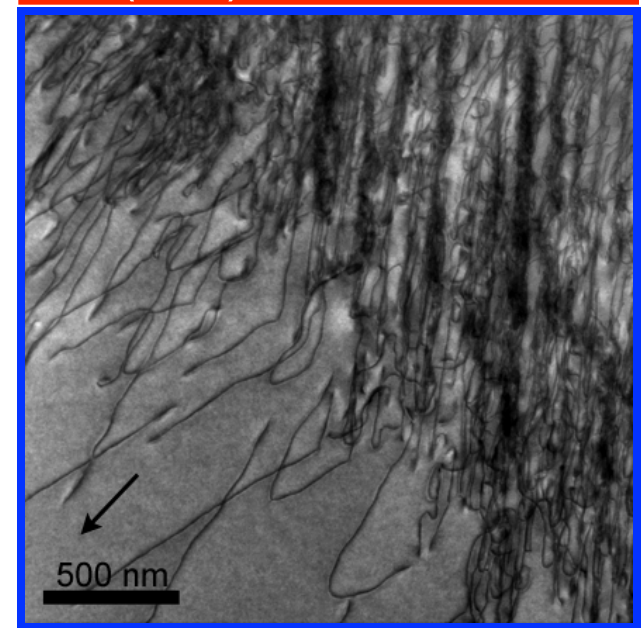
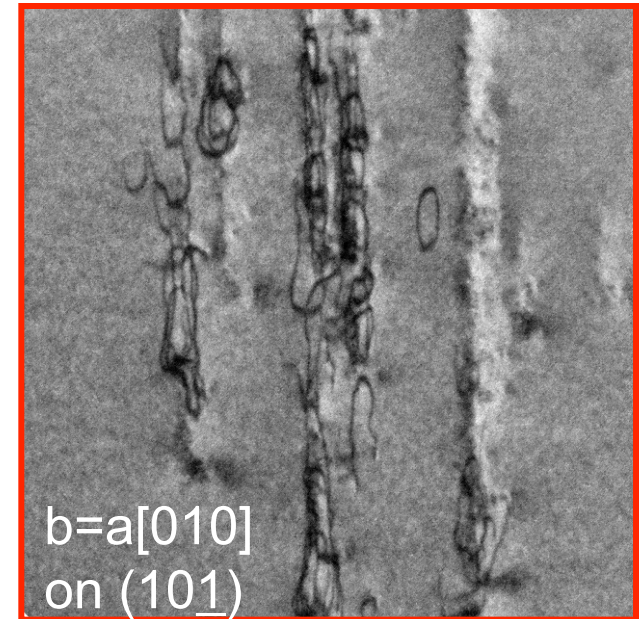
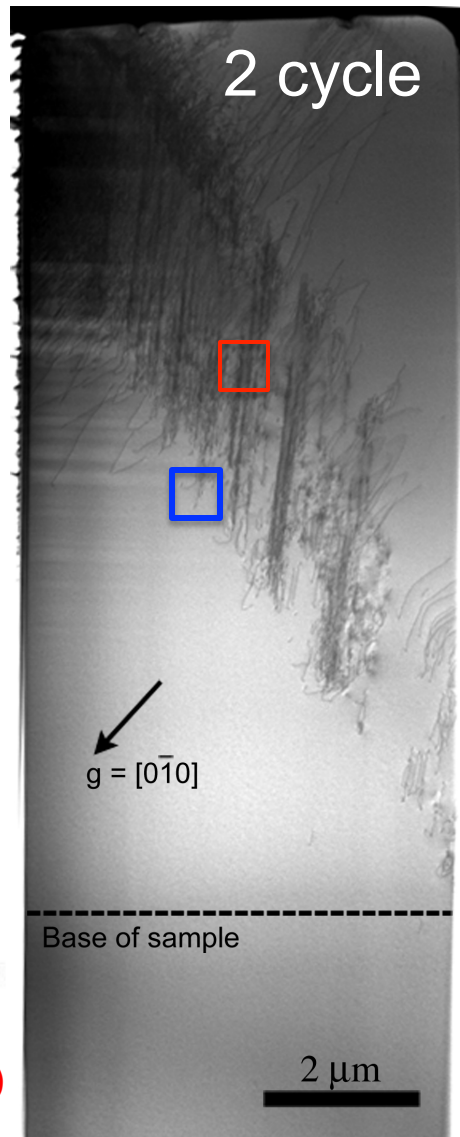


Useful for 3D defect analysis ?

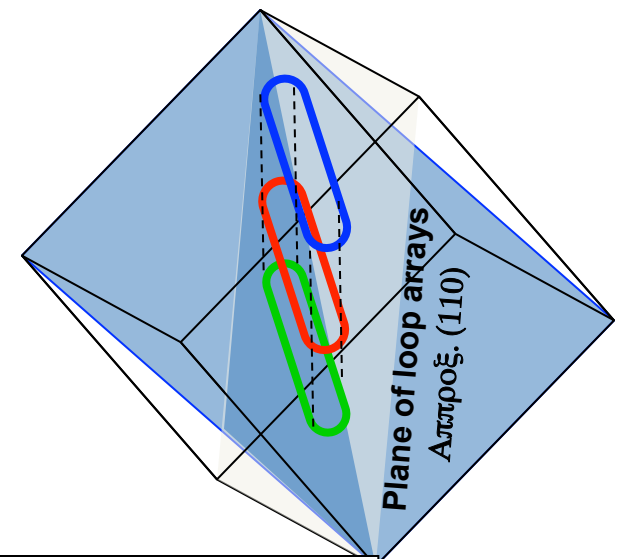
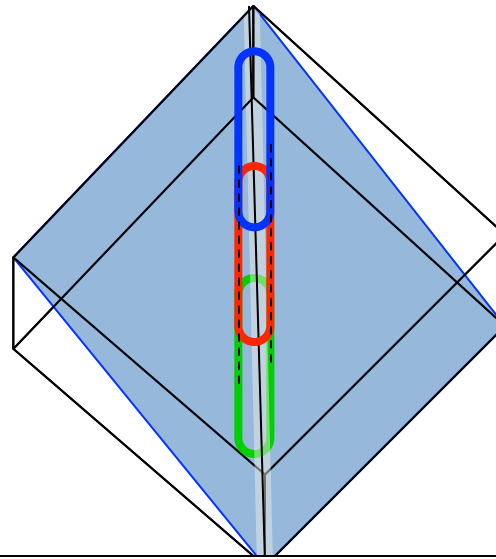
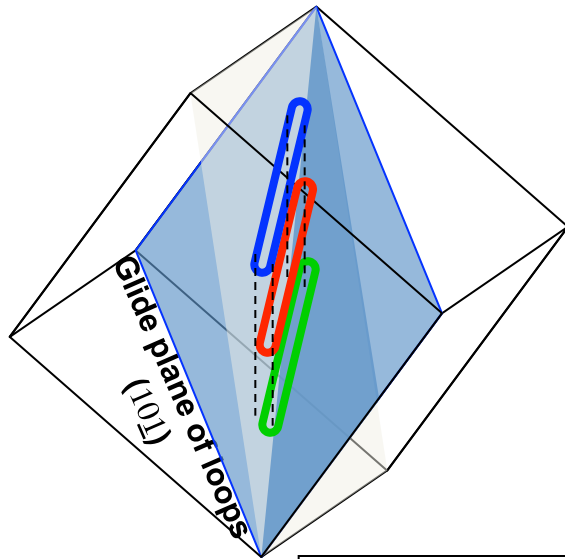
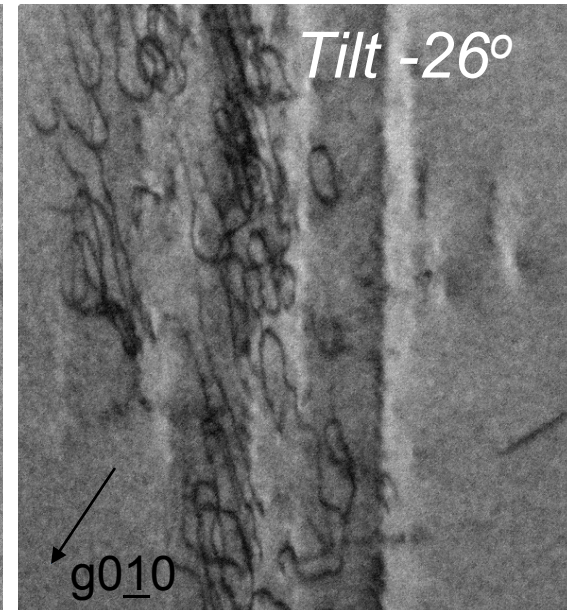
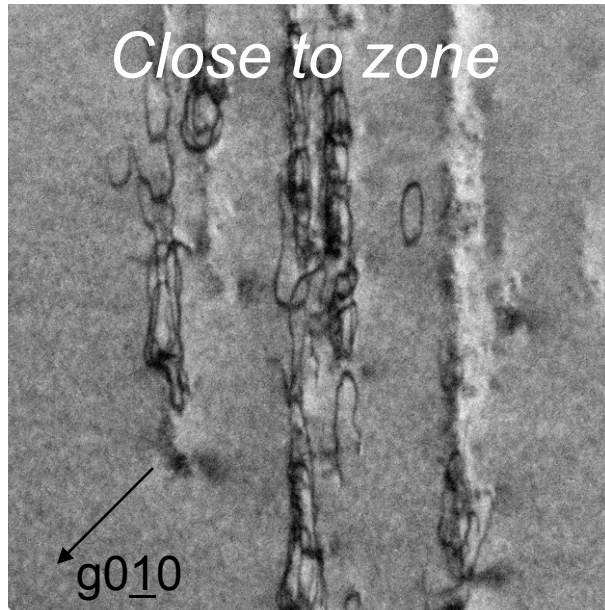
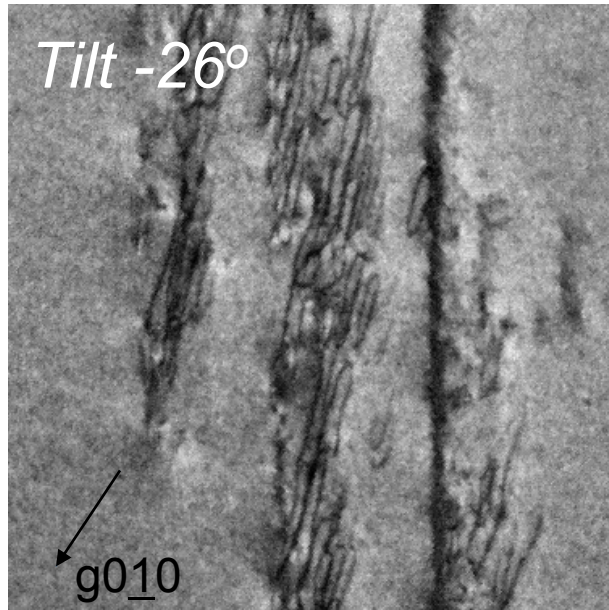
Pillar Testing of Ni-49.3at.%Ti



Norfleet, et al. *Acta Mat.*, 57 (2009)

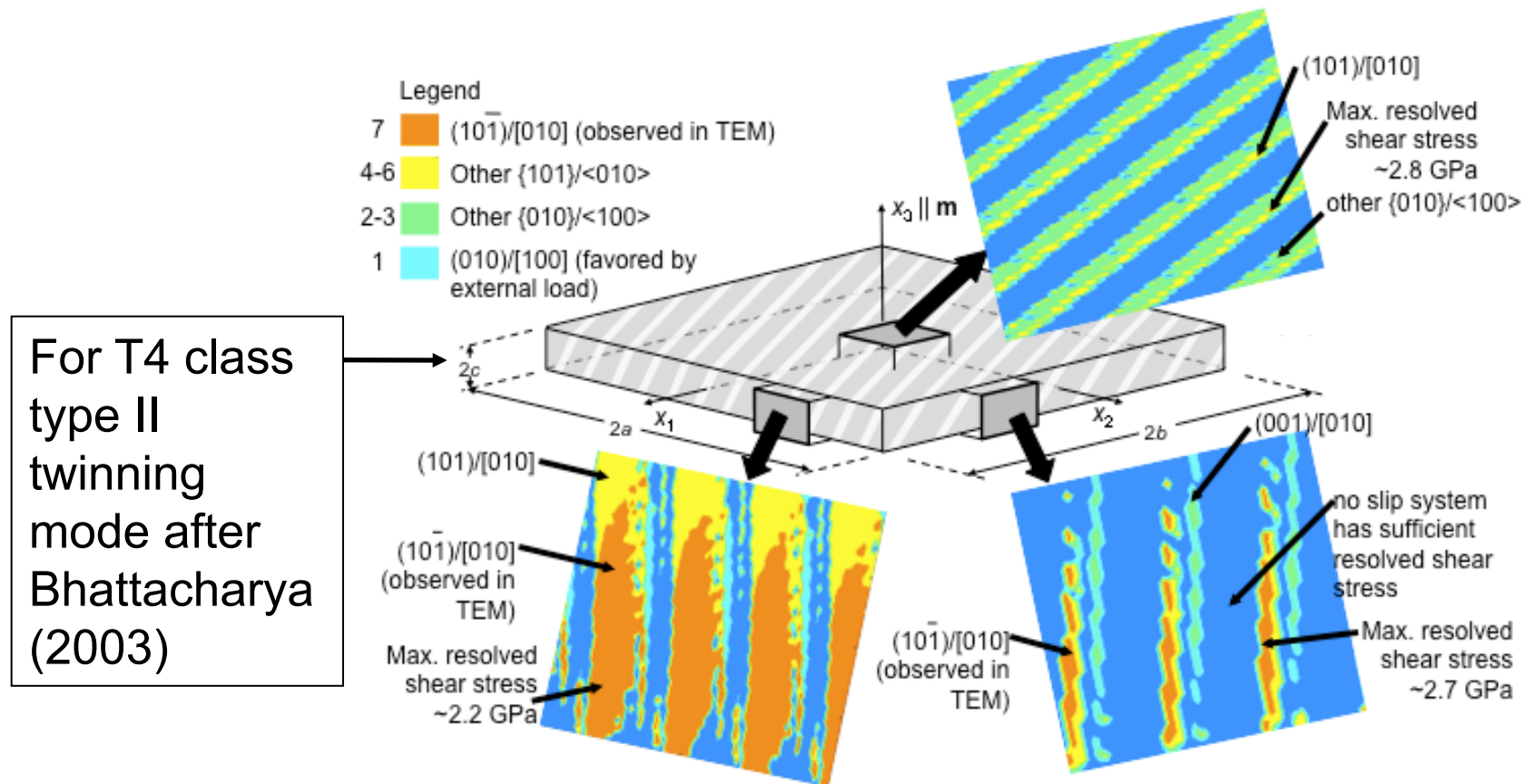


3D Geometry of Dislocations in NiTi



Individual $a[0\bar{1}0]$ loops also on $(10\bar{1})$ planes

Transformation-Induced Dislocation Related to Twin Interfaces of Martensite



- Supports hypothesis that dislocation loop arrays driven into austenite by local stress field of transforming martensite variants
- Nucleation of loop arrays not presently understood

Norfleet, et al. *Acta Mat.*, 57 (2009)

Diffraction Contrast STEM Example

Structures in Superalloy ME3 after LCF at 700°C:

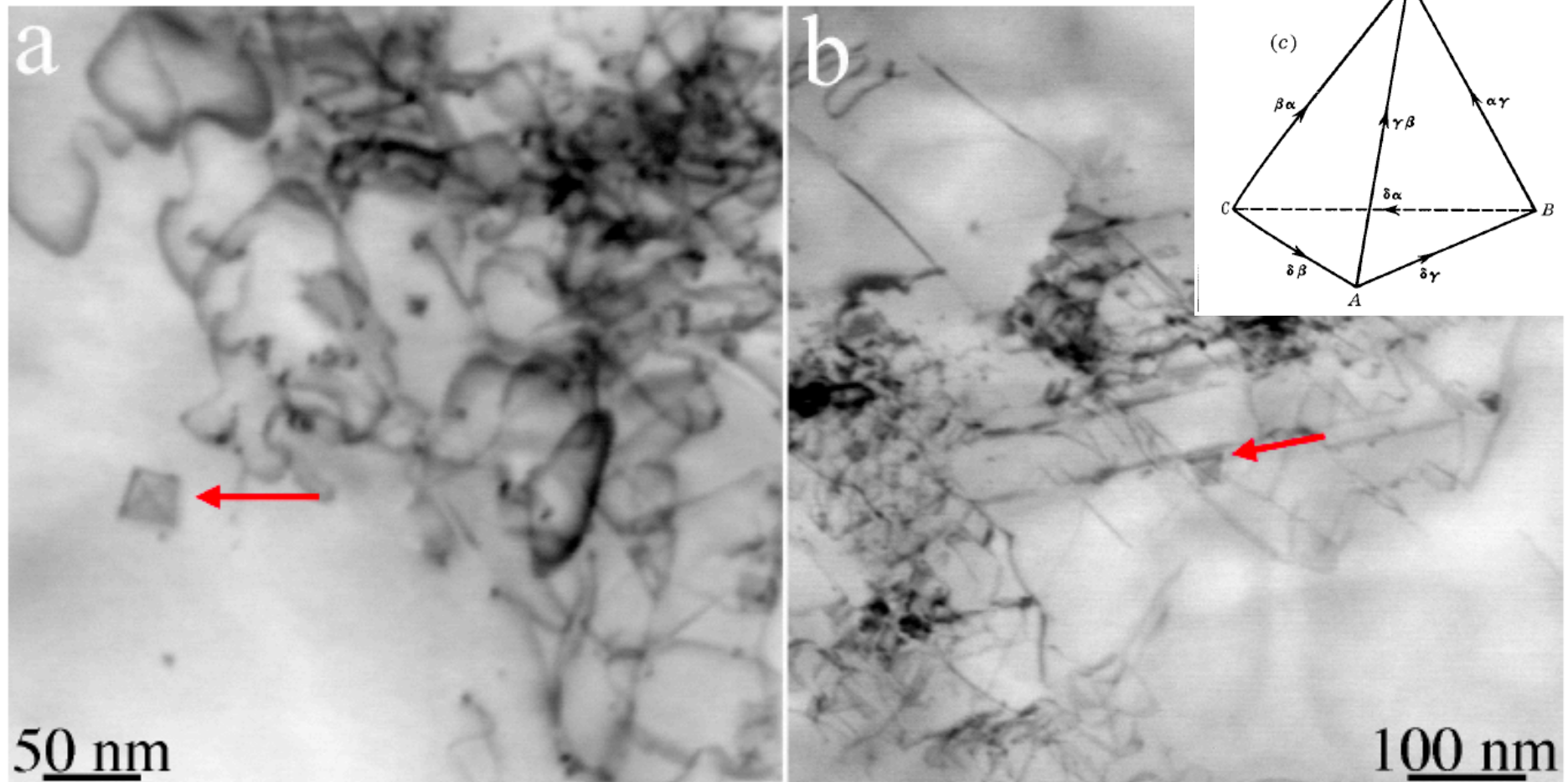


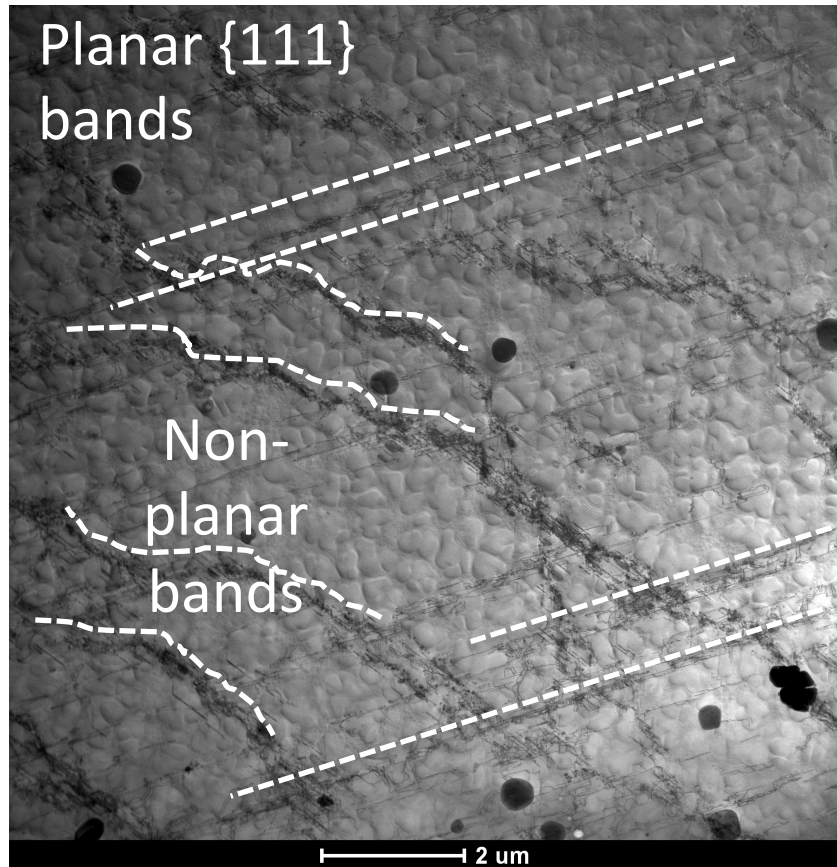
Figure 4.14: Stacking fault tetrahedra; a) specimen 704/0.80/1295, $\vec{B} \approx [001]$; b) specimen 427/0.75/21, $\vec{B} \approx [013]$. Images acquired on TF20.

Phillips (2011)

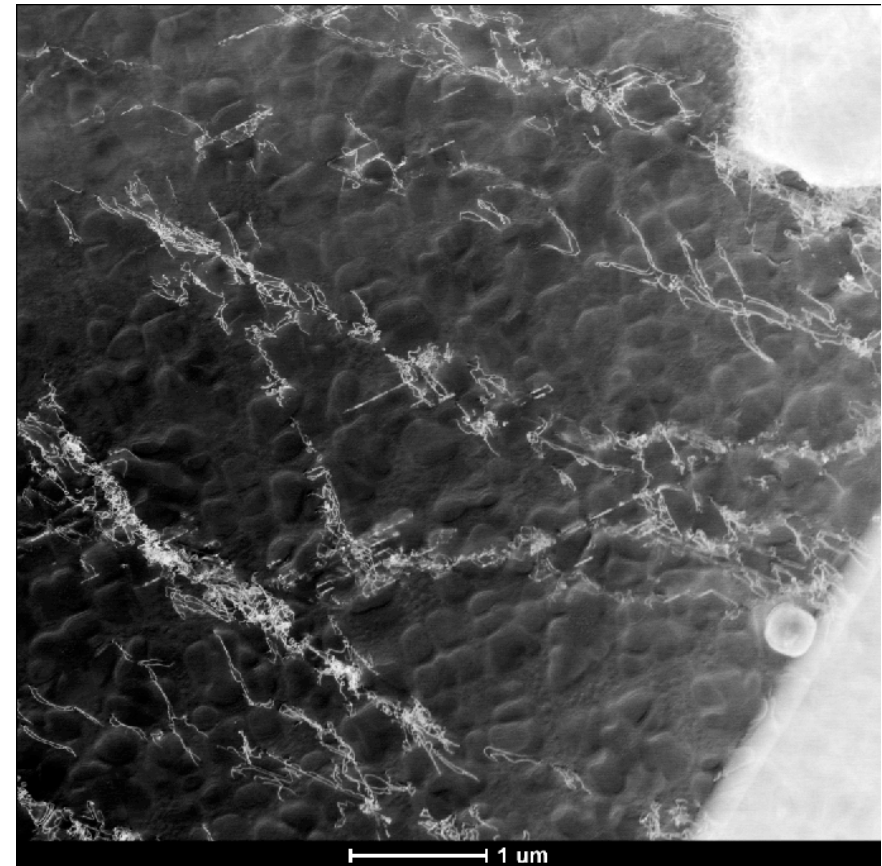
Planar and Wavy Slip after High Temperature LCF – Superalloy ME3



Edge-on View



1295 cycles

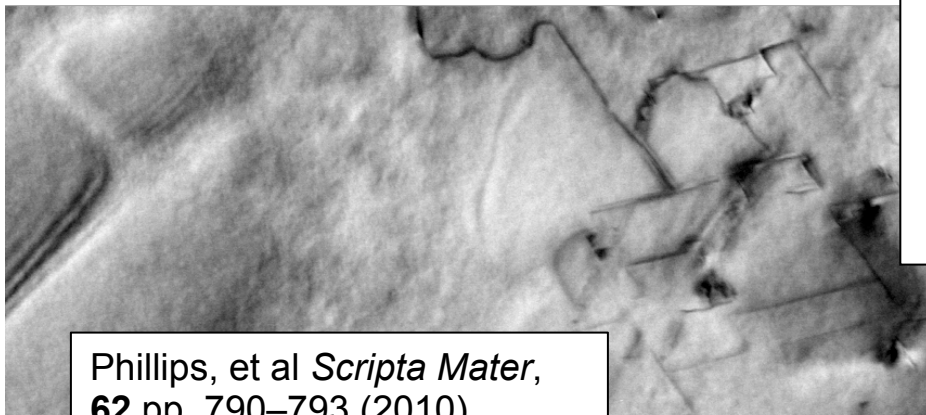


395 cycles

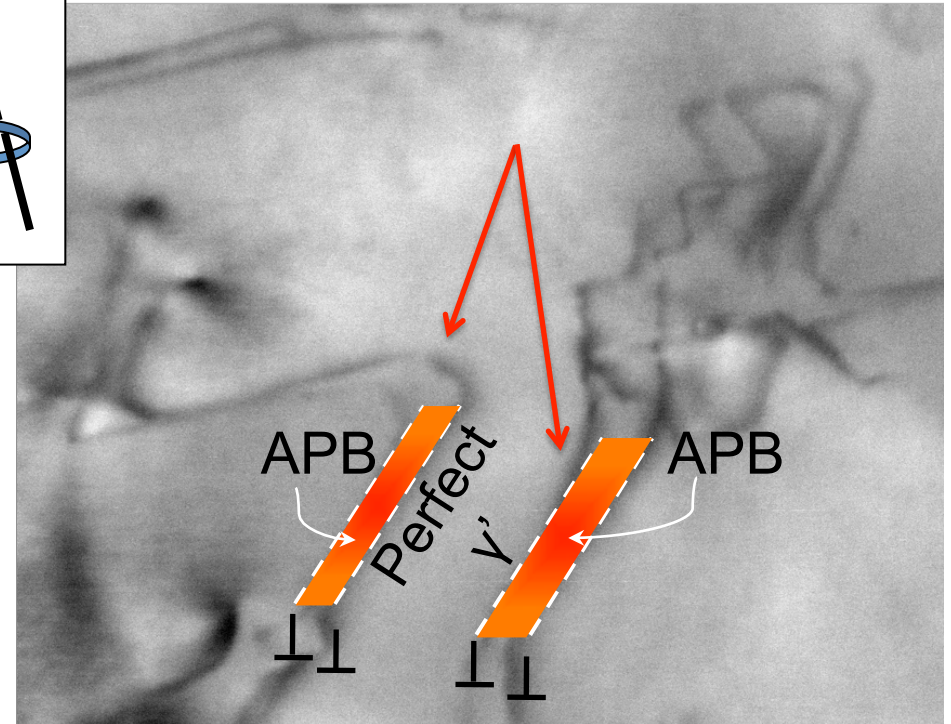
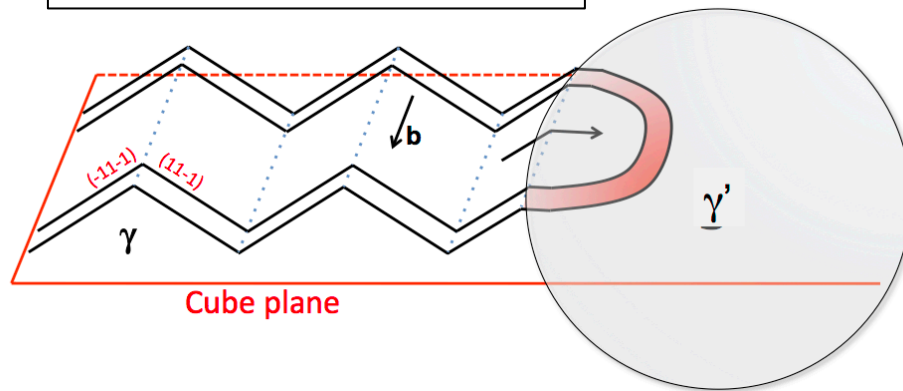
*Wavy slip between {111}
and {010} planes*

Tilting for 3D Information

“Cube Slip” in Superalloy ME3



Phillips, et al *Scripta Mater*,
62 pp. 790–793 (2010).



each pair of dislocations:

$$\frac{1}{2} \langle 110 \rangle + APB_{[001]} + \frac{1}{2} \langle 110 \rangle$$



- Coupled dislocations resolved on both {111} and {001} planes

Diffraction Contrast STEM Stereo-pairs

L. Agudo Jácome et al. / Acta Materialia xxx (2013) xxx-xxx

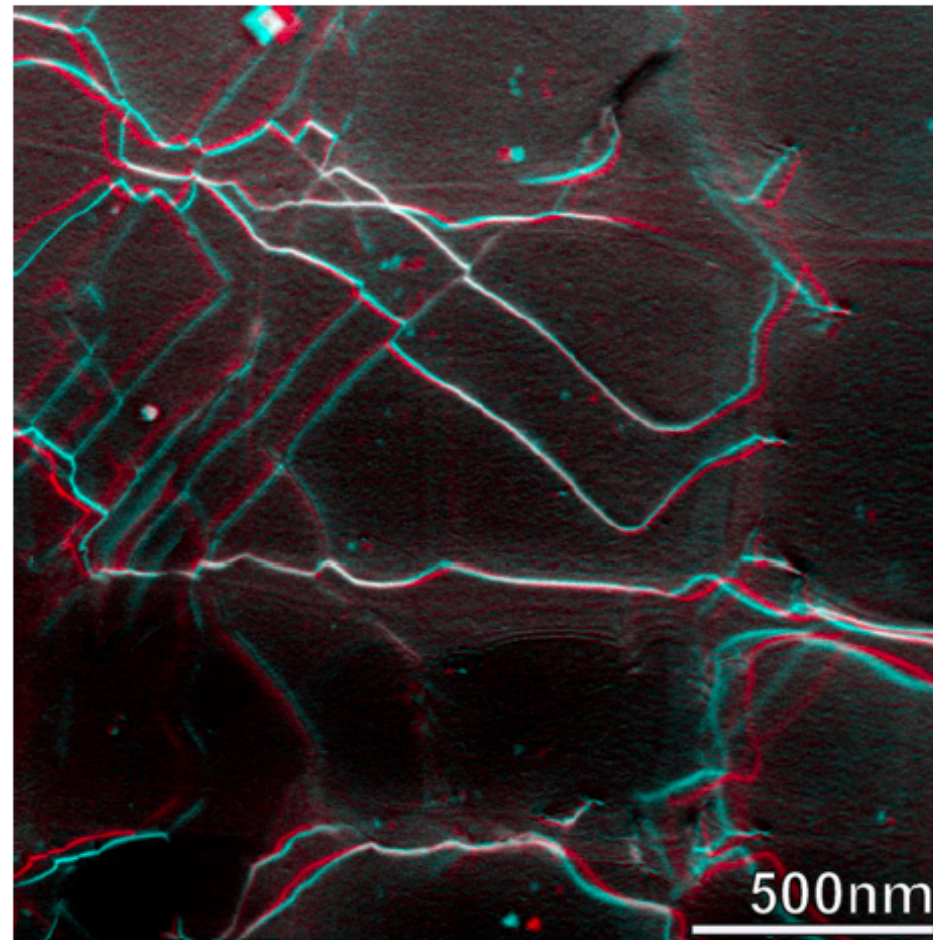
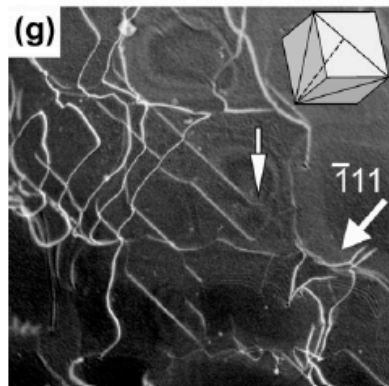
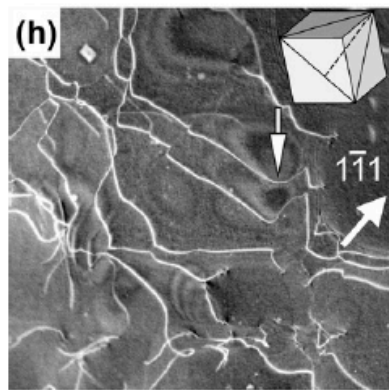
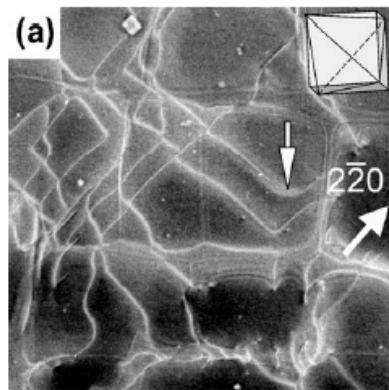
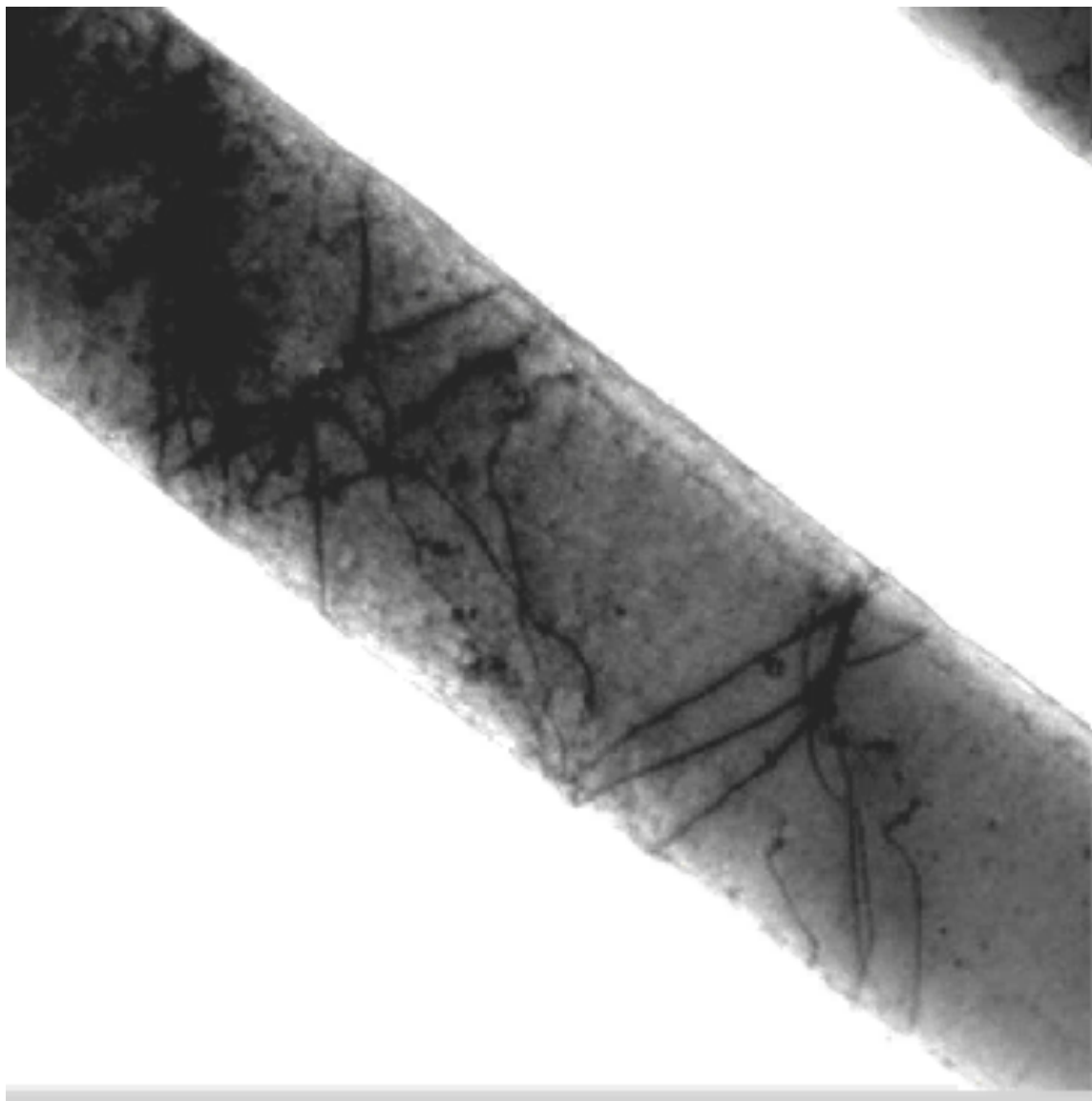


Fig. 6. Three-dimensional anaglyph of the pair of dislocations highlighted in the micrographs in Fig. 5 obtained applying the stereo STEM procedure of Agudo et al. [60]. For a realistic 3D impression, the anaglyph must be viewed with a special pair of colored glasses (👓), [60].

Diffraction Contrast STEM Tilt Series



0.6 μm Thick
Molybdenum ($Z=42$)
Fiber

BF tilt series using
 g_{200}

Images obtained
every 1.5°

Tilt range: -30 to $+30^\circ$

*J. Kwon (OSU)
EFRC Center for Defect
Physics (DOE-BES)*

STEM Tomography

Practical considerations for tilt series acquisition:

- Align sample so single tilt axis (α) is diffraction vector
 - Same diffraction condition (systematic row) must be maintained throughout tilt series
 - Multiple tilt axes makes tilting and subsequent image alignment difficult
 - Depending on sample and image quality, automated tilt series acquisition routines may be used (FEI Inspect3D)
- Uniform intensity is vital for quality reconstructions!
 - ADF-STEM offers many advantages over conventional weak beam dark field:

1. Fewer dynamical effects (bend contours, thickness fringes, oscillatory dislocation contrast due to inclination)
2. Less sensitive to small misalignments, such as from regions of large strain
3. Capable of resolving details from much thicker specimens (up to $\sim 1\mu\text{m}$) than CTEM

Options for alignment and reconstruction



– **IMOD**

- Created by Boulder Laboratory
- Image segmentation, cross-correlation and manual alignment, tomographic reconstruction
- Capable of handling dual axis tilt series

– **TomoJ (ImageJ, FIJI)**

- ImageJ plugin developed at Curie Institute
- Automated and manual alignment with landmark detection, tomographic reconstruction (back projection, SIRT, ART, etc) for single tilt axis
- Allows preprocessing of raw images (hot spot removal, background subtraction, etc.)

– **EM3D**

- Developed at Stanford (no longer in development)
- Created for segmentation, alignment, and reconstruction of electron tomography
- Capable of handling dual axis tilt series

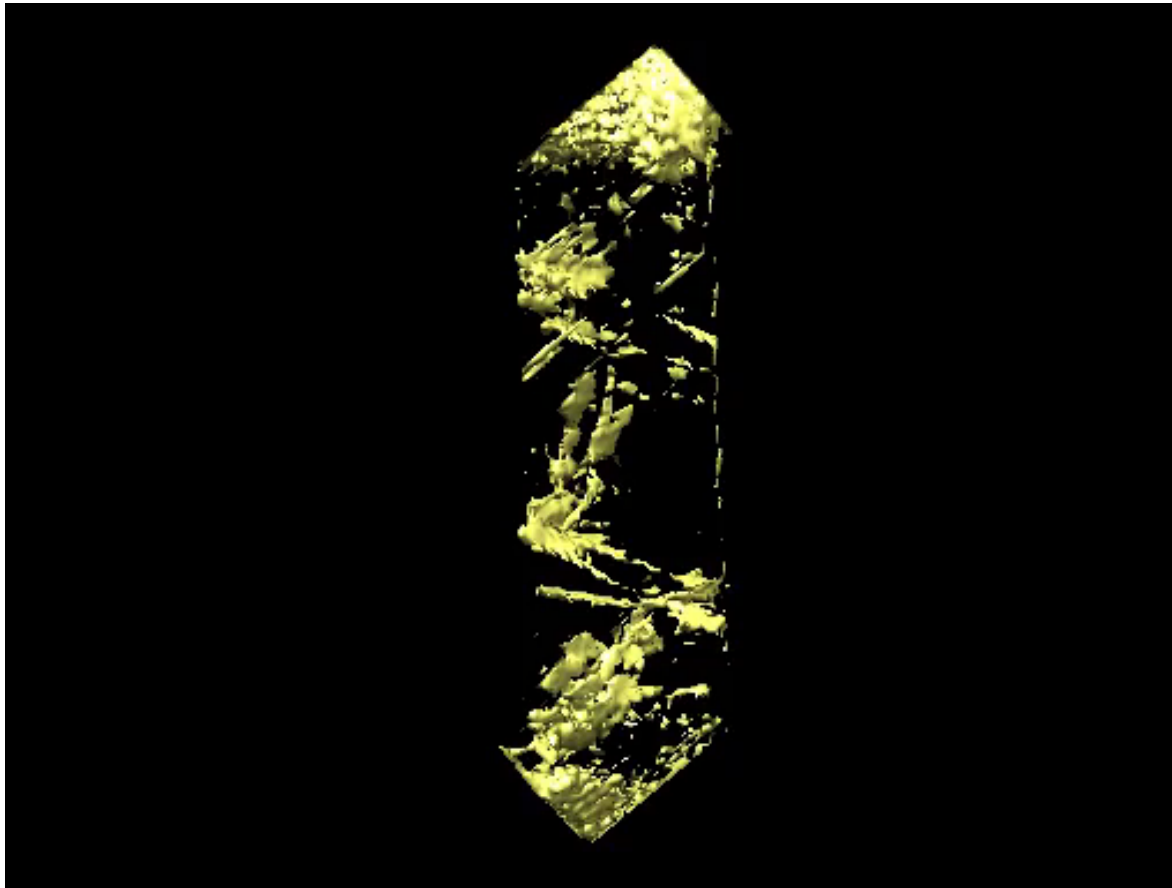
– **FEI Xplore3D**

- Microscope-integrated software package
- Automated electron tomography tilt-series acquisition (including drift correction), alignment and reconstruction

Visualization of tomographic data:

- **Chimera: 3D molecular visualization software**
 - Developed at UCSF
 - Refinement and processing of 3D data sets
 - Thresholding and segmentation of tomograms
 - Many visualization options: solid, mesh, surface, etc.
 - Movie creation

Diffraction Contrast STEM Tilt Series



0.6 μm Thick
Molybdenum ($Z=42$)
Fiber (8% prestrain)

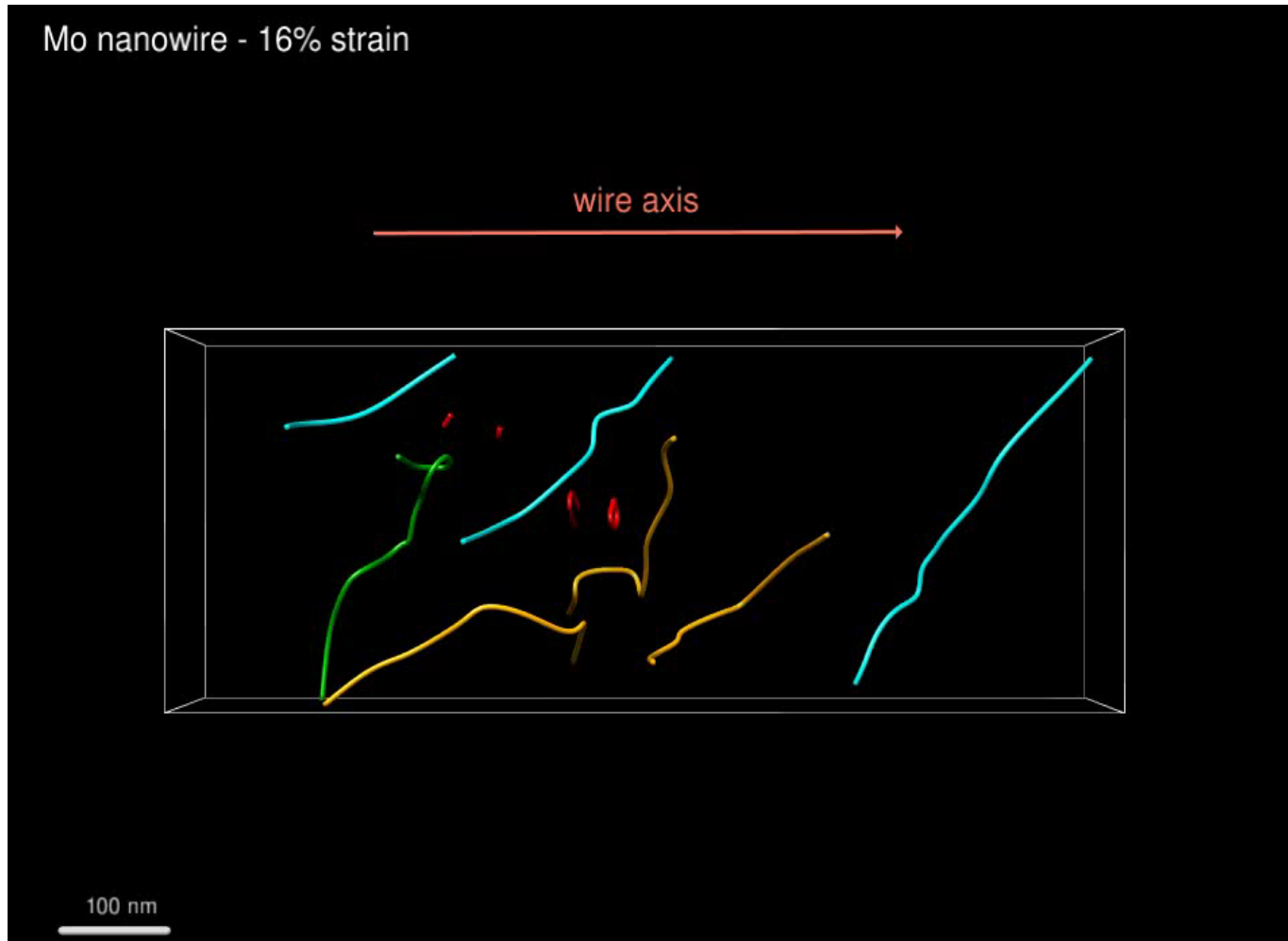
BF tilt series using
g200

Images obtained
every 1.5°

Tilt range: -30 to $+30^\circ$

*J. Kwon and Matt Bowers (OSU)
EFRC Center for Defect Physics
(DOE-BES)*

Diffraction Contrast TEM Tomogram



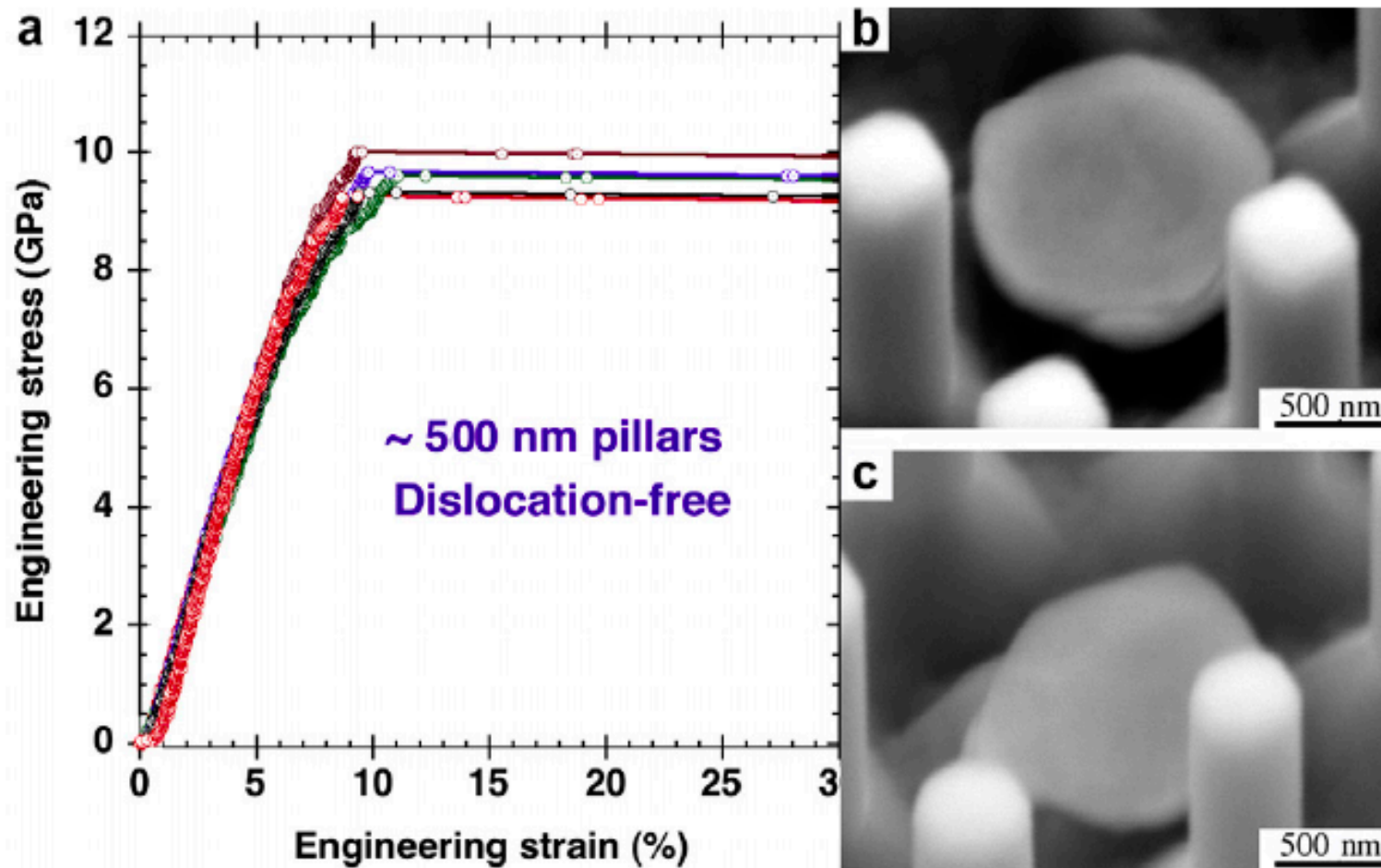
0.6 μm Thick
Mo fiber

- “Tracing” of lines in 3D tomogram
- Use prior knowledge of end-points at surfaces/ interfaces

Virginia
McCreary
(UIUC)

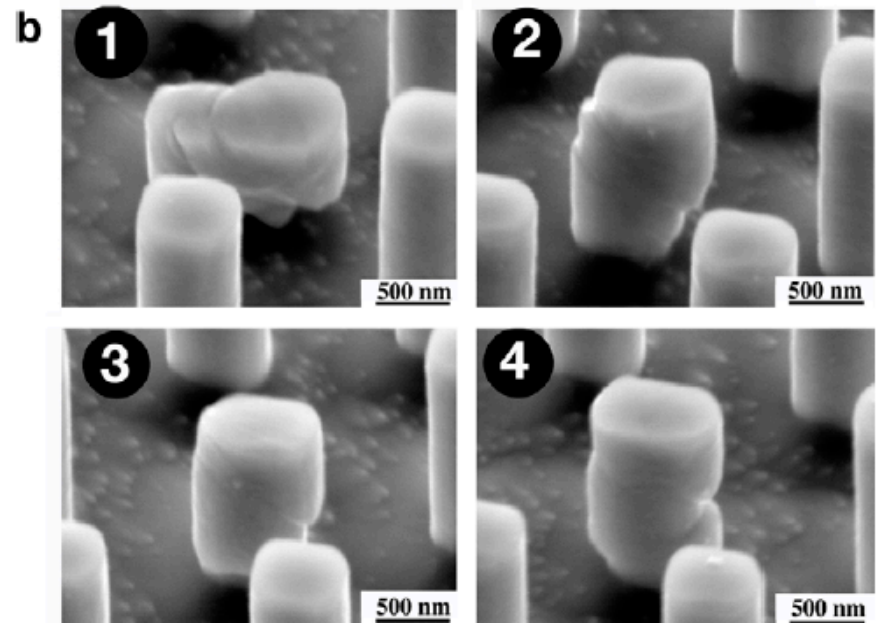
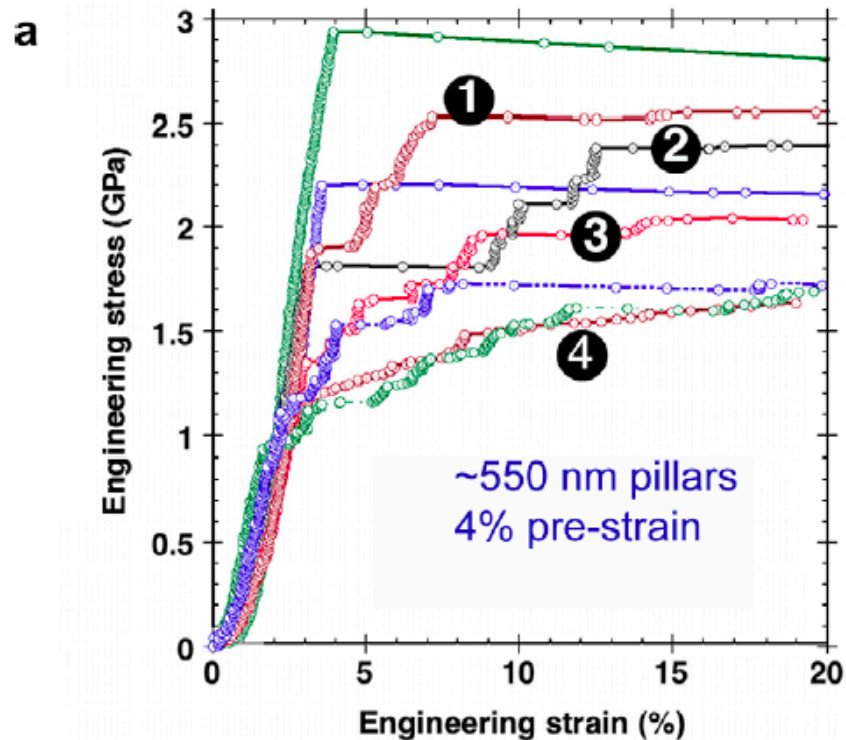
Ideal Strength of Perfect Mo Fibers

Bei, et al (2008)



Stochastic Behavior at Intermediate Pre-strain

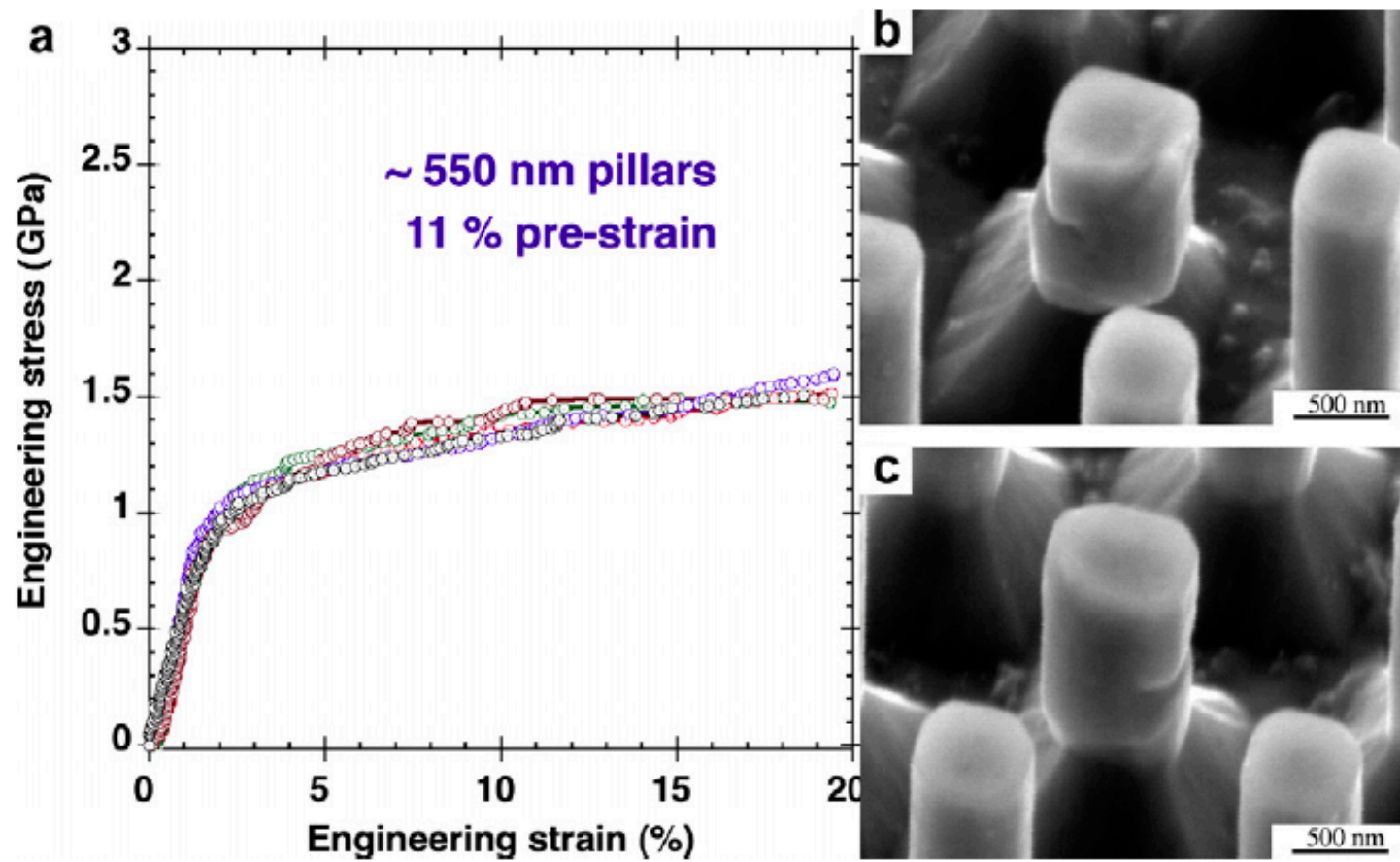
Bei, et al (2008)



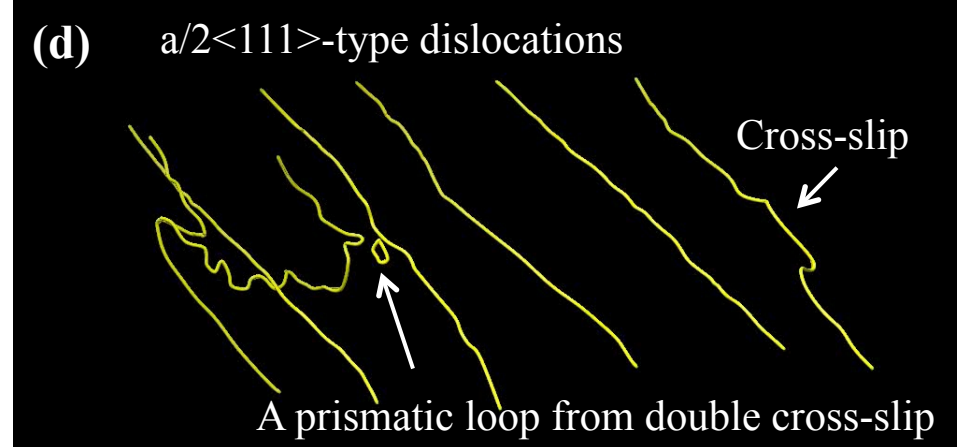
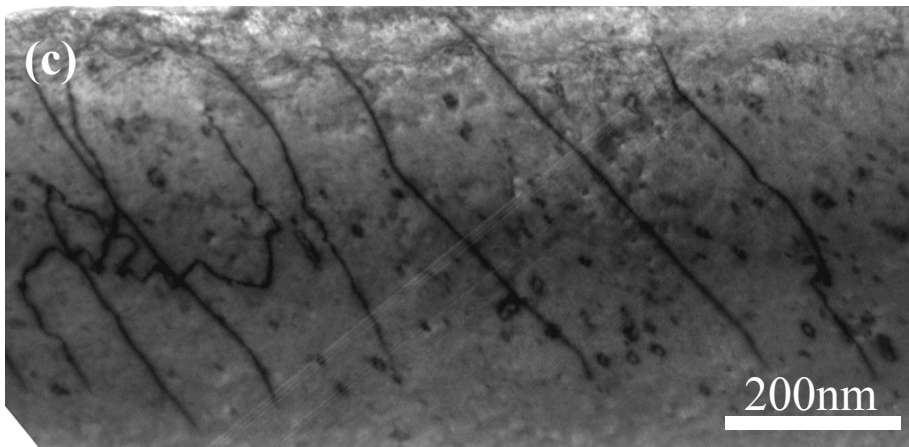
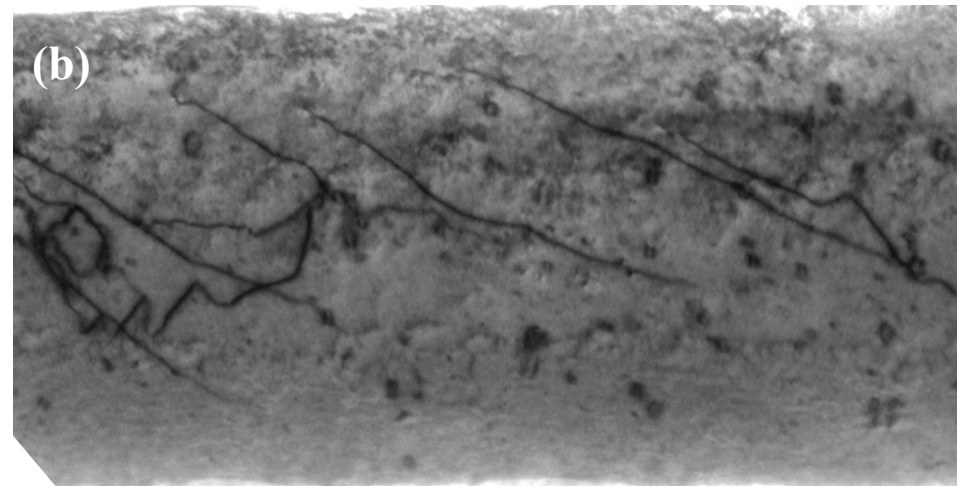
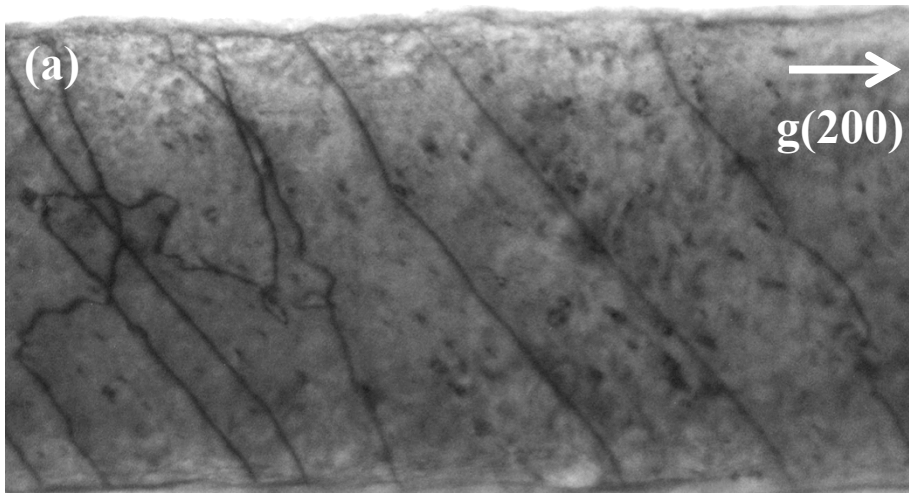
- Stochastic behavior – not predictable!
- Hypothesis: depends on details of dislocation sources prior to deformation

“Bulk-like” Behavior at Larger Pre-strain

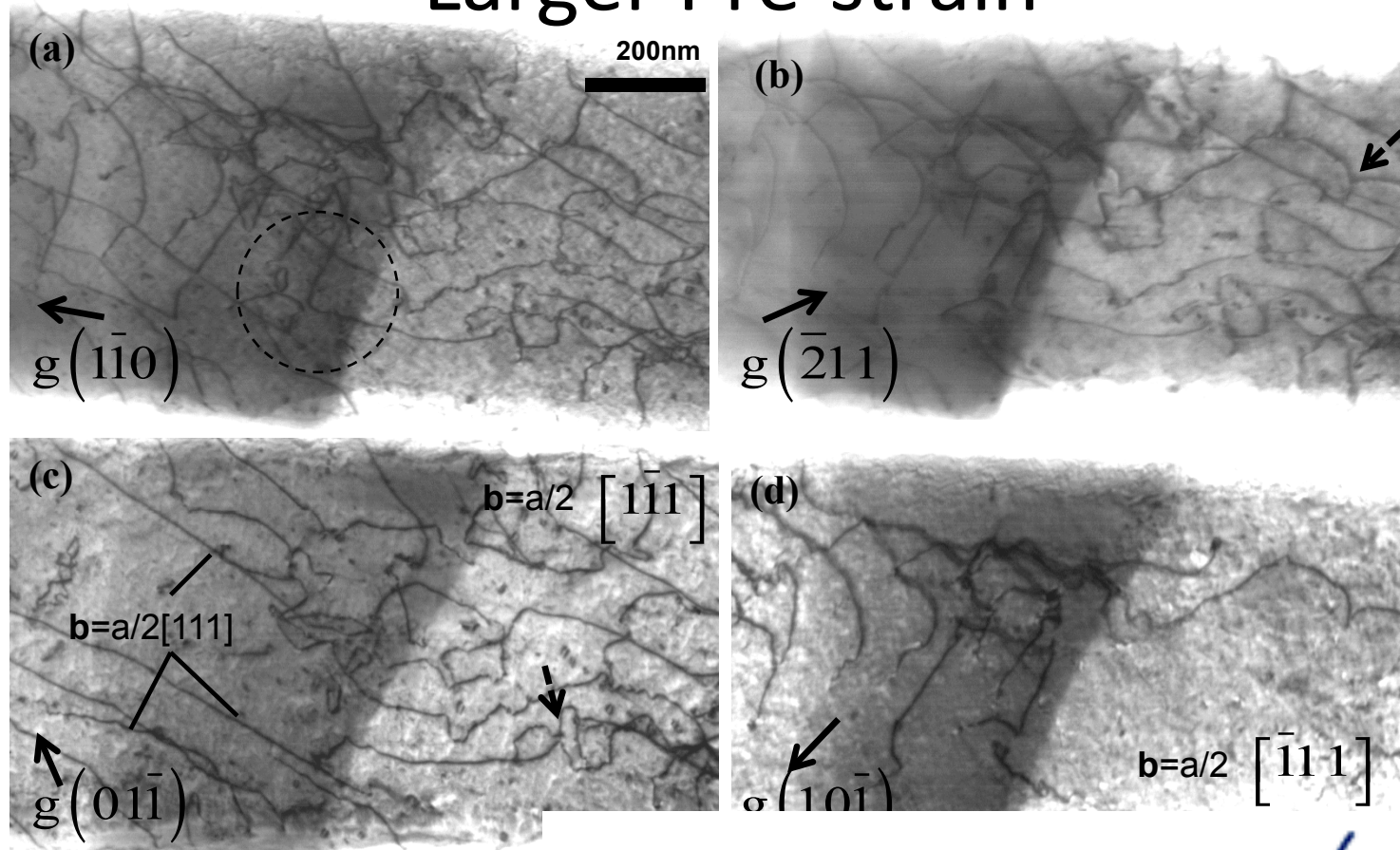
Bei, et al (2008)



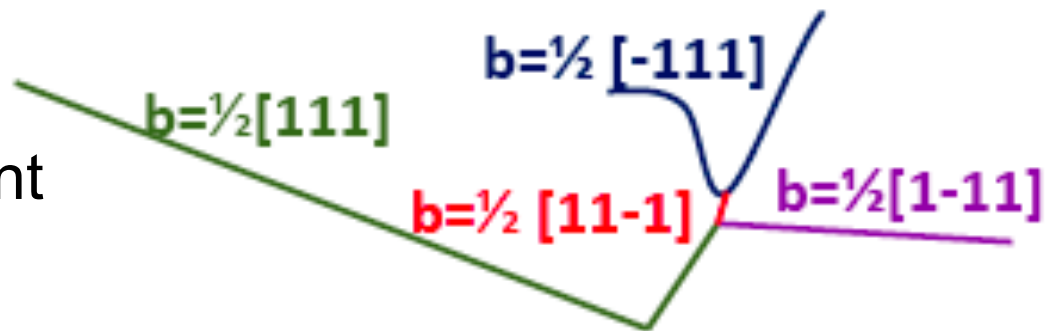
Dislocation Configurations at Larger Pre-strain



Dislocation Configurations at Larger Pre-strain

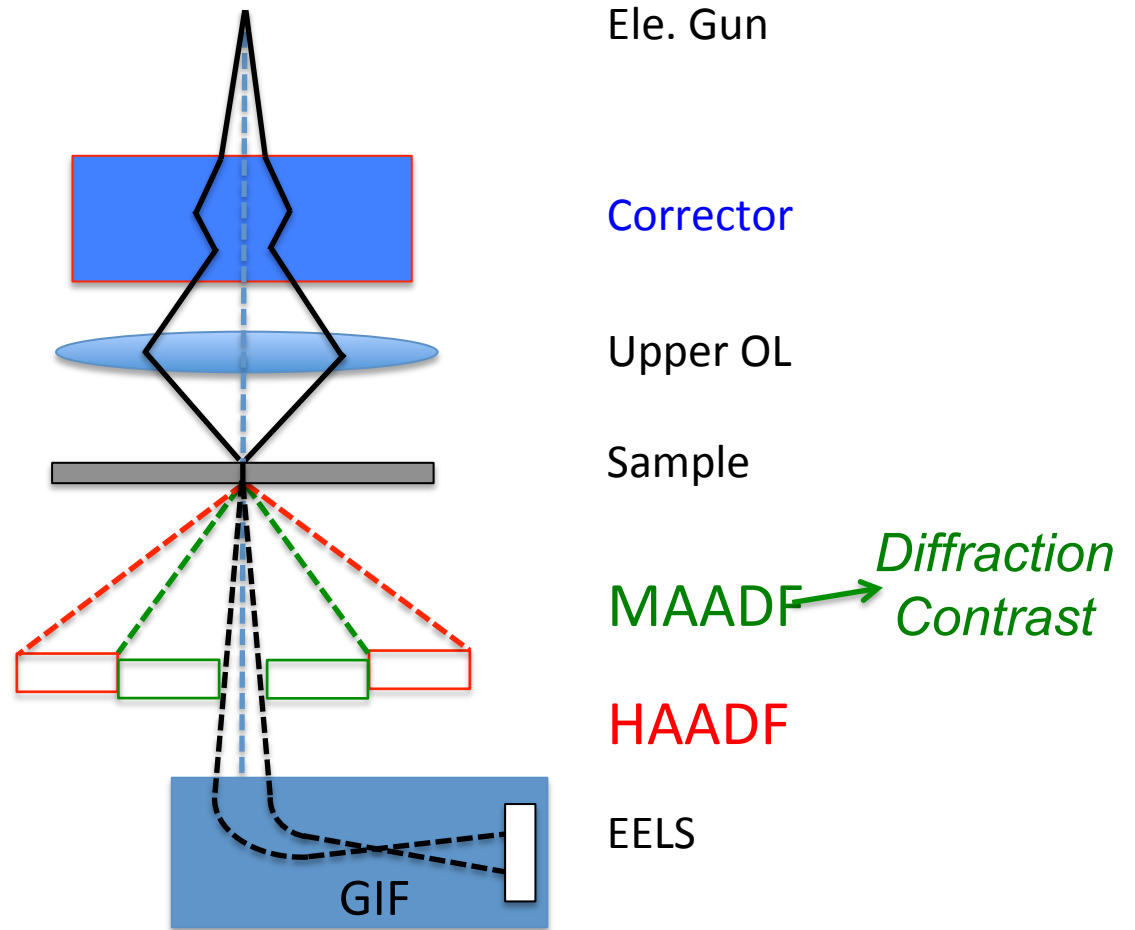


- Multi-junction observed
- Favorable as a persistent dislocation source



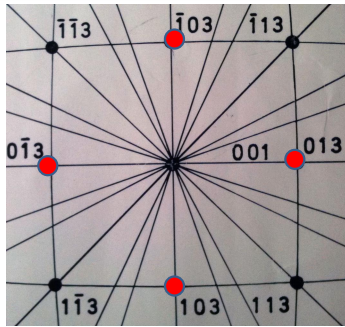
Zone Axis MAADF and HAADF Imaging

FEI Titan³ 80-300 Probe Aberration Corrected

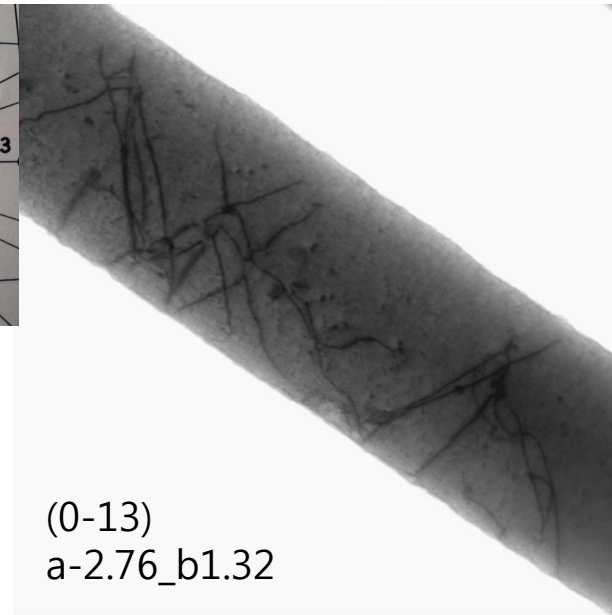


Both diffraction contrast and atomic number (Z) contrast can be accessed in zone axis orientations

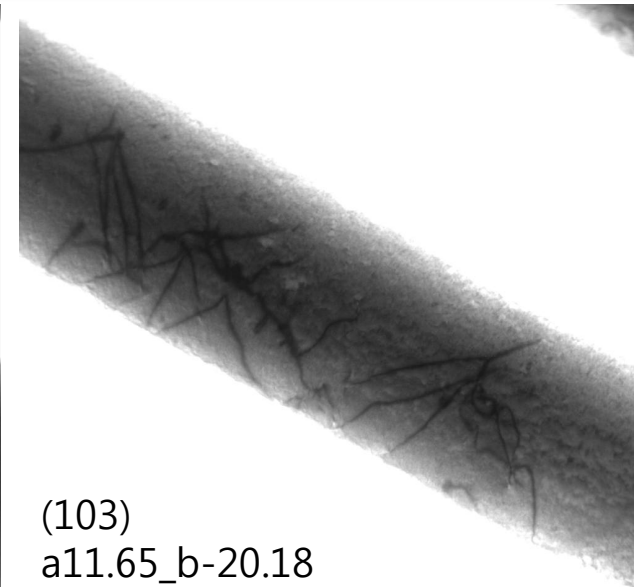
Zone Axis STEM Defect Imaging



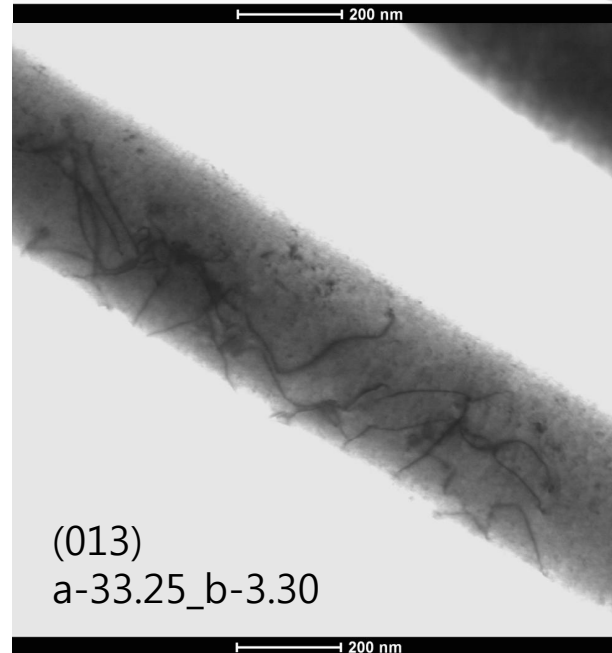
0.6 μm Mo fibers



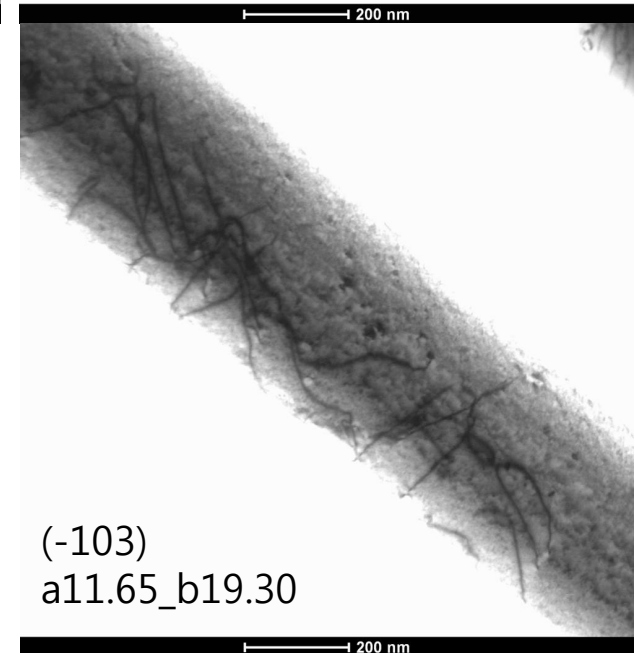
(0-13)
a-2.76_b1.32



(103)
a11.65_b-20.18



(013)
a-33.25_b-3.30

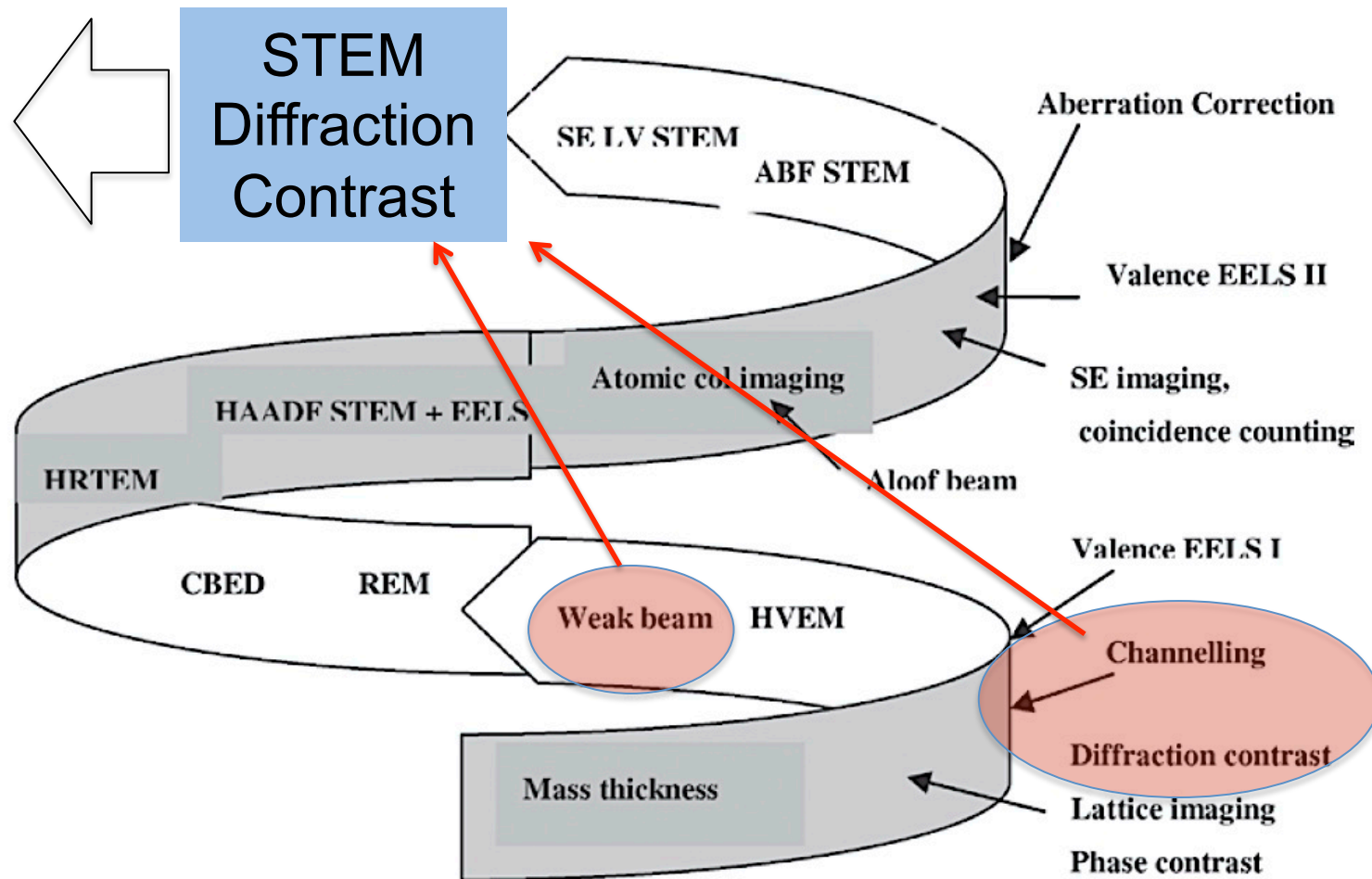


(-103)
a11.65_b19.30

Interesting possibilities for 3D tomography !

Spiral History of TEM

A. Howie, M&M Proceedings, 2012



*Advances in high brightness sources **can** benefit diffraction contrast defect studies*

Possibilities

- Automated specimen stages for computer-controlled tilting:
 - Tilt series acquisition
 - Zone axis image acquisition
 - 3D Reconstruction software
- Sector (or CCD array) detectors for:
 - Accurate selection of diffraction conditions
 - Post-processing “g•b” experiments with zone axis images
- In situ deformation experiments taking advantage of enhanced thickness capabilities of STEM diffraction contrast
- Rapid STEM acquisition for in situ observations

